## **Photoemission from solids**

#### G. Paolucci Elettra - Sincrotrone Trieste

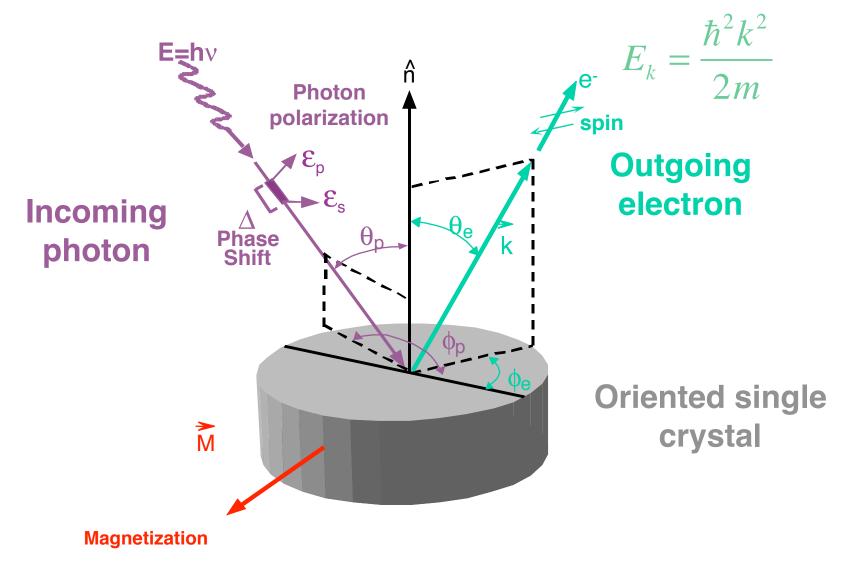
## **Outline**

## Outline

#### Basics

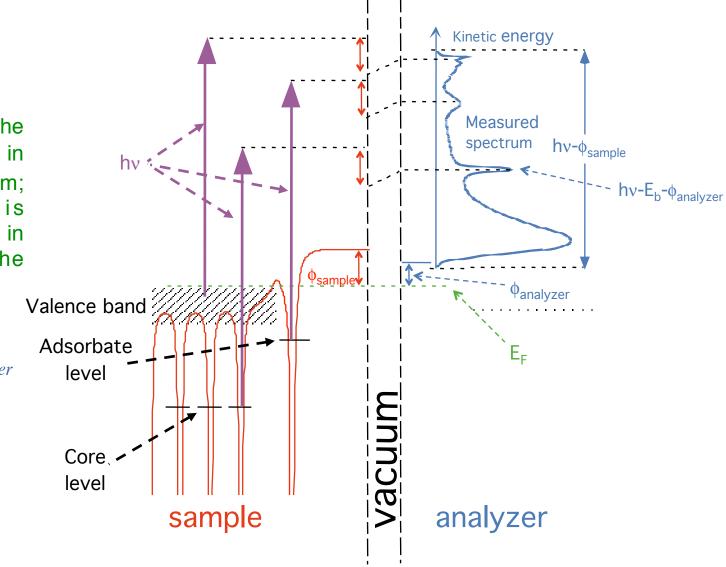
- Photoelectric effect
- Sources and electronananalyzers
- A bit of quantum mechanics
- Photoemission cross section&Cooper minimum
- Valence band angle resolved photoemission
  - momentum conservation
  - band mapping
  - dipole selection rules
- Core level photoemission
  - Element specificity
  - Sensitivity to chemical environment
  - Photoelectron diffraction
  - Time evolution
  - Microscopy

# The photoemission experiment



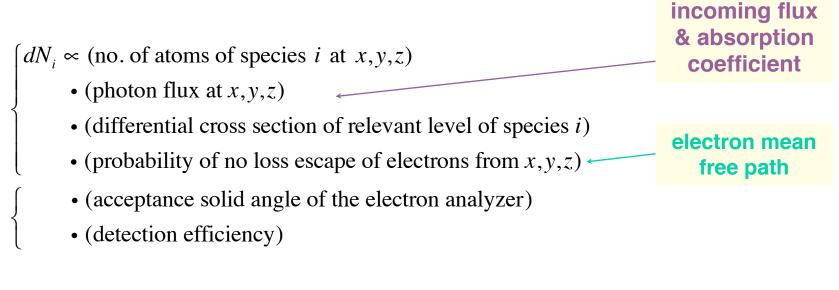
The electron must overcome the sample work function  $\phi_{sample}$  in order to reach the vacuum; afterwards its energy is changed by the difference in work function between the analyzer and the sample. So:

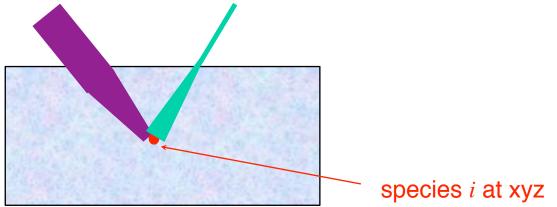
$$E_k^{meas} = hv - E_b - \phi_{analyze}$$



#### The total photoemission intensity from species *i* is obtained by integrating:

relevant for the choice of photon energy!



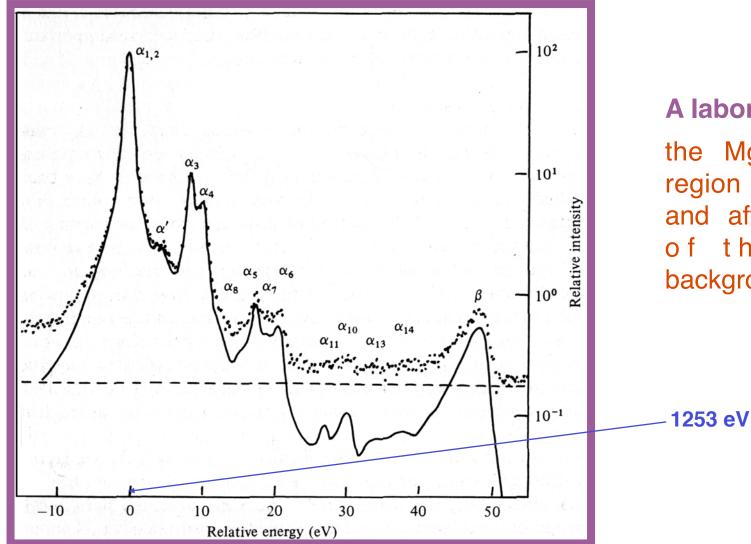


The incoming photons

UV to soft x-rays ( hv ~10 to ~1500 eV or  $\lambda$  ~ 1240 to ~ 5 Å)

- Laboratory sources (relatively cheap) use characteristic transition lines:
  - noble gas discharge (e.g.  $HeI_{\alpha}$ =21.22 eV)
  - solid target emission lines (AI  $K_{\alpha}$ =1428 eV; Mg  $K_{\alpha}$ =1253 eV
- Synchrotron radiation (expensive!) gives tunable, polarized and bright radiation

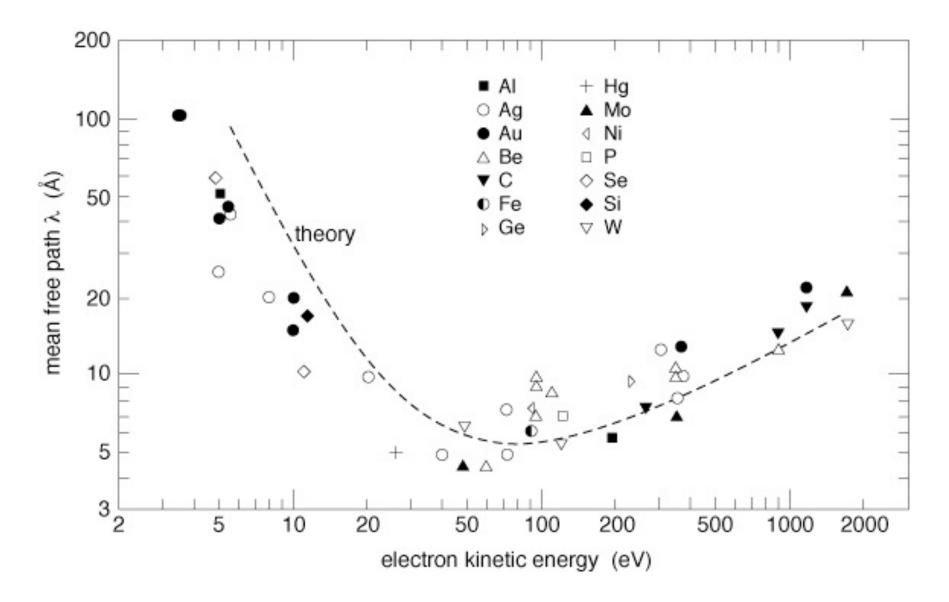
## The incoming photons



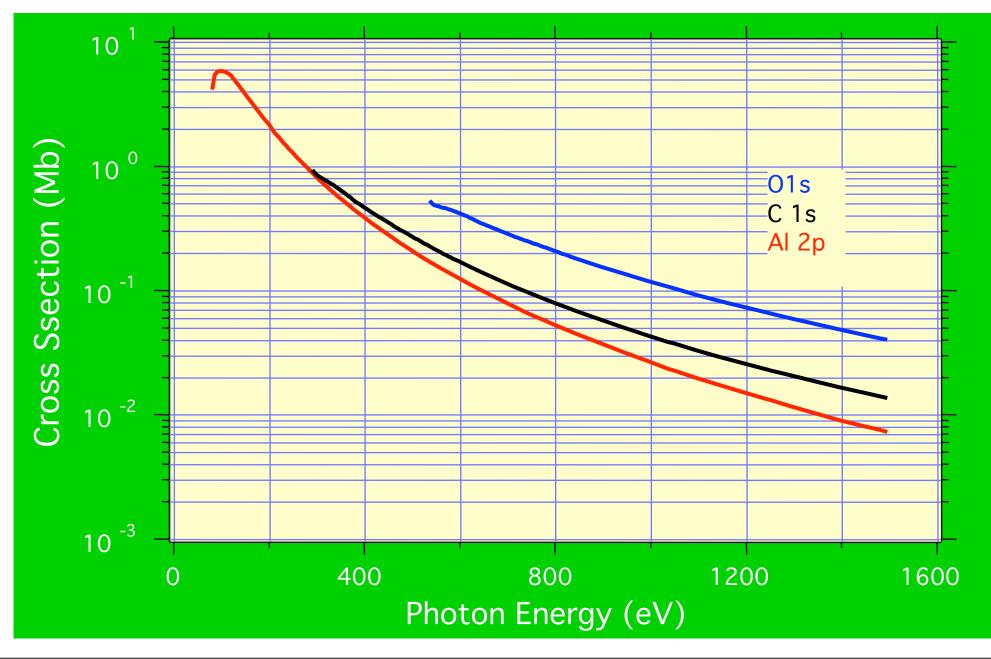
#### A laboratory source:

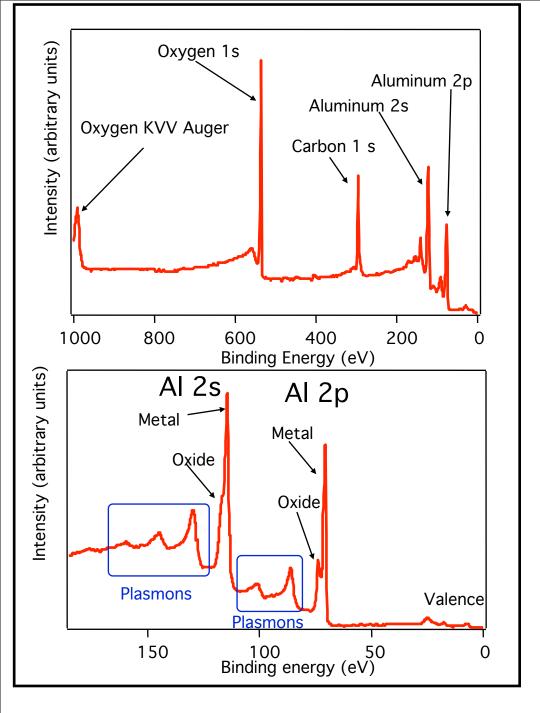
the Mg K emission region before (dots) and after subtraction of the dashed background (line).

# **Electron mean free path**



## Photoemission atomic cross section



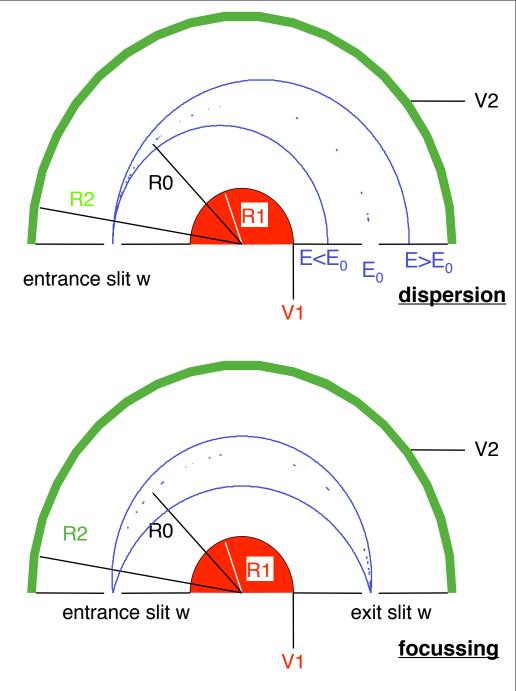


The photoemission spectrum of a "dirty" aluminum sample is dominated by the oxygen 1s level. The core levels of oxidized aluminum show a shift with respect to the metal. The spherical electron energy analyzer

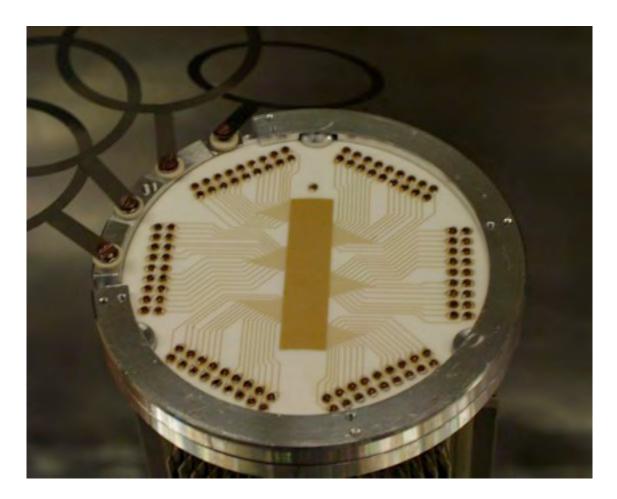


The pass energy  $E_0$  is the energy at which electrons follow a circular trajectory

$$E_{0} = \frac{2\Delta V}{R_{0}} \left(\frac{1}{R_{1}} - \frac{1}{R_{2}}\right)^{-1}$$



# **Position sensitive detection**



The hamiltonian for a system with an external em field, described by a vector potential  $\hat{A}$  and a scalar potential  $\phi$  is:

$$H = \frac{1}{2m} \left( \vec{p} + e \frac{\vec{A}(\vec{r},t)}{c} \right)^2 - e\phi(\vec{r},t) + V(\vec{r})$$

With the transverse gauge (no charges, no currents)

$$\vec{\nabla} \cdot \vec{A} = 0 \phi(\vec{r}, t) = 0$$
 
$$\Rightarrow \nabla^2 \vec{A} + \frac{1}{c^2} \frac{\partial^2 \vec{A}}{\partial t^2} = 0$$

So the hamiltonian becomes:

$$H = \frac{1}{2m}p^{2} + \frac{e}{2mc}\left(\vec{p}\cdot\vec{A} + \vec{A}\cdot\vec{p}\right) - \frac{e}{2mc^{2}}A^{2} + V(\vec{r})$$

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$$\{\vec{p},\vec{A}\}=0$$

The hamiltonian for a system with an external em field, described by a vector potential A and a scalar potential  $\phi$  is:

$$H = \frac{1}{2m} \left( \vec{p} + e \frac{\vec{A}(\vec{r},t)}{c} \right)^2 - e\phi(\vec{r},t) + V(\vec{r})$$

With the transverse gauge (no charges, no currents)

$$\vec{\nabla} \cdot \vec{A} = 0$$
  
$$\phi(\vec{r}, t) = 0$$
  $\rightarrow \nabla^2 \vec{A} + \frac{1}{c^2} \frac{\partial^2 \vec{A}}{\partial t^2} = 0$ 

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$$\{\vec{p},\vec{A}\} = 0 \qquad ~\mathbf{0}$$

$$H = \frac{1}{2m}p^2 + \frac{e}{mc}\vec{A}\cdot\vec{p} + V(\vec{r})$$

We can write:

$$H = H_0 + H_1$$

where

$$H_1 = \frac{ie\hbar}{mc}\vec{A}\cdot\vec{\nabla}$$

is the perturbation.

The incoming radiation can be described as a superposition of plane waves of the form:

$$\vec{A}(\vec{r},t) = \vec{A}_{\omega} e^{i(\vec{q}\cdot\vec{r}-\omega t)}$$

We put all this into the time dependent perturbation theory to get:

$$c_{f,i} = -\frac{2\pi e}{mc} \vec{A}_{\omega} \cdot \langle f | e^{i\vec{q}\cdot\vec{r}} \vec{\nabla} | i \rangle \delta \left( \omega - \frac{E_f - E_i}{\hbar} \right)$$

For photoemission the wavelength  $\lambda = 2\pi/|q|$  is always much longer than the size of the atoms. So we can approximate the exponential with 1

$$c_{f,i} = -\frac{2\pi e}{mc}\vec{A}_{\omega}\cdot\langle f|\vec{\nabla}|i\rangle\delta\left(\omega - \frac{E_f - E_i}{\hbar}\right) = -\frac{2\pi i e}{mc\hbar}\vec{A}_{\omega}\cdot\langle f|\vec{p}|i\rangle\delta\left(\omega - \frac{E_f - E_i}{\hbar}\right)$$

this formula represents the so-called dipole approximation

We define the photoionization cross section:

$$\sigma(\hbar\omega) = \frac{P(\hbar\omega)}{I(\hbar\omega)}$$

where  $P(\hbar\omega)$  is the number of photons absorbed by one atom per unit time at photon energy  $\hbar\omega$  (phot×s<sup>-1</sup>) and  $I(\hbar\omega)$  is the incident photon flux (phot×s<sup>-1</sup>×cm<sup>-2</sup>)

For a medium with *n* atoms per unit volume and photons traveling a distance *dx* 

$$\frac{dI}{I} = -n\sigma dx$$

or

$$I(x) = I_0 e^{-n\sigma x}$$

$$\eta = \frac{2\omega\kappa}{c} = n\sigma$$

 $\sigma$  is generally measured in Megabarn (Mb, 1Mb=10<sup>-18</sup>cm<sup>2</sup>)

For a spherically symmetric system (isolated atom) the initial and final states can be expressed as product of a radial and angular part:

$$\Psi_i(\vec{r}) = \tilde{R}_{l_i}^i(r) Y_{L_i}(\hat{r})$$

$$\Psi_f(\vec{r}) = 4\pi \sum_L Y_L^*(\hat{k}_f) i^{-l} e^{i\delta_l} \tilde{R}_l^f(r) Y_L(\hat{r})$$

The  $\Psi_f$  can also be regarded as

$$\Psi_f(\vec{r}) = e^{-i\vec{k}_f \cdot \vec{r}} + f(E_f, \vec{k}_f) \frac{e^{ik_f r}}{r}$$

For a spherically symmetric system (isolated atom) the initial and final states can be expressed as product of a radial and angular part obtaining:

$$\frac{d\sigma_{nl}(hv)}{d\Omega} = \frac{\sigma_{nl}(hv)}{4\pi} \Big[ 1 + \beta P_2(\cos\gamma) \Big]$$

In which

$$\sigma_{nl}(hv) = \frac{4\pi^2 \alpha a_0^2}{3} \frac{N_{nl}}{2l+1} hv \Big[ lR_{l-1}^2(\varepsilon_k) + (l+1)R_{l+1}^2(\varepsilon_k) \Big]$$

and

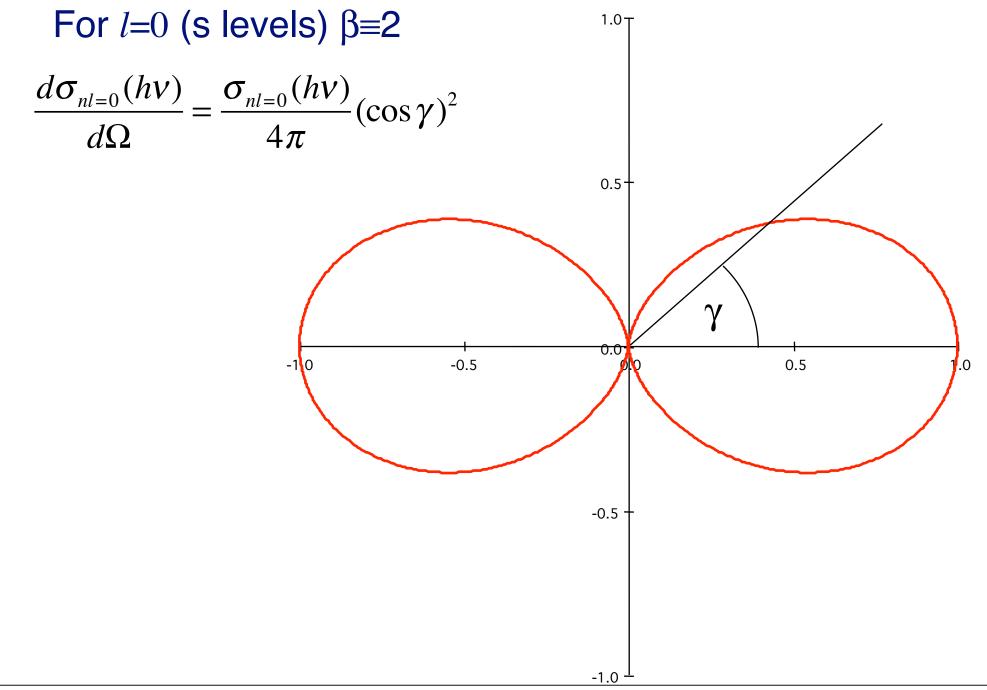
$$R_{l\pm 1}(\varepsilon) = \int_{0}^{\infty} \tilde{R}_{l}^{i}(r) r \tilde{R}_{l\pm 1}^{f}(r) dr$$

For spherically symmetric systems (free atoms) the well known selection rules  $(\Delta l = \pm 1)$  apply.

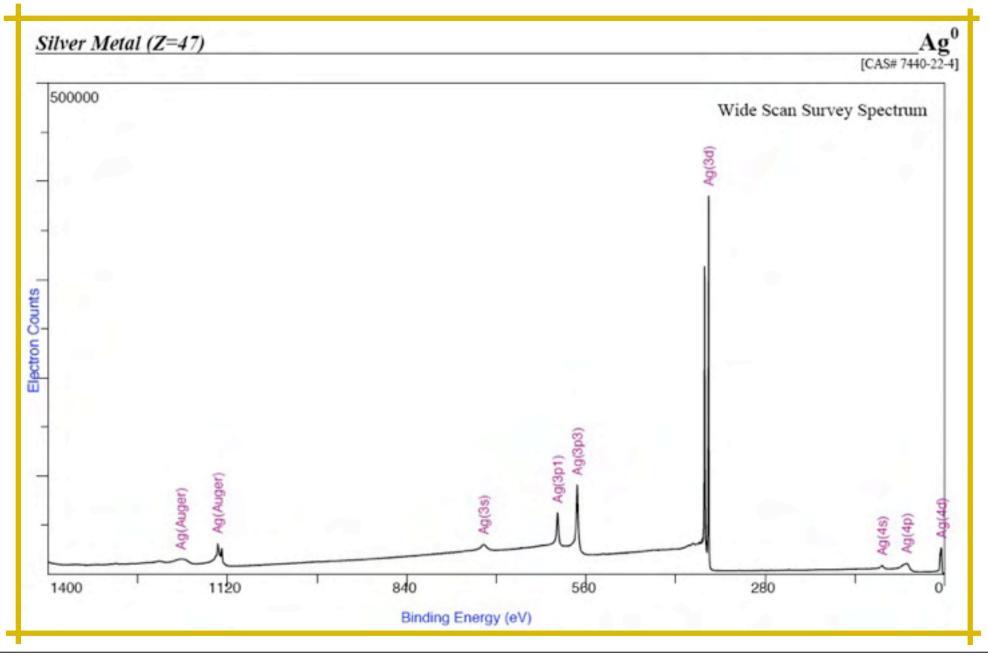
One can write the intensity for emission at a given angle  $\gamma$  from the polarization of the beam in the following form

$$\frac{d\sigma_{nl}(hv)}{d\Omega} = \frac{\sigma_{nl}(hv)}{4\pi} \left[1 + \beta P_2(\cos\gamma)\right]$$
  
$$\sigma_{nl}(hv) = \frac{4\pi^2 \alpha a_0^2}{3} \frac{N_{nl}}{2l+1} hv \left[lR_{l-1}^2(\varepsilon_k) + (l+1)R_{l+1}^2(\varepsilon_k)\right]$$
  
$$P_2(\cos\gamma) = \frac{3\cos^2\gamma - 1}{2}$$
  
This term controls the weigh of  $\Delta l = +1$  and  $\Delta l = -1$  channels  $-1 \le \beta \le 2$ 

At  $\gamma$ =54.7° (magic angle) P<sub>2</sub>=0: the measurement is independent of  $\beta$ For *l*=0 (s levels)  $\beta$ =2

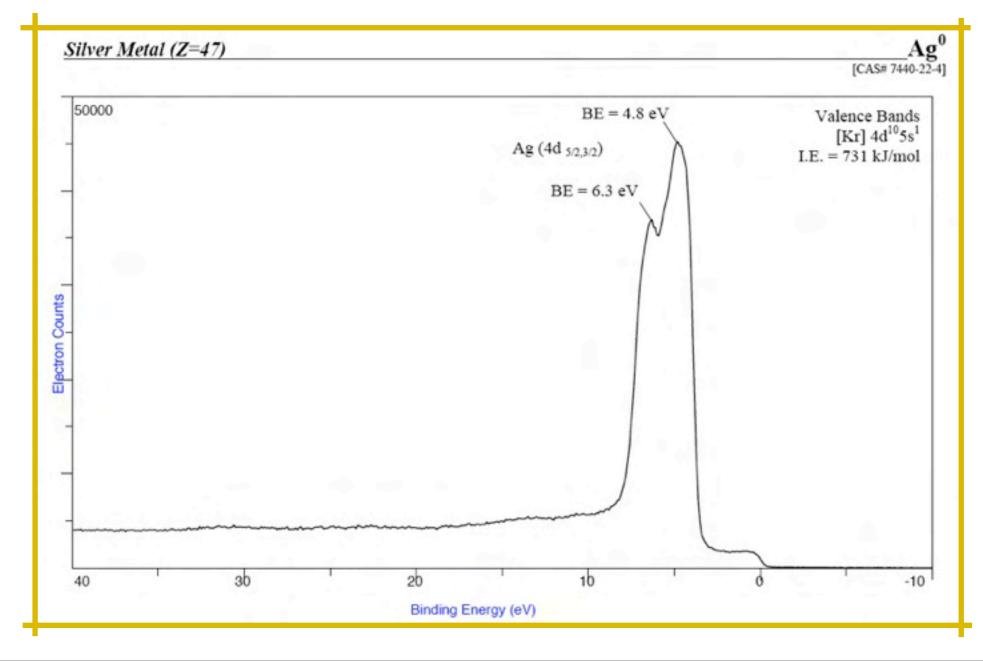


#### The Ag XPS spectrum



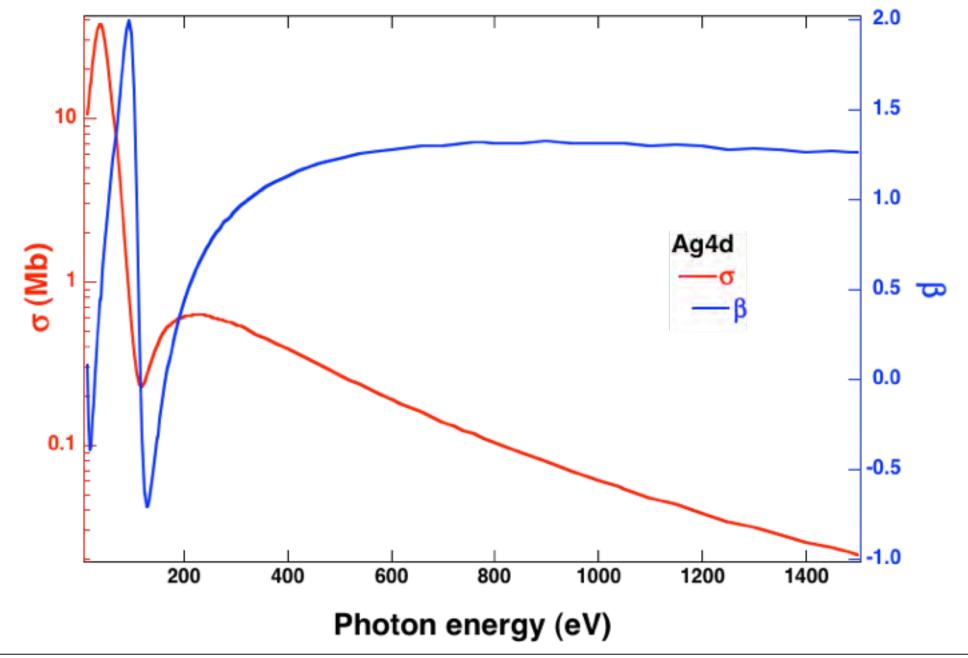
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#### The Ag XPS spectrum



**Example: the Ag 4d level** 

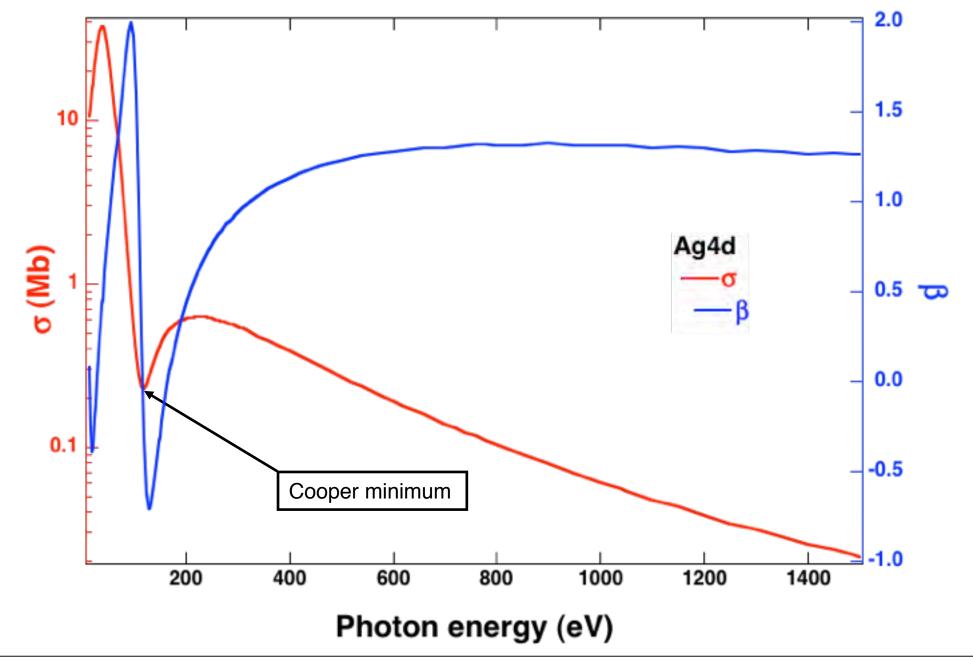
(from J.J. Yeh: "Atomic calculation of photoionization cross sections and asymmetry parameters", Gordon Breach)

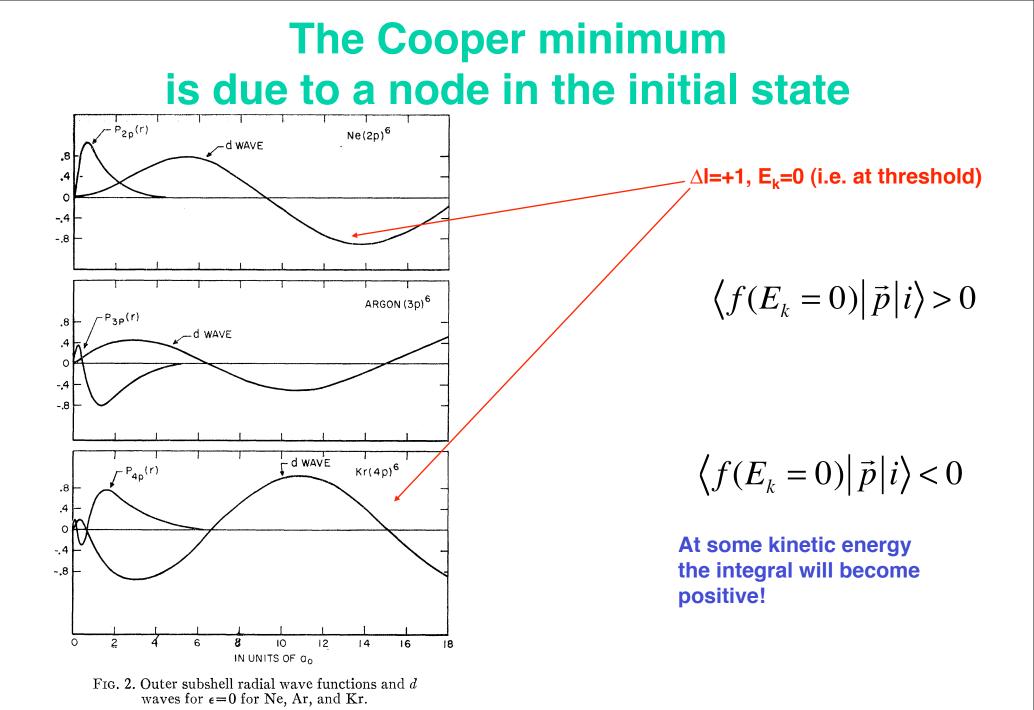


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**Example: the Ag 4d level** 

(from J.J. Yeh: "Atomic calculation of photoionization cross sections and asymmetry parameters", Gordon Breach)





### **The Cooper minimum**

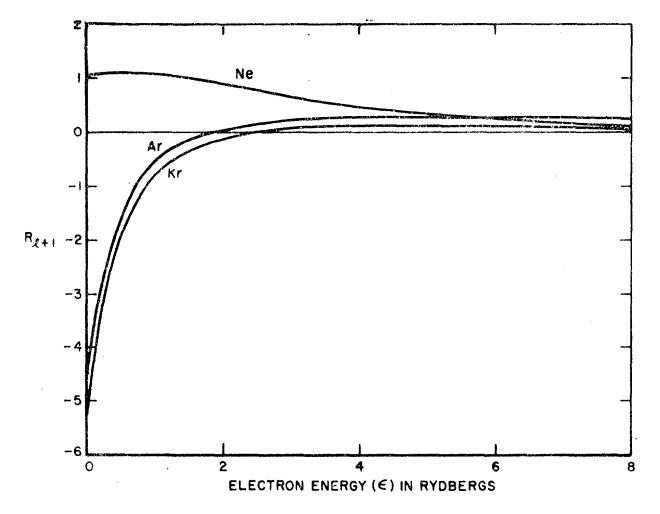
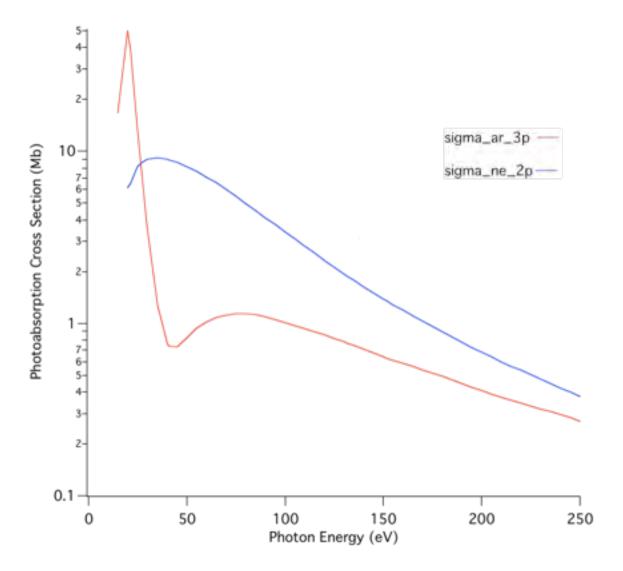


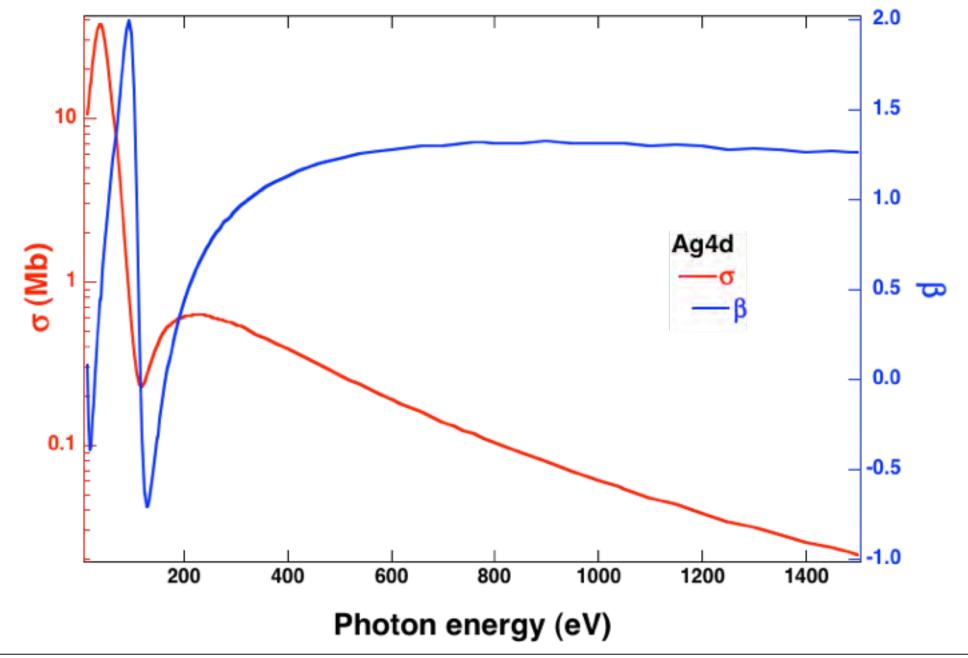
FIG. 3. Matrix elements for  $p \rightarrow d$  transitions in Ne, Ar, and Kr.

### **The Cooper minimum**



**Example: the Ag 4d level** 

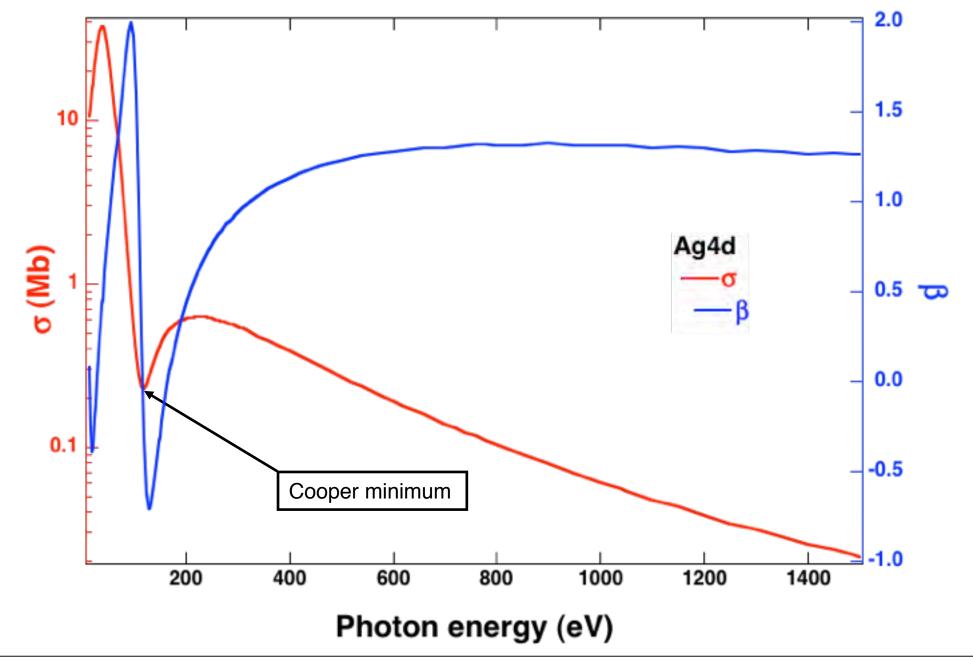
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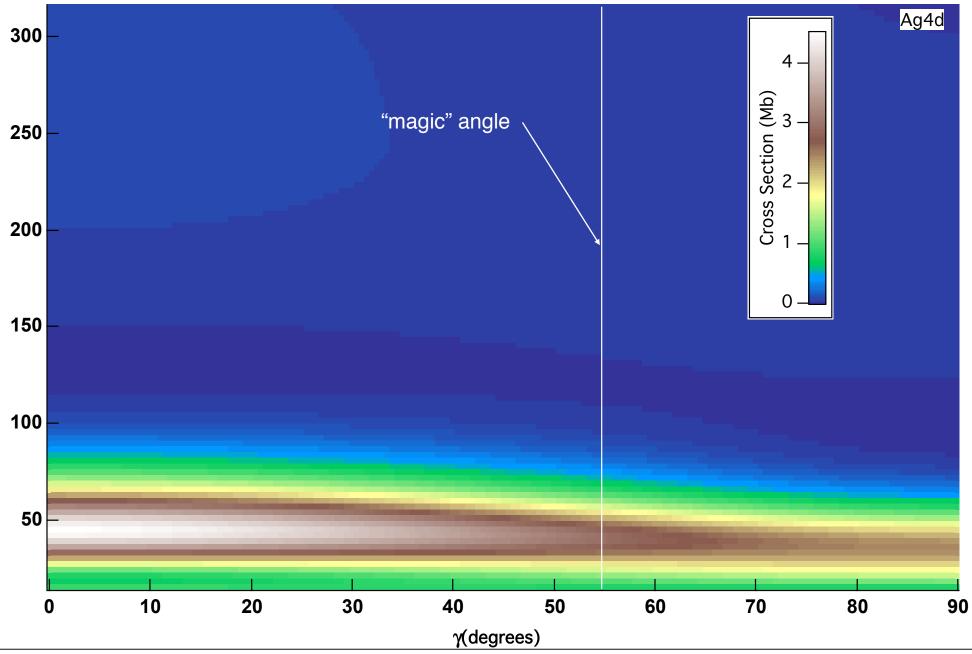
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**Example: the Ag 4d level** 

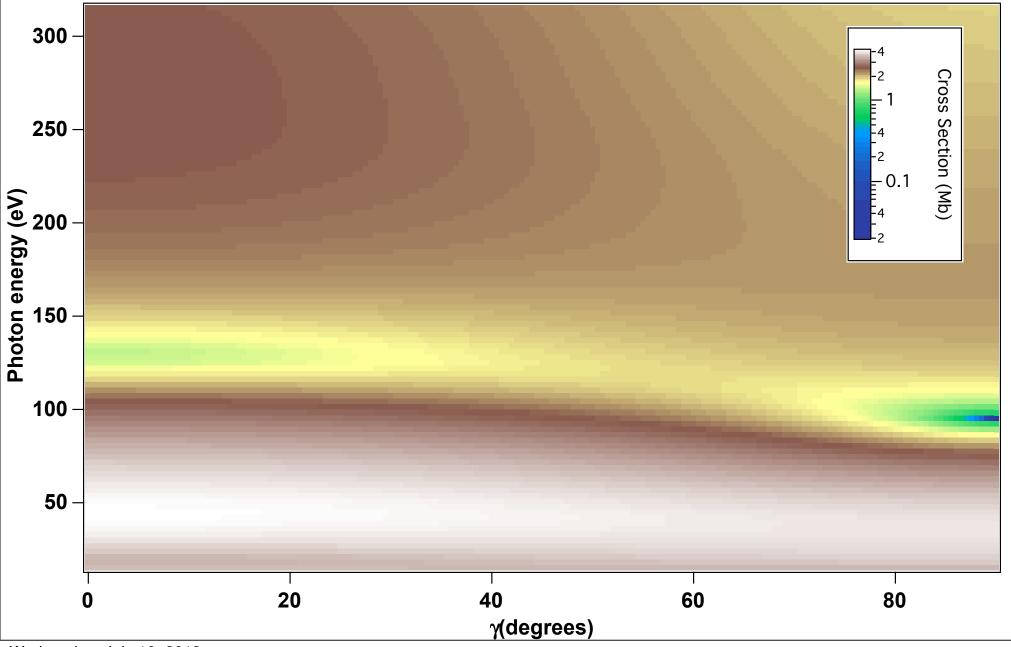
(from J.J. Yeh: "Atomic calculation of photoionization cross sections and asymmetry parameters", Gordon Breach)



#### Example: the Ag 4d level

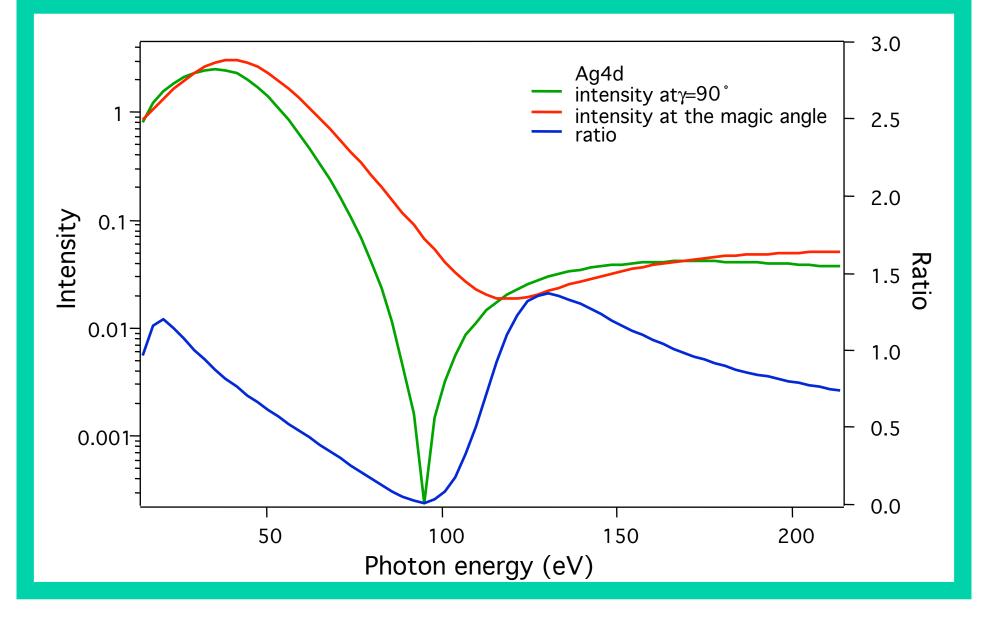


#### Example: the Ag 4d level (log scale)



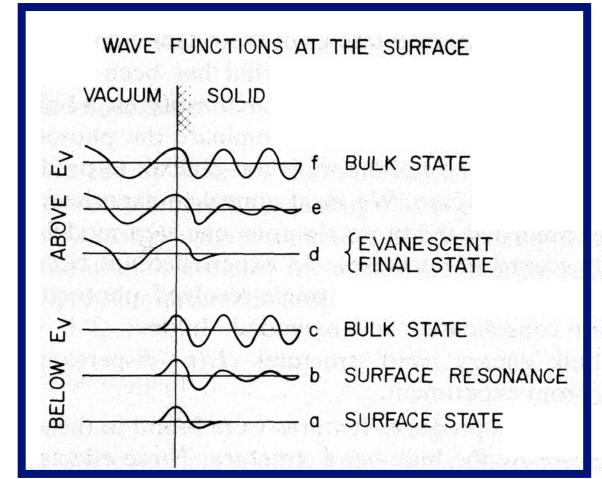
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#### Example: the Ag 4d level



Valence band angle resolved photoemission (ARUPS)

- Bulk and surface states
- Band mapping
- Selection rules
  - determination of the symmetry
  - determination of adsorption geometry



Schematic representation of the wave functions of initial states (a), (b) and (c), and final states (d), (e) and (f), involved in optical transitions giving rise to photoelectron emission. States (c) and (f) correspond to bulk Bloch states hardly modified by the presence of the surface. States (b) and (e) are more strongly evanescent (surface resonances). States (a) and (d) have essentially no amplitude in the interior of the solid and correspond respectively to a true bound surface state and the case of band-gap emission.



## **Photoexcitation process: Momentum conservation**

Photon Momentum Photon Energy

$$p = \hbar q = h / \lambda$$
  

$$E = hv = hc / \lambda$$
  

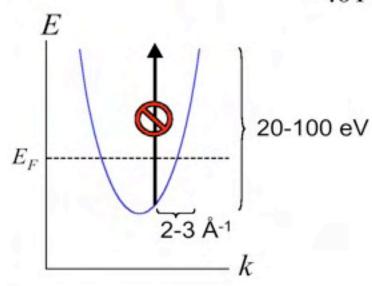
$$q = 2\pi \frac{E}{R} = 2\pi \frac{E[eV]}{R}$$

Typical photon wavenumber

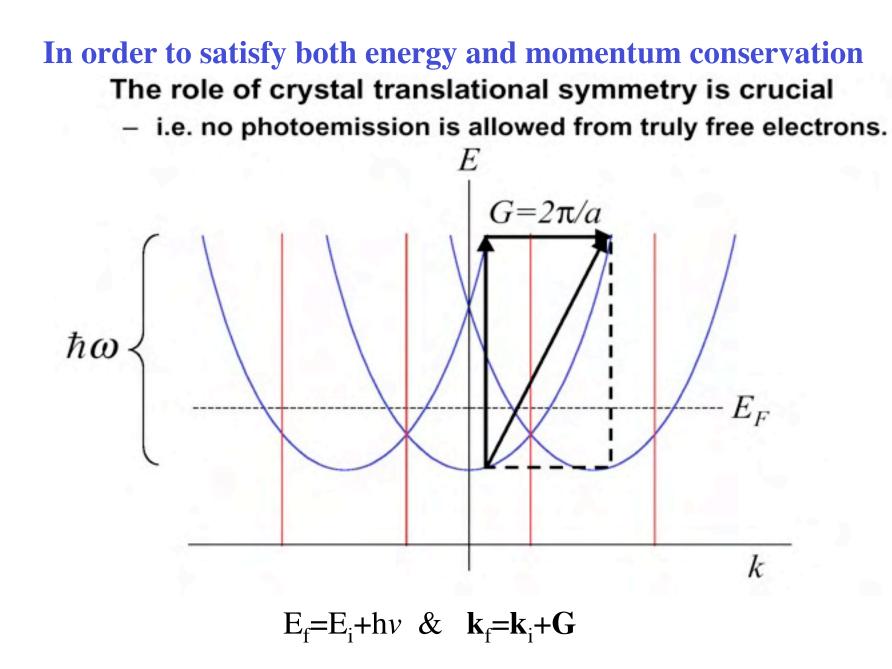
$$E = hV = hc / \lambda$$

$$q = 2\pi \frac{E}{hc} = 2\pi \frac{E \text{ [eV]}}{12400 \text{ [eV - Å]}}$$

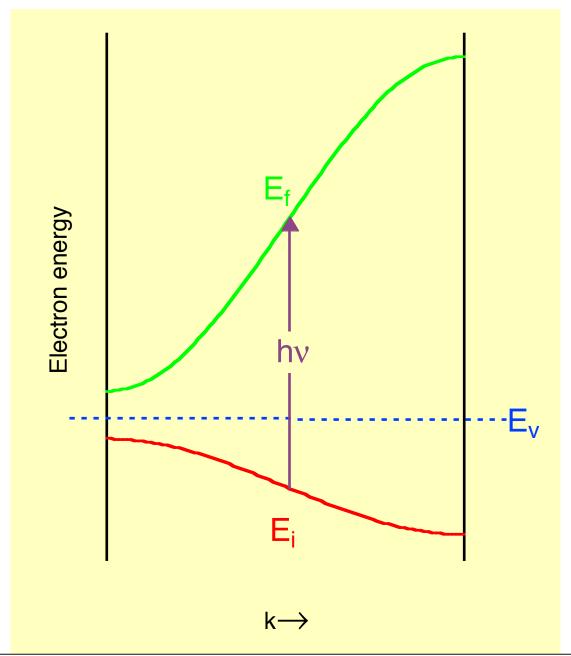
$$= .01 \text{ to } .05 \text{ Å}^{-1} \text{ (for } E = 20 \text{ to } 100 \text{ eV}$$



- The photons impart very little momentum in the photoemission process, i.e. vertical transitions
- Therefore photon-stimulated transitions are not allowed for free electrons (energy and momentum conservation laws cannot be satisfied at the same time).

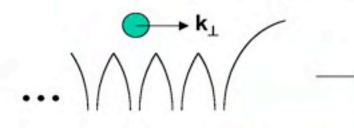


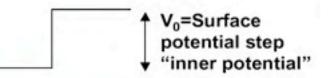
# **Direct transitions**



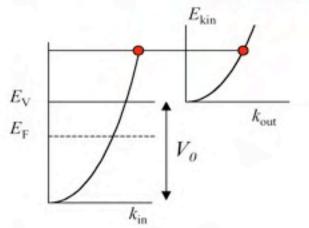
At the surface the crystal symmetry is conserved in the surface plane but is broken perpendicularly to the surface: the component of the electron momentum parallel to the surface plane  $(k_{//})$  is conserved, but  $k_{\perp}$  is not

The potential barrier at the surface slows the electron in the direction normal to the surface.





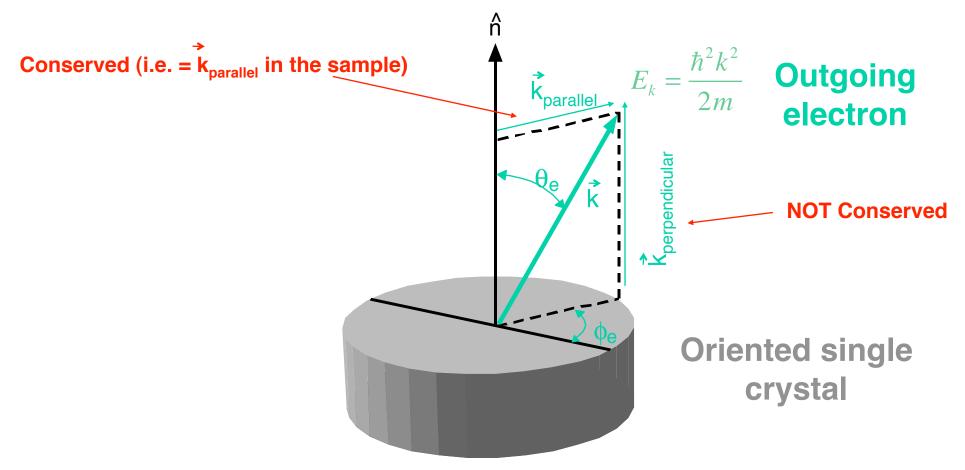
Free-electron final state model



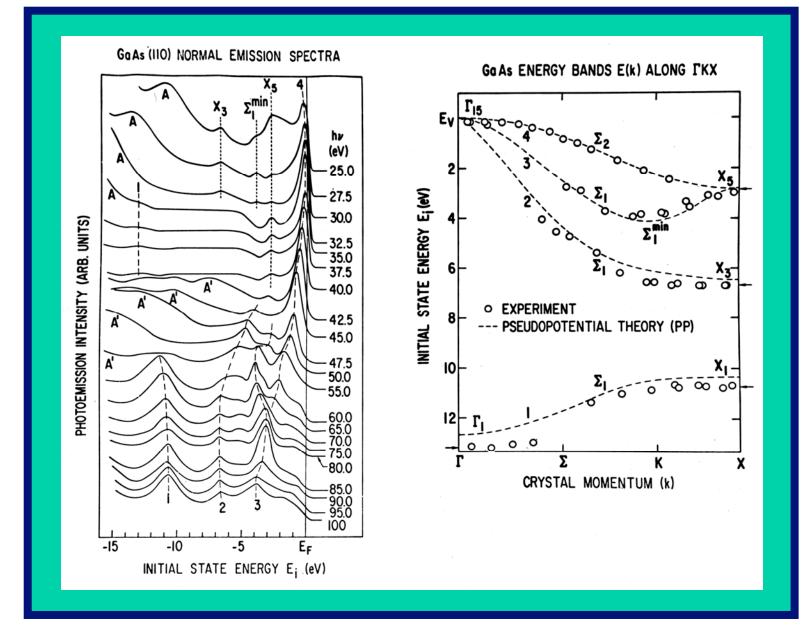
We match the free-electron parabolas inside and outside the solid to obtain the wavevector k inside the solid

# **Momentum conservation**

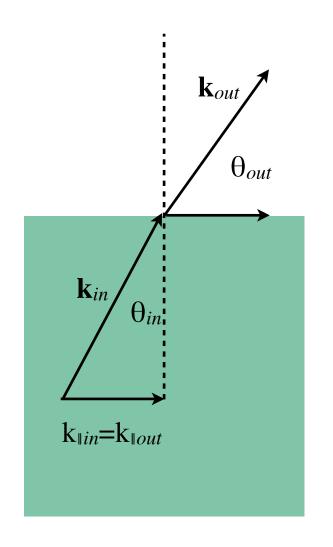
The surface breaks the traslational symmetry along  $\hat{\mathbf{n}}$ 



# **Band mapping: GaAs**



At the surface the crystal symmetry is conserved in the surface plane but is broken perpendicularly to the surface: the component of the electron momentum parallel to the surface plane  $(k_{//})$  is conserved, but  $k_{\perp}$  is not



Kinematic relations

$$k_{out} = \sqrt{\frac{2m^*}{\hbar^2}} E_{kin}$$
$$k_{in} = \sqrt{\frac{2m^*}{\hbar^2}} (E_{kin} + V_0)$$
$$k_{out\parallel} = k_{in\parallel} = k_{\parallel}$$

"Snell's law"

$$k_{\parallel} = \sin \theta_{out} \sqrt{\frac{2m^*}{\hbar^2} E_{kin}} = \sin \theta_{in} \sqrt{\frac{2m^*}{\hbar^2} (E_{kin} + V_0)}$$

Critical angle for emission from bulk states

$$(\sin\theta_{in})_{max} = \sqrt{\frac{E_{kin}}{E_{kin} + V_0}}$$

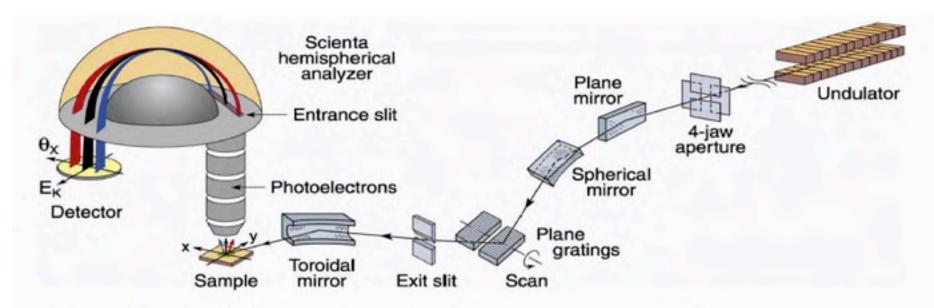
## **First important results:**

$$E_k = h\nu - |E_B| - \Phi_{Analyzer}$$

$$k_{//} = \sqrt{\frac{2m^* E_k}{\hbar^2}} \sin \theta_{out} \approx 0.512 \sqrt{E_k} \sin \theta_{out}$$

Band mapping is therefore completely determined for 2D systems and surface states for which  $k_{//}$  is a good quantum number

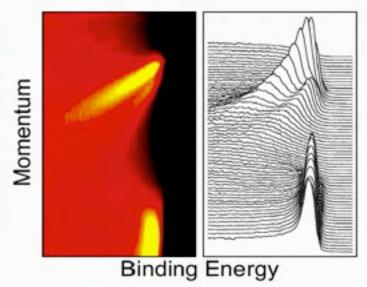
## State-of-the-art



## Parallel multi-angle recording

- Improved energy resolution
- Improved momentum resolution
- Improved data-acquisition efficiency

	$\Delta E (meV)$	$\Delta \theta$
past	20-40	2°
now	2-10	0.2°

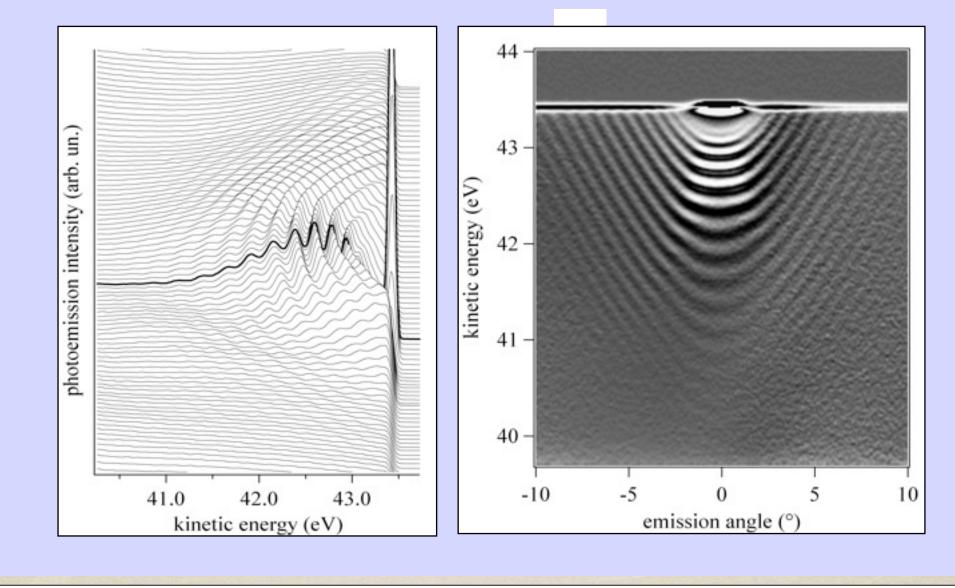


courtesy of A. Damascelli

Mapping Two-dimensional band  $E = E(k_{par})$ 



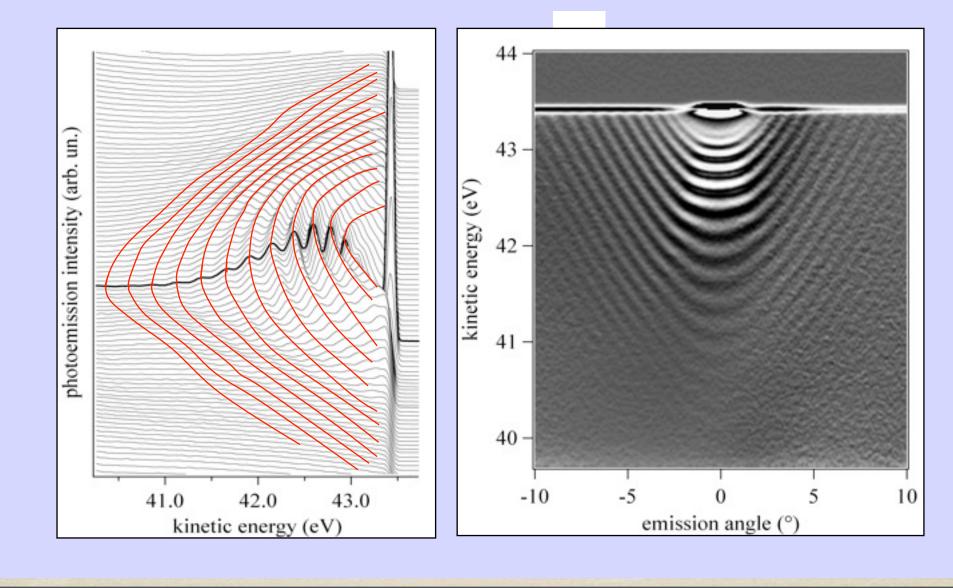
## Discrete quantum well states of an atomically flat 150 Å Ag film on Pt(111)







## Discrete quantum well states of an atomically flat 150 Å Ag film on Pt(111)

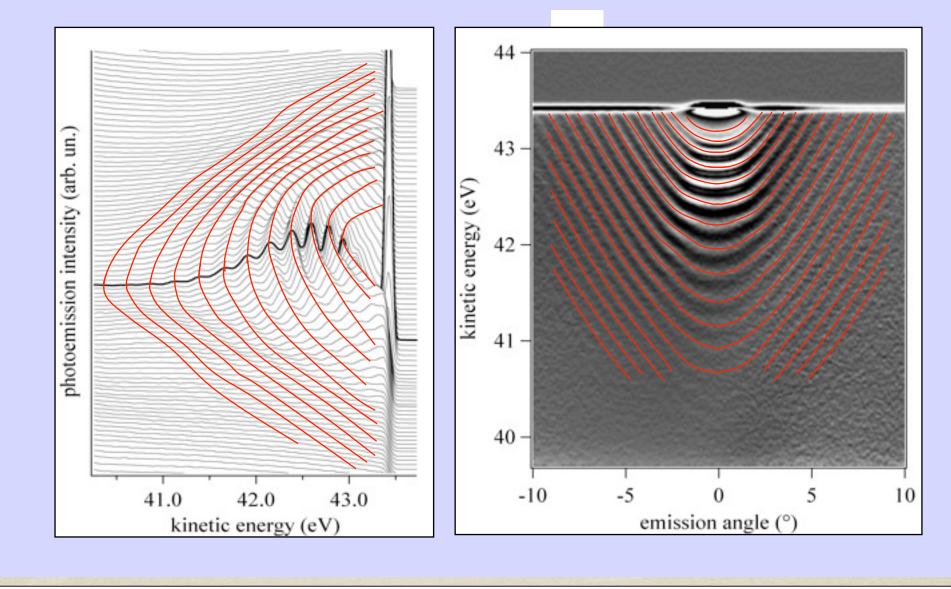


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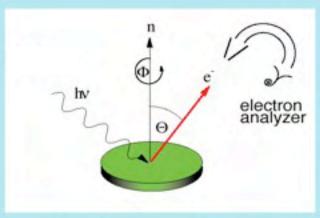


## Discrete quantum well states of an atomically flat 150 Å Ag film on Pt(111)



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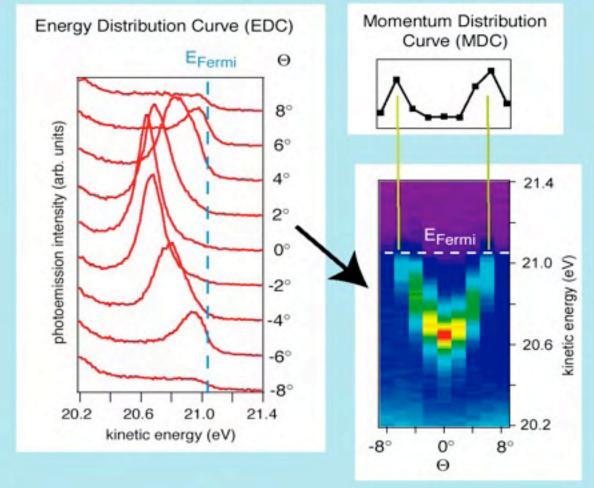
### Angle-resolved photoemission from (quasi) 2D systems: a simple picture



measure E<sub>kin</sub>, Θ, Φ.

$$k_x = \sqrt{\frac{2m}{\hbar^2}} \sin \Theta \cos \Phi \sqrt{E_{kin}}$$
$$k_y = \sqrt{\frac{2m}{\hbar^2}} \sin \Theta \sin \Phi \sqrt{E_{kin}}$$

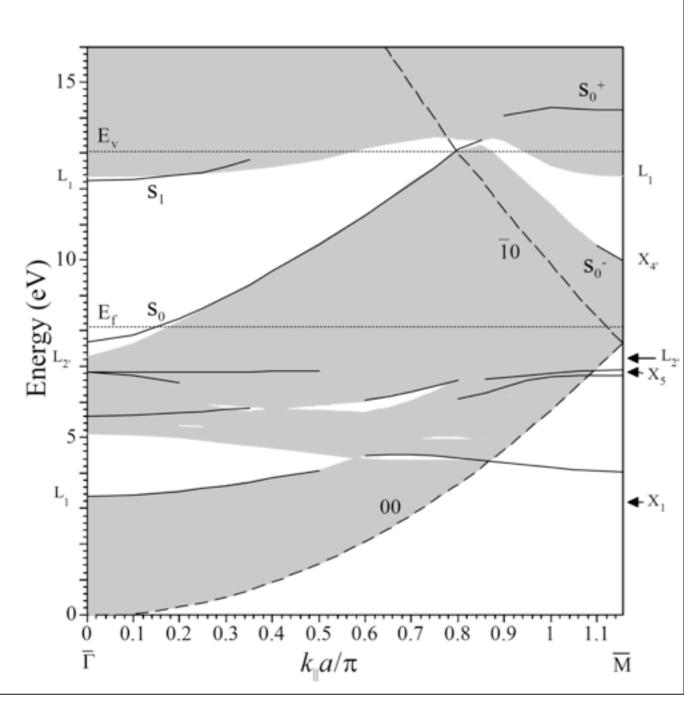
obtain E<sub>bin</sub>(k<sub>x</sub>,k<sub>y</sub>), i.e. the occupied band structure



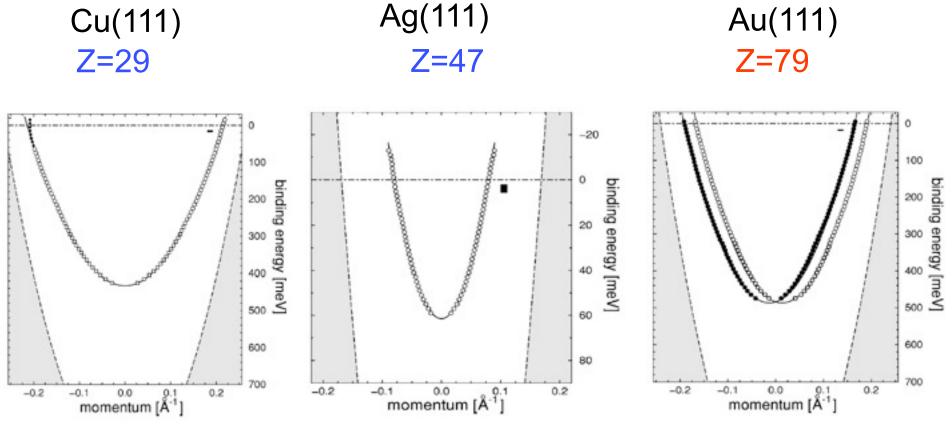
#### Example: Cu(111) surface state

Courtesy of Ph. Hofmann

# Cu (111) surface band structure



## Shockley Surface States of Noble Metal (111) Surfaces

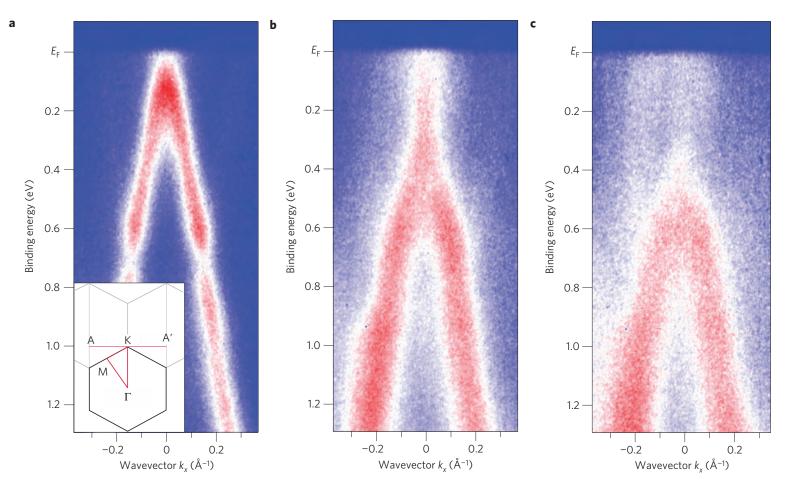


Two parabolas: spin-orbit splitting

PES Experiment, Reinert, Nicolay, Ehm, and Hüfner, PRB 63, 115415 (2001)

# Bandgap opening in graphene induced by patterned hydrogen adsorption

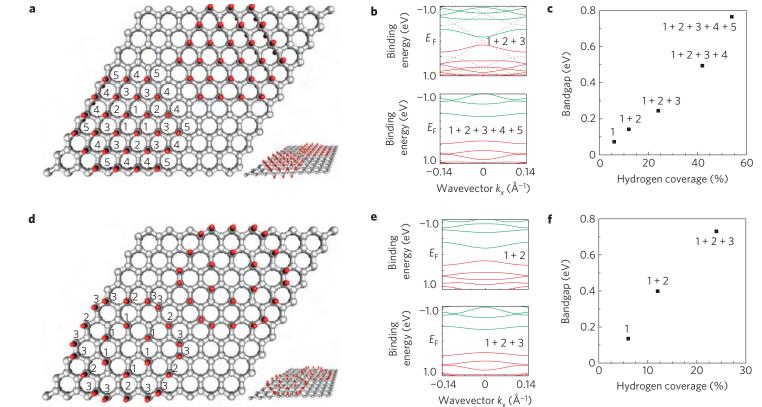
Richard Balog<sup>1</sup>, Bjarke Jørgensen<sup>1</sup>, Louis Nilsson<sup>1</sup>, Mie Andersen<sup>1</sup>, Emile Rienks<sup>2</sup>, Marco Bianchi<sup>3</sup>, Mattia Fanetti<sup>4</sup>, Erik Lægsgaard<sup>1</sup>, Alessandro Baraldi<sup>3,4</sup>, Silvano Lizzit<sup>5</sup>, Zeljko Sljivancanin<sup>6</sup>, Flemming Besenbacher<sup>1</sup>, Bjørk Hammer<sup>1</sup>, Thomas G. Pedersen<sup>7</sup>, Philip Hofmann<sup>2</sup> and Liv Hornekær<sup>1\*</sup>



**Figure 1** | **Observation of a gap opening in hydrogenated graphene. a**-**c**, Photoemission intensity along the A-K-A' direction of the Brillouin zone (see inset) for clean graphene on Ir(111) (**a**), graphene exposed to a 30 s dose of atomic hydrogen (**b**) and graphene exposed to a 50 s dose of atomic hydrogen (**c**).

# Bandgap opening in graphene induced by patterned hydrogen adsorption

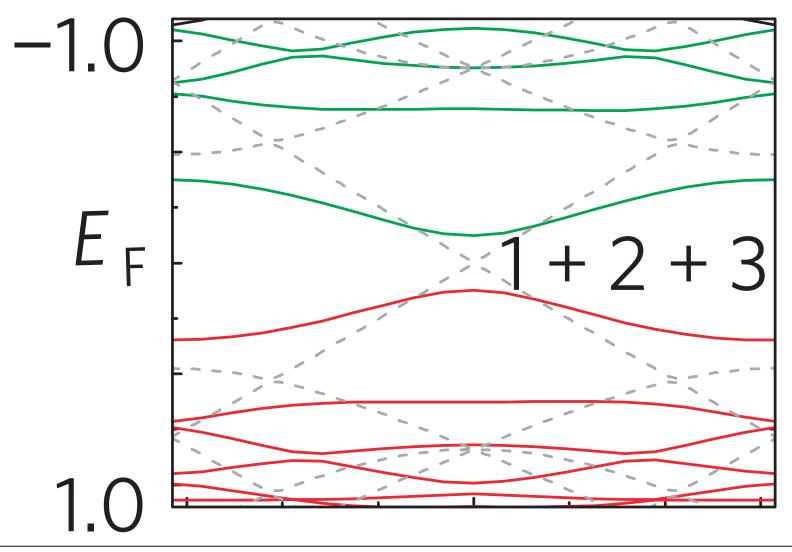
Richard Balog<sup>1</sup>, Bjarke Jørgensen<sup>1</sup>, Louis Nilsson<sup>1</sup>, Mie Andersen<sup>1</sup>, Emile Rienks<sup>2</sup>, Marco Bianchi<sup>3</sup>, Mattia Fanetti<sup>4</sup>, Erik Lægsgaard<sup>1</sup>, Alessandro Baraldi<sup>3,4</sup>, Silvano Lizzit<sup>5</sup>, Zeljko Sljivancanin<sup>6</sup>, Flemming Besenbacher<sup>1</sup>, Bjørk Hammer<sup>1</sup>, Thomas G. Pedersen<sup>7</sup>, Philip Hofmann<sup>2</sup> and Liv Hornekær<sup>1\*</sup>



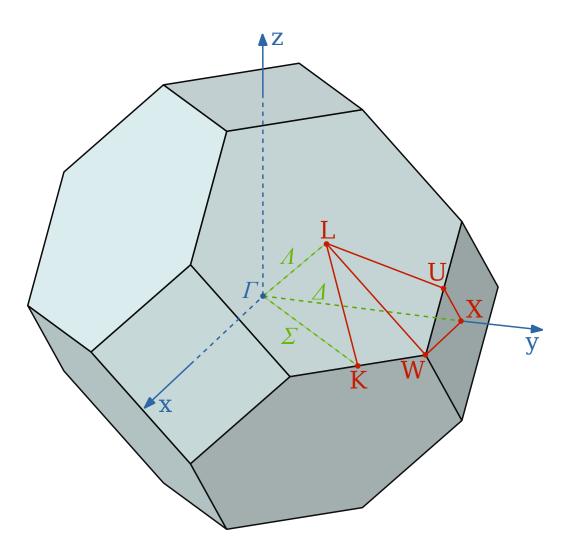
**Figure 4 | Hydrogen adsorbate structures, calculated band structures and bandgaps. a**, Hydrogen atom adsorbate structures forming graphane islands with hydrogen coverage ranging between 6% and 54% (corresponding to 3%-27% of the top sites) following the Moiré superlattice periodicity. **b**, Band structures for graphane-like islands with medium and high hydrogen coverage. Filled and empty bands are shown in red and green, respectively. For comparison, the band structure of intact graphene is shown in grey (dashed). **c**, Bandgap opening as a function of hydrogen coverage. A maximum of 0.77 eV is reached with 54% coverage (corresponding to 27% top site coverage). **d**, Adsorbate structures composed of increasing amounts of hydrogen pairs in *para* and *ortho* dimer configurations. **e**, Band structures with and without *ortho*-hydrogen dimers. **f**, Bandgap opening as a function of hydrogen coverage a bandgap opening as large as 0.73 eV is obtained. In **b**, **c**, **e** and **f**, numbers 1–5 refer to absorbate structures formed by hydrogen atomes at all the positions marked by the corresponding numbers in **a** and **d** respectively.

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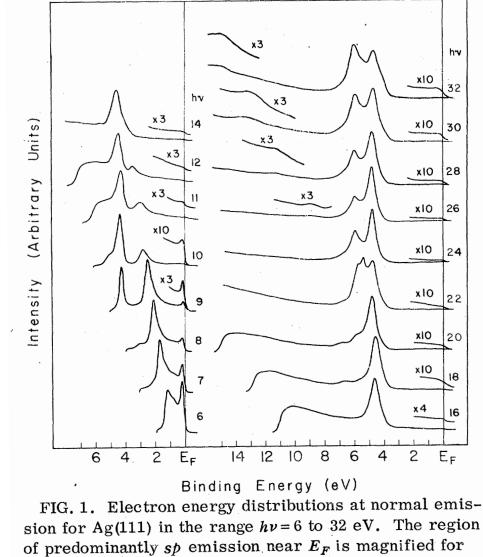


# The fcc Brillouin zone



#### Valence-band structure of silver along $\Lambda$ from angle-resolved photoemission

P. S. Wehner,\* R. S. Williams,<sup>†</sup> S. D. Kevan, D. Denley,<sup>‡</sup> and D. A. Shirley Materials and Molecular Research Division, Lawrence Berkeley Laboratory and Department of Chemistry, University of California, Berkeley, California 94720 (Received 20 November 1978)



#### of predominantly sp emission near $E_F$ is magnified for most spectra. For $h\nu = 26$ to 32 eV the region containing the constant final-state feature is also magnified.

# Ag band structure

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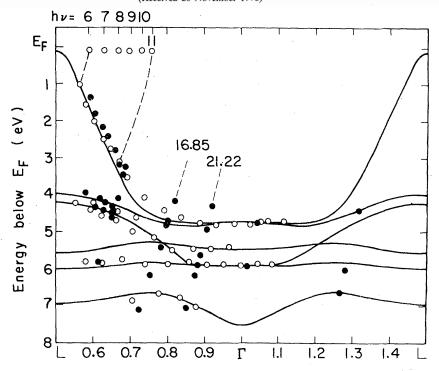


FIG. 2. Valence-band energies of silver along  $\Lambda$  vs the k point along  $\Lambda$  in the second zone that corresponds to each photoemission peak. A partial photon energy scale is indicated along the top, together with dashed curves for the conduction band (band 7) displaced down by 6 eV and by 10 eV. Christensen's band structure is plotted, together with our data (open circles) and those of Hansson and Flodström (filled circles from 7 to 11.6 eV); Roloff and Neddermeyer (filled circles at 11.83, 16.85, and 21.22 eV); and Liebowitz and Shevchik (filled circles at 26.9 and 40.8 eV).

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# Ag band structure

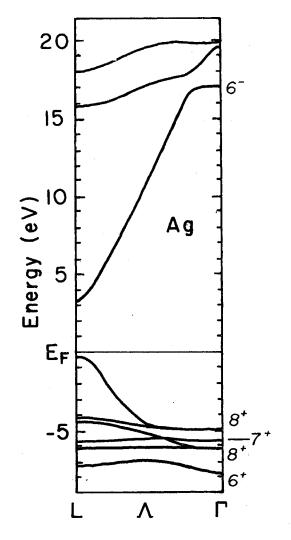
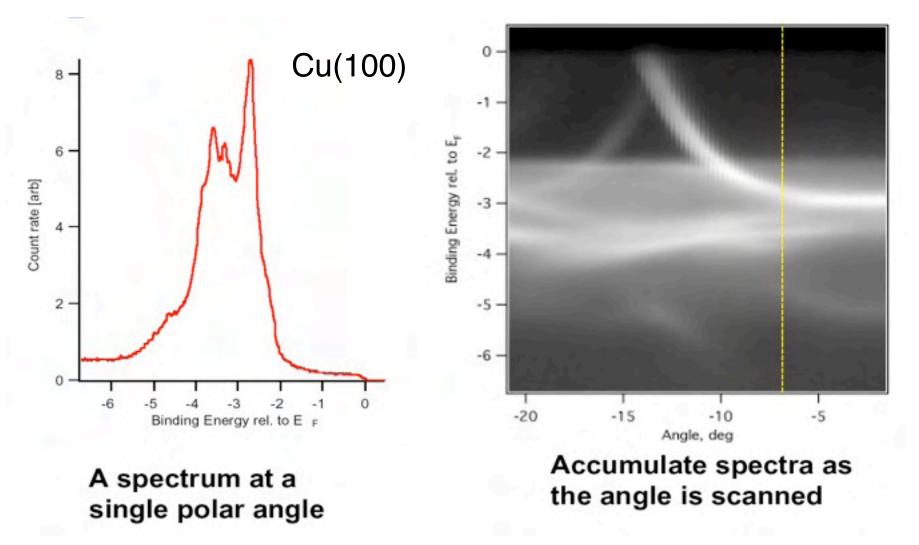
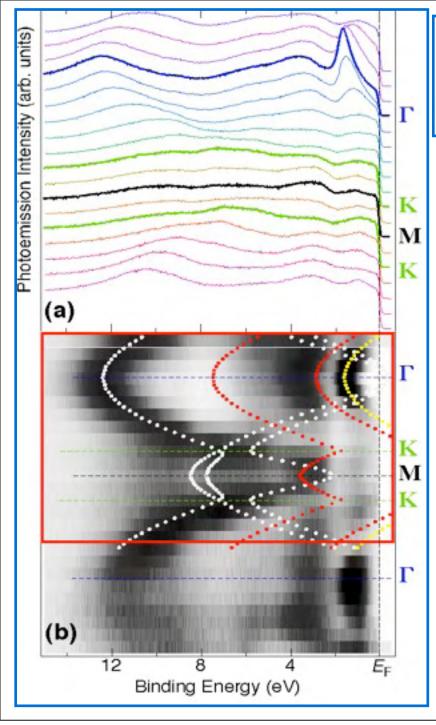


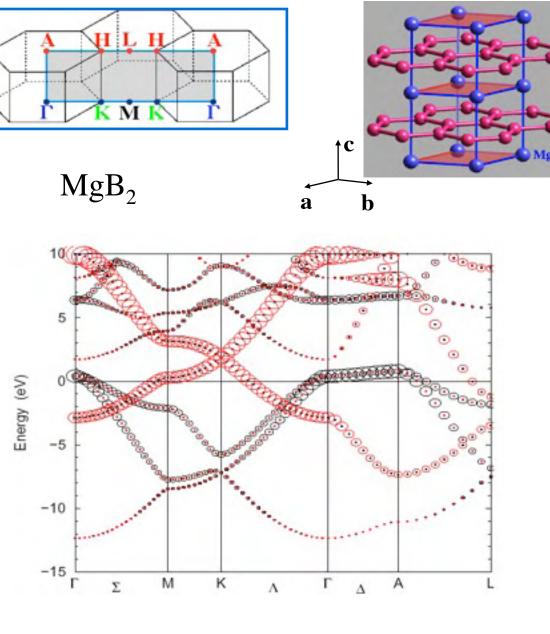
FIG. 5. Ag band structure along  $\Lambda$  as calculated in Ref. 15.

## What does a photoemission spectrum look like?



Bulk or surface states? Why are bulk bands quite sharp anyway?

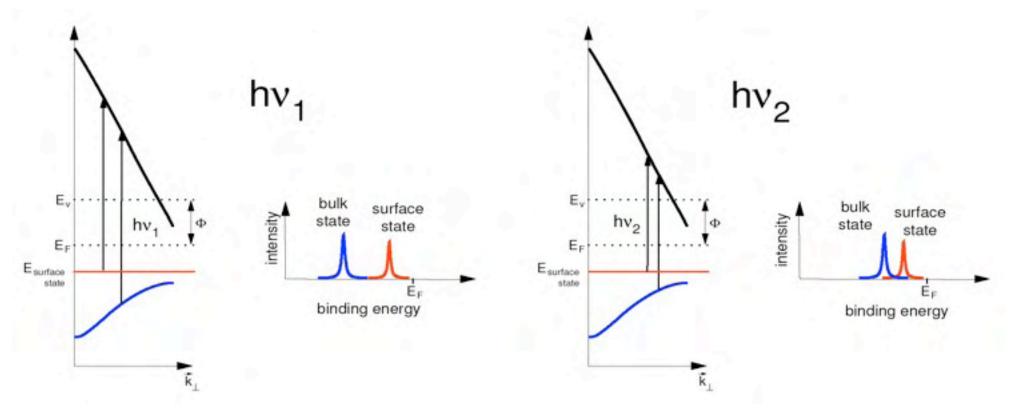




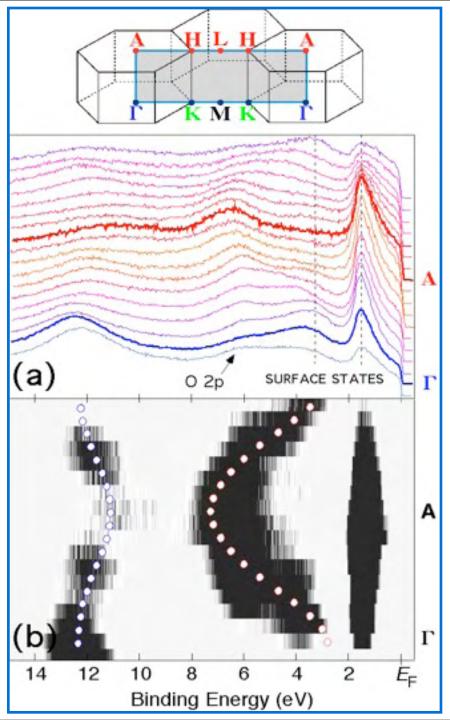
Photon energy: 105eV ( $\Delta E \approx 50meV$ ) in-plane dispersion along  $\Gamma - K - M - K - \Gamma$ 

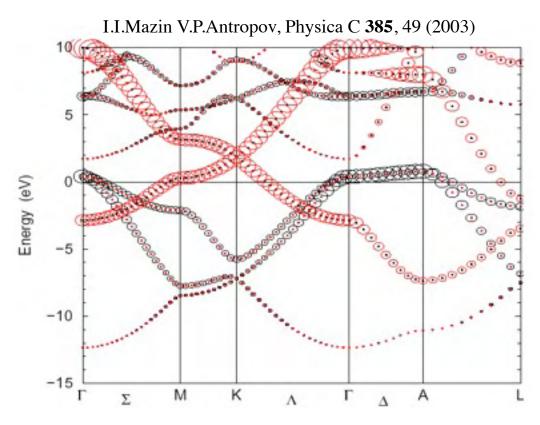
## **Recognize surface states from bulk bands**

fix  $\mathbf{k}_{//}$  and change  $\mathbf{k}_{-|-}$ . Bulk states should have dispersion, surface states should not.



**Easiest way:** fix  $\mathbf{k}_{I} = 0$  ( $\underline{\Gamma}$ , normal emission) and change the photon energy



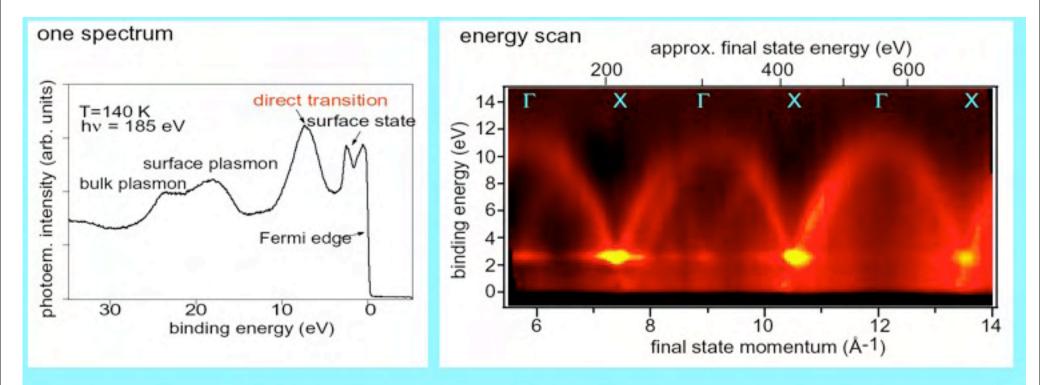


 $\Gamma$ -A direction Normal emission geometry Photon energy: 95 eV - 185 eV ( $\Delta E \approx 50$ meV) No dispersive peak at 1.65 eV: Mg terminated MgB<sub>2</sub>(0001) surface state

Weak no dispersive peak at 3.2 eV: B terminated MgB<sub>2</sub>(0001) surface state (B terminated domains)

# Surface states and k<sub>1</sub> mapping: example AI(100)

Photon energy changed at normal emission k<sub>//</sub>=0

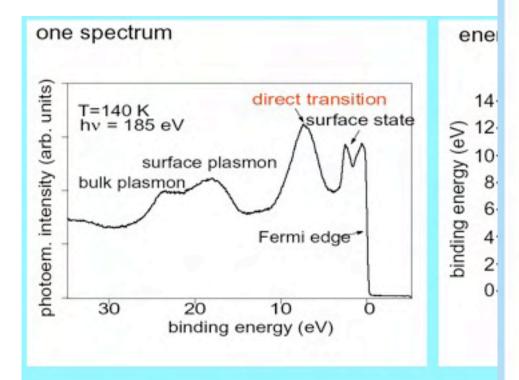


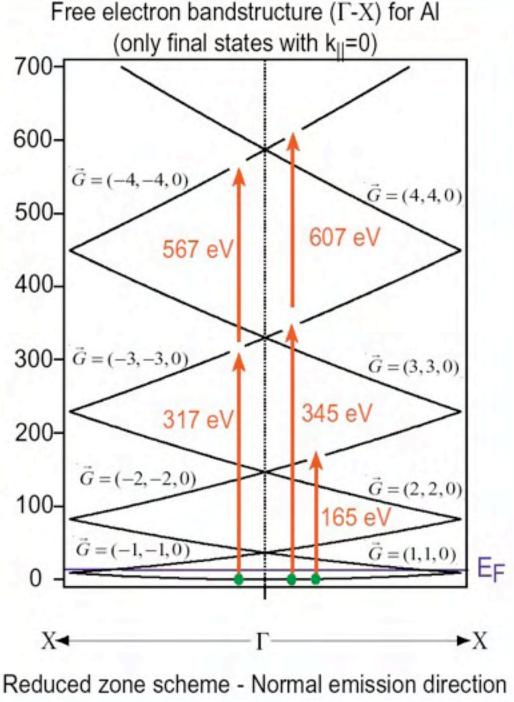
 The free electron-like band structure is evident but there are also some "ghost" bands caused by surface umklapp processes

The surface state intensity is observable at all energies but resonantly enhanced at the X points.

# Surface states and k<sub>1</sub> map example AI(100)

Photon energy changed at normal emission k



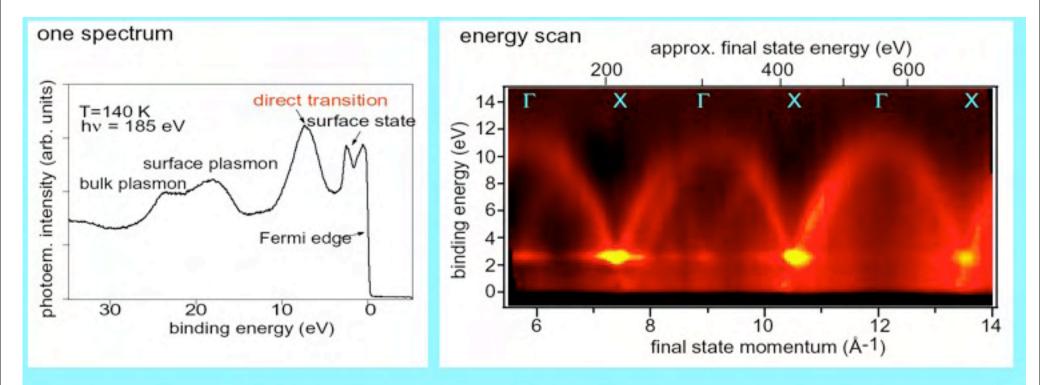


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# Surface states and k<sub>1</sub> mapping: example AI(100)

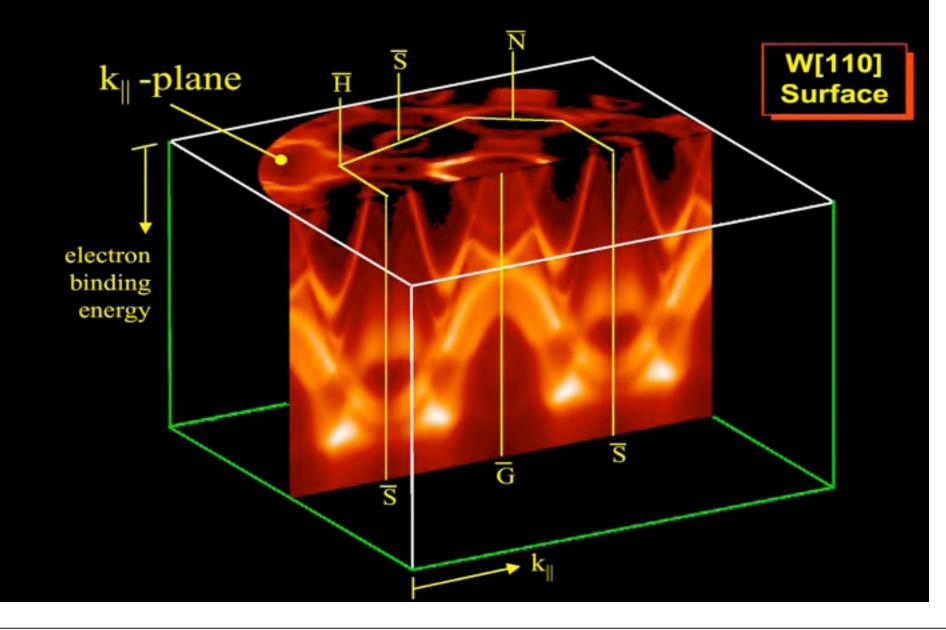
Photon energy changed at normal emission k<sub>//</sub>=0



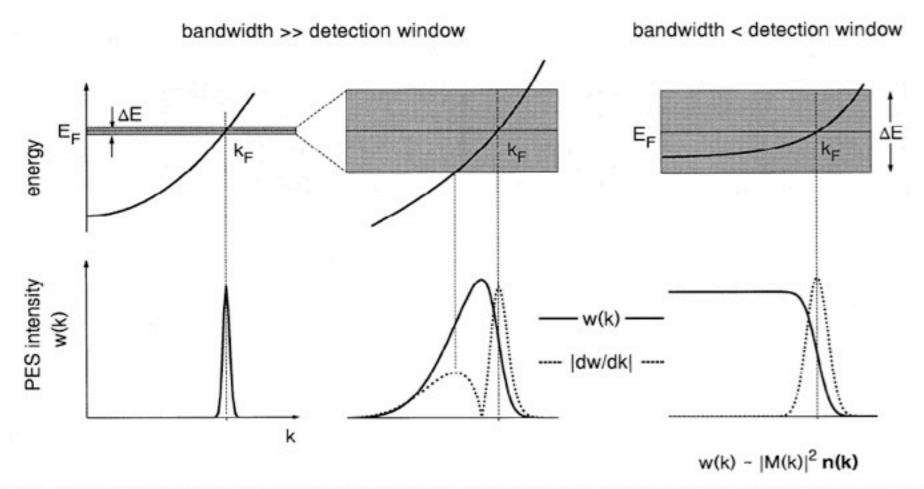
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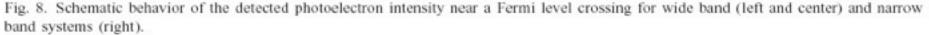
The surface state intensity is observable at all energies but resonantly enhanced at the X points.

# **Band Mapping and Fermi Contours**



## Determining Fermi vectors by angle resolved photoemission





## Determining Fermi vectors by angle resolved photoemission

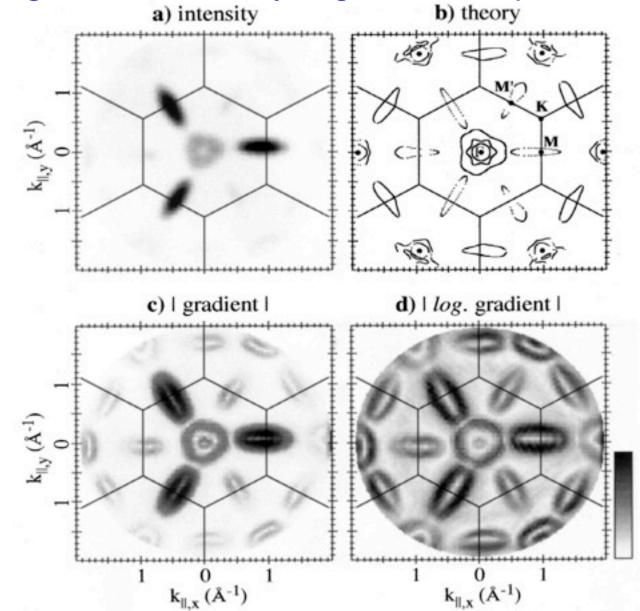
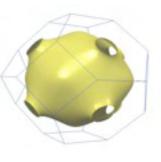


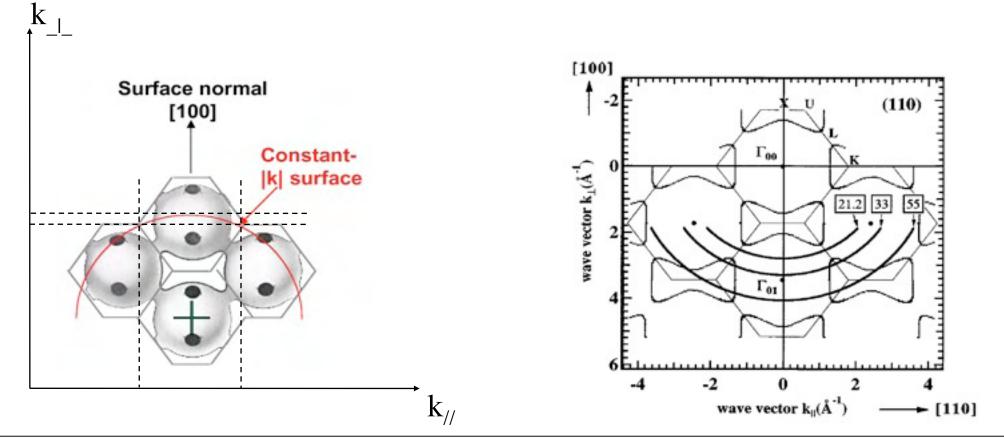
Fig. 9. Analysis of the He I FSM data on TiTe2; see text for details. (From Ref. [45]).

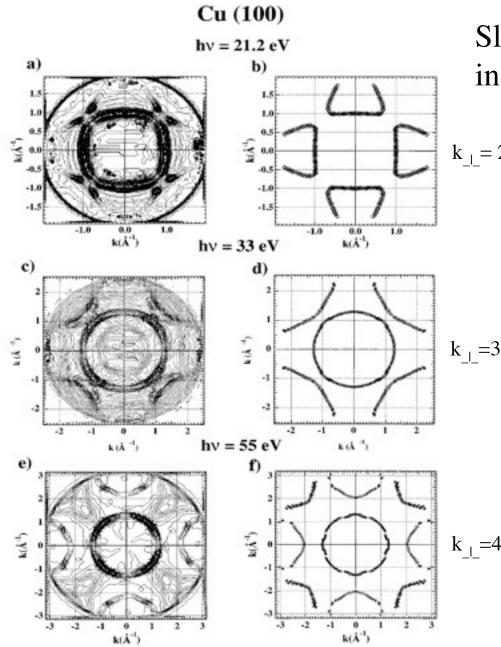
## **Bulk Fermi Surface mapping: case studies Cu**

$$k_{out} = \sqrt{\frac{2m^*}{\hbar^2}} E_{kin}$$
$$k_{in} = \sqrt{\frac{2m^*}{\hbar^2}} (E_{kin} + V_0)$$

$$k_{\parallel out} = k_{\parallel in} = \sin \theta_{out} \sqrt{\frac{2m^*}{\hbar^2} E_{kin}}$$
$$k_{in\perp} = \sqrt{\frac{2m^*}{\hbar^2} (E_{kin} \cos^2 \theta_{out} + V_0)}$$







Slices of the Fermi surface in the  $k_{//}$  plane at different  $k_{-/}$ 

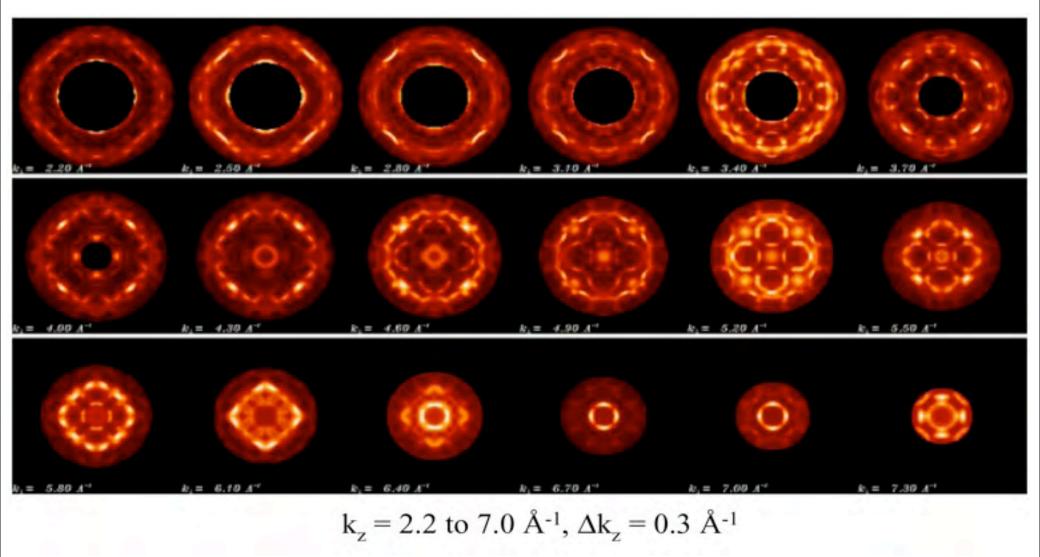
 $k_{\perp} = 2.83 \text{ Å}^{-1}$ 

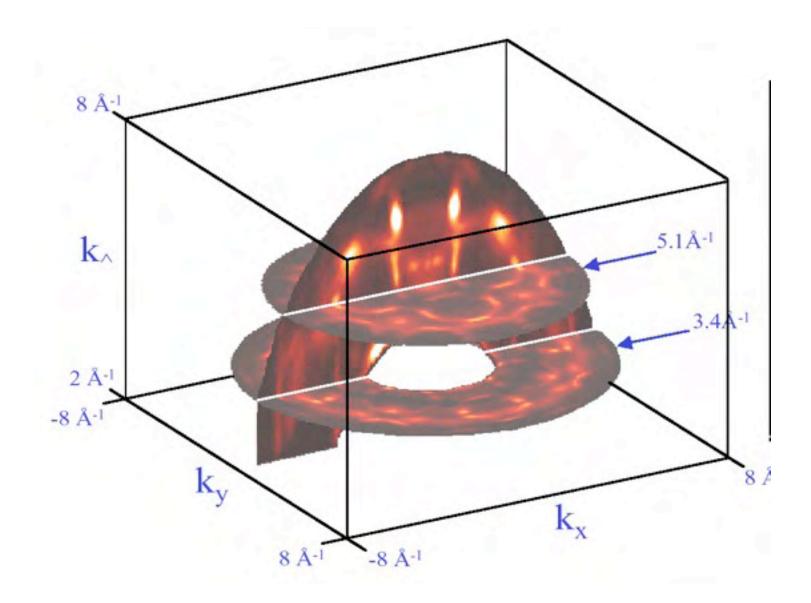
Less defined  $k_{\perp}$  at low kinetic energy (broader Fermi contours, ie. thicker slices).  $k_{\perp}=3.33$ Å<sup>-1</sup>

> 3D reconstruction of the Fermi surface shape is possible

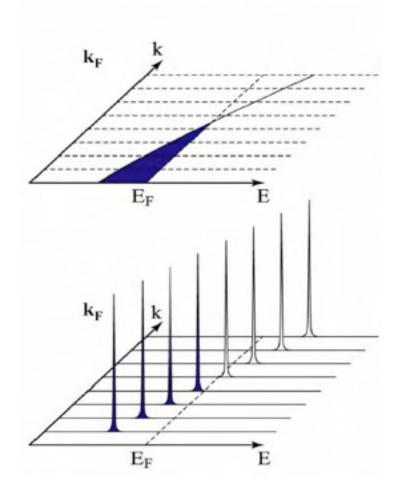
k\_i=4.11 Å-1

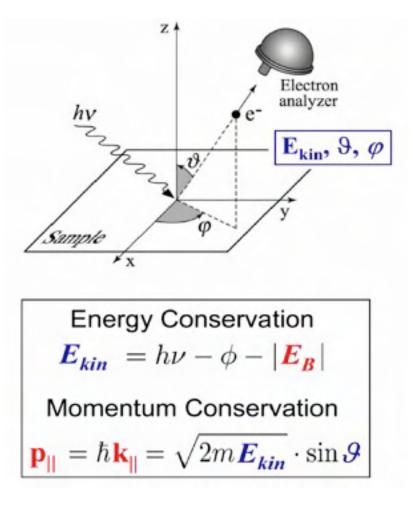
Fig. 3. On the left side, experimental photoelectron angular distributions from the Cu(100) Fermi surface at 21, 33, and 55 eV kinetic energies. On the right side, the results of a tight binding theoretical calculation for the same energies are indicated.





#### The photoelectron spectrum consists of "spikes" at energies $E_{kin}$





The intensity is modulated by the matrix element  $|M_{fi}|^2 = |\langle k_f | A_0 p | k_i \rangle|^2$ 

### **Selection rules**

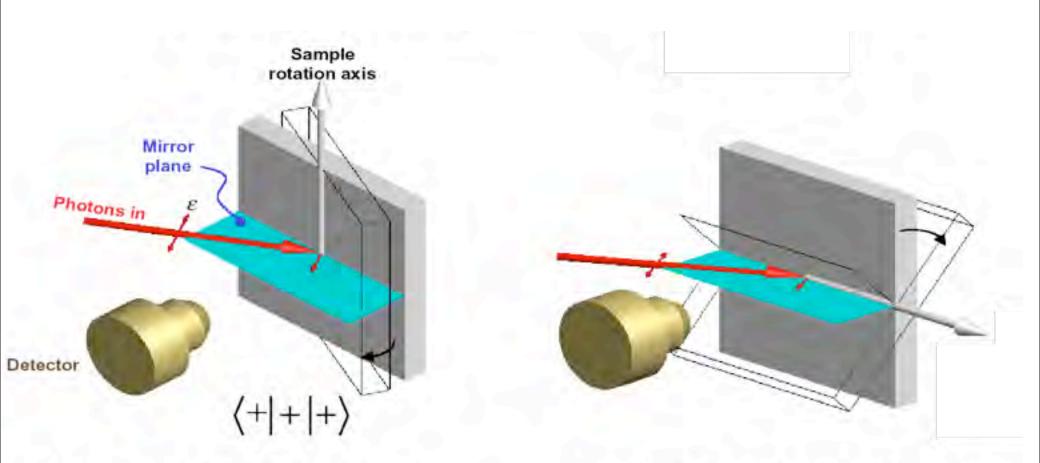
In the dipole matrix element:

$$c_{f,i} \propto \vec{A} \cdot \langle f | \vec{\nabla} | i \rangle \delta \left( \omega - \omega_{i,f} \right) = \left[ A_x \langle f | \frac{\partial}{\partial x} | i \rangle + A_y \langle f | \frac{\partial}{\partial y} | i \rangle + A_z \langle f | \frac{\partial}{\partial z} | i \rangle \right] \delta \left( \omega - \omega_{i,f} \right)$$

both  $|i\rangle$  and  $|f\rangle$  must belong to irreproducibile representations of the symmetry operations of the surface.

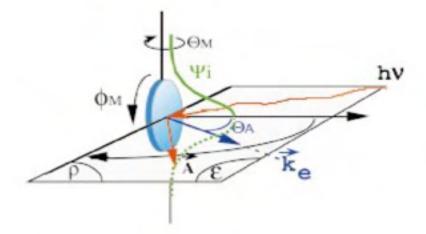
If electrons are collected along a direction contained for example in a mirror plane, If> has even parity with respect to mirroring: an odd function has node in the plane.

By orienting the polarization in a direction contained in the same mirror plane (even operator) only even initial states contribute to the spectrum. if the polarization is perpendicular only odd states are seen.



Only even initial states are observed at all rotation angles Mixture of even and odd states

#### a) even detection



b) odd detection

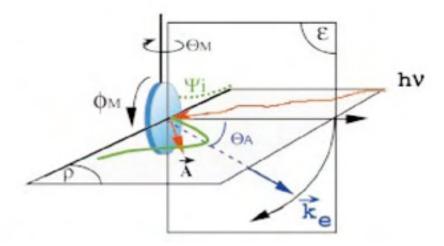
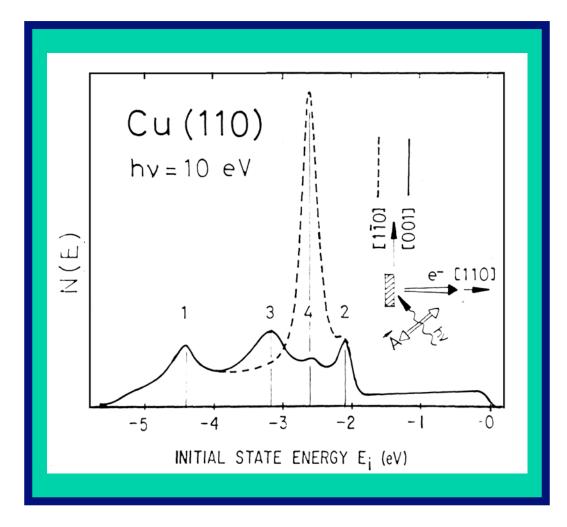


FIG. 1. (Color) The meaning of "even" and "odd" detection geometry in the present ARPES experiments is explained.  $\vec{k}_e$  points toward the detector. In the even case, the detector moves in the plane of incident light (horizontal plane) in which the synchrotron light is polarized. In the odd case, the detector moves in a perpendicular plane as shown. The sample is kept fixed. For initial states lying in a mirror plane (e.g., along the  $\vec{\Gamma} \cdot \vec{M}$  line), the even polarization selects emission only from states symmetric with respect to the mirror plane, while the odd polarization couples to antisymmetric states as discussed in the text. The detector is rotated along the vertical and horizontal axis to access states throughout the  $(k_x, k_y)$ plane.

#### **Applications of selection rules**

a) knowing the geometry one can determine the symmetry of the states:Cu(110)

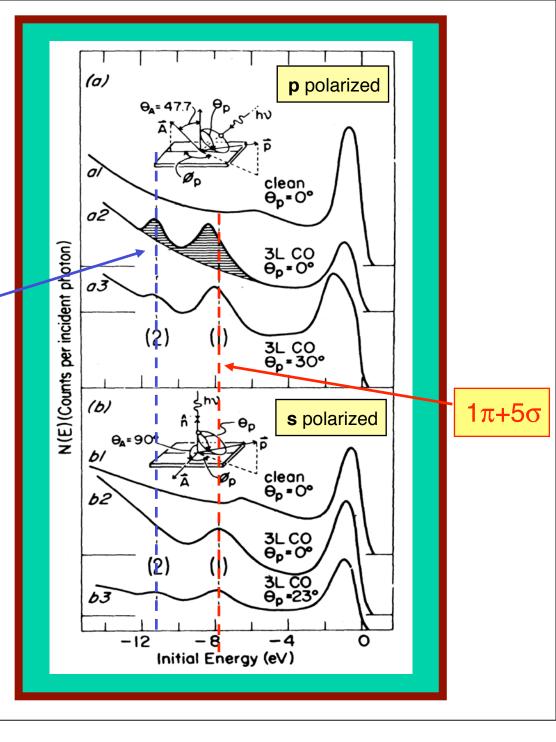


## Applications of selection rules

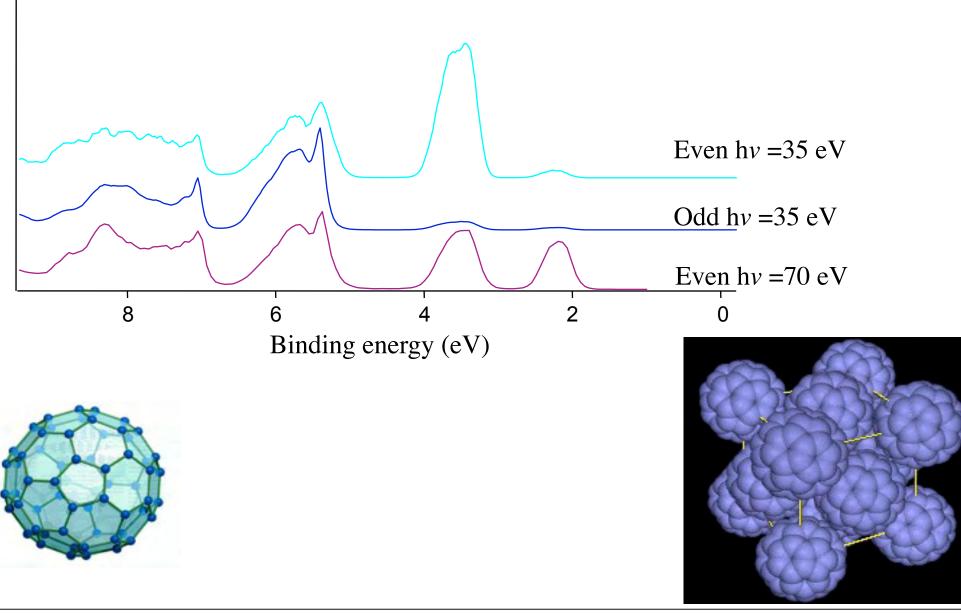
b) knowing the symmetry of the states one can dermine the geometry: orientation of CO/Ni(100)

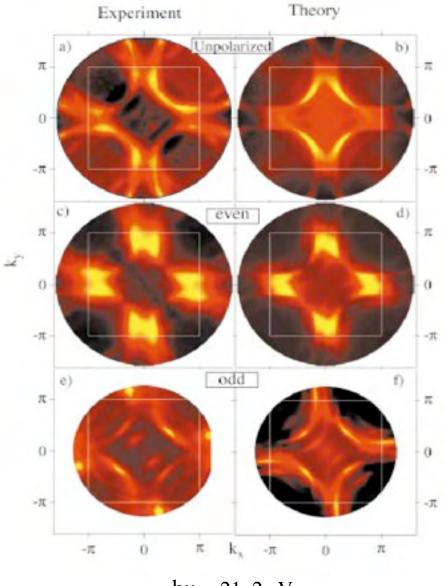
> the 4o disappears for an antisymetric geometry: CO is standing upright

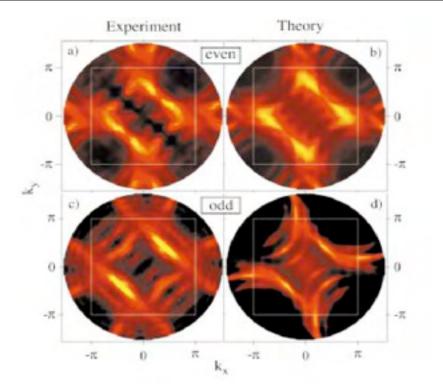
4σ

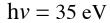


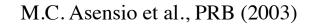
#### Matrix effects on a molecular crystal: C<sub>60</sub>







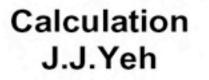




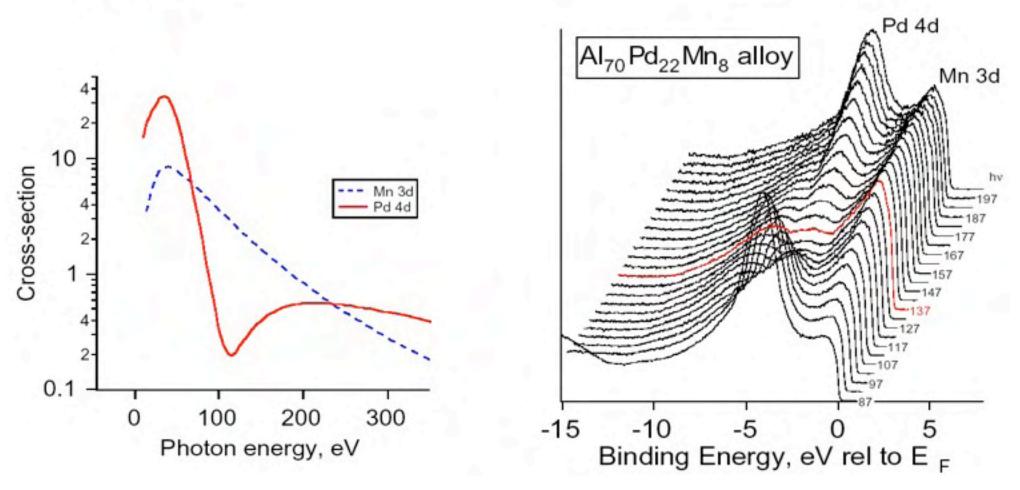
hv = 21..2 eV

Matrix effects on the Fermi surface shape in Bi2212

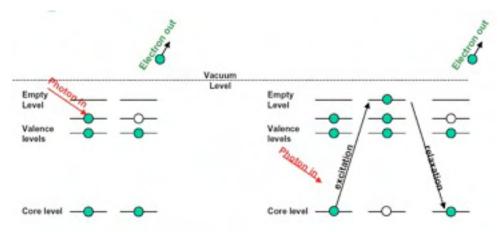
#### **Application of the Cooper minimum effect to alloys**



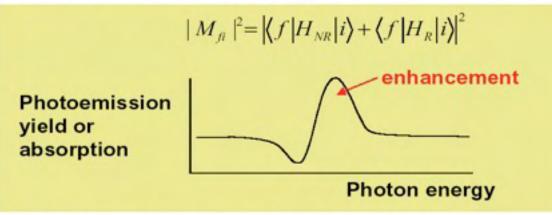
#### Expt. Rotenberg et al



#### Resonant photoemission



- These processes (non-resonant and resonant photoemission) have the same initial and final states.
- As quantum mechanics dictates, these independent channels will interfere when added coherently

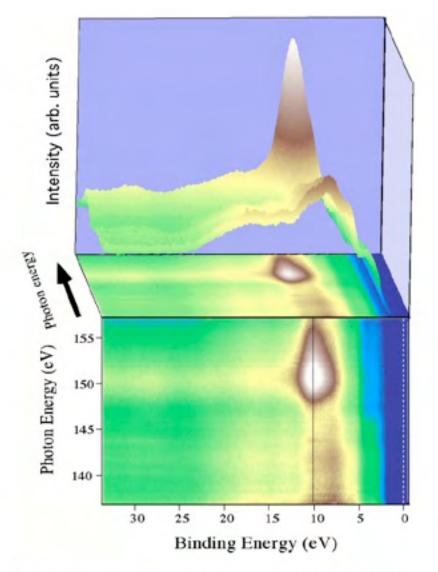


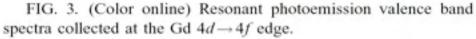
- Not all valence electrons are enhanced equally!
- Only those with overlap to the core hole are enhanced
- This can be very useful to get projections of the valence bands to the individual atoms.

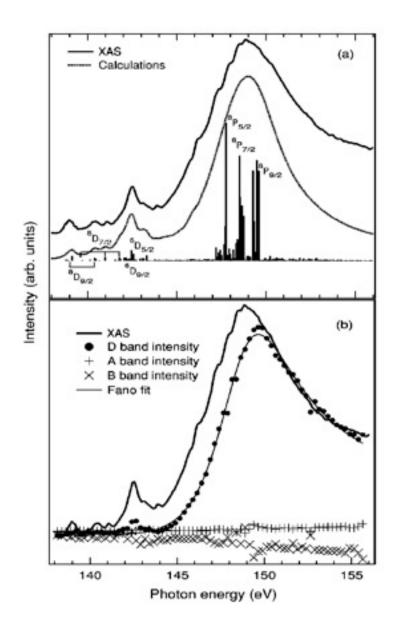
Two constrains on the time scale of the process:

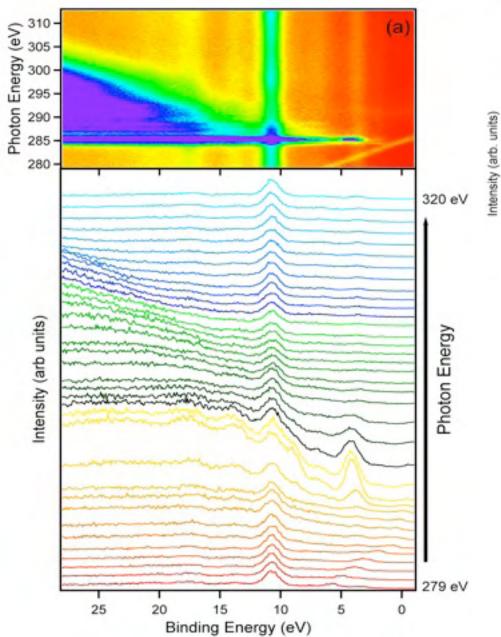
- 1) To have a coherent interfering process the time scale of the two channels must be comparable.
- The the excited electron must remain localized on the same atom of the core hole for a time scale bigger or comparable to the core hole lifetime

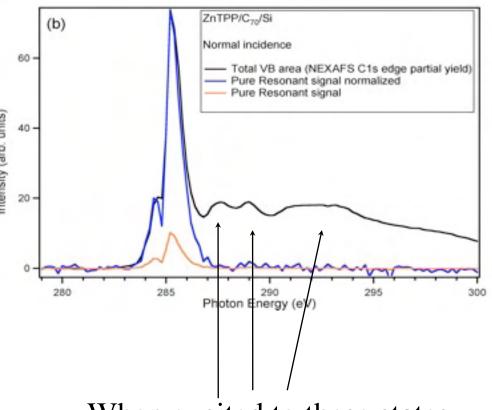
#### Gd@C<sub>82</sub> resonant photoemission









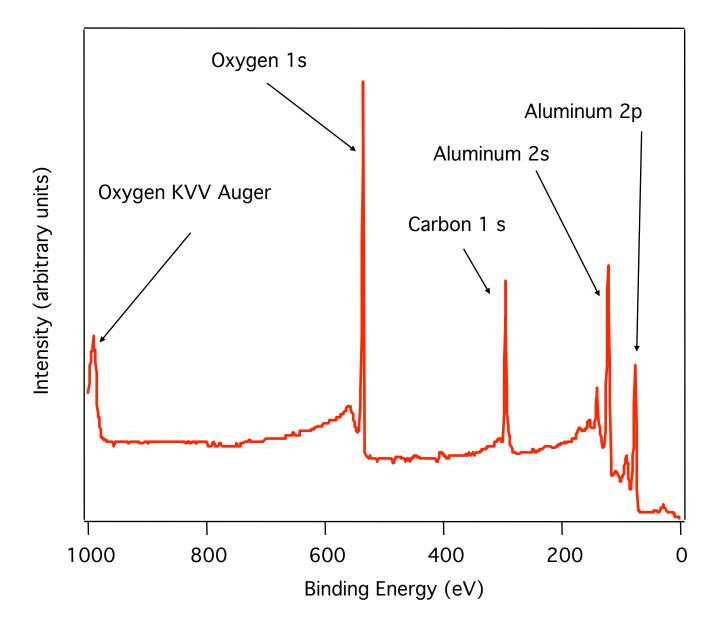


When excited to these states, C1s core electrons delocalize well before the core hole decay.

### **Core level photoemission (XPS or ESCA)**

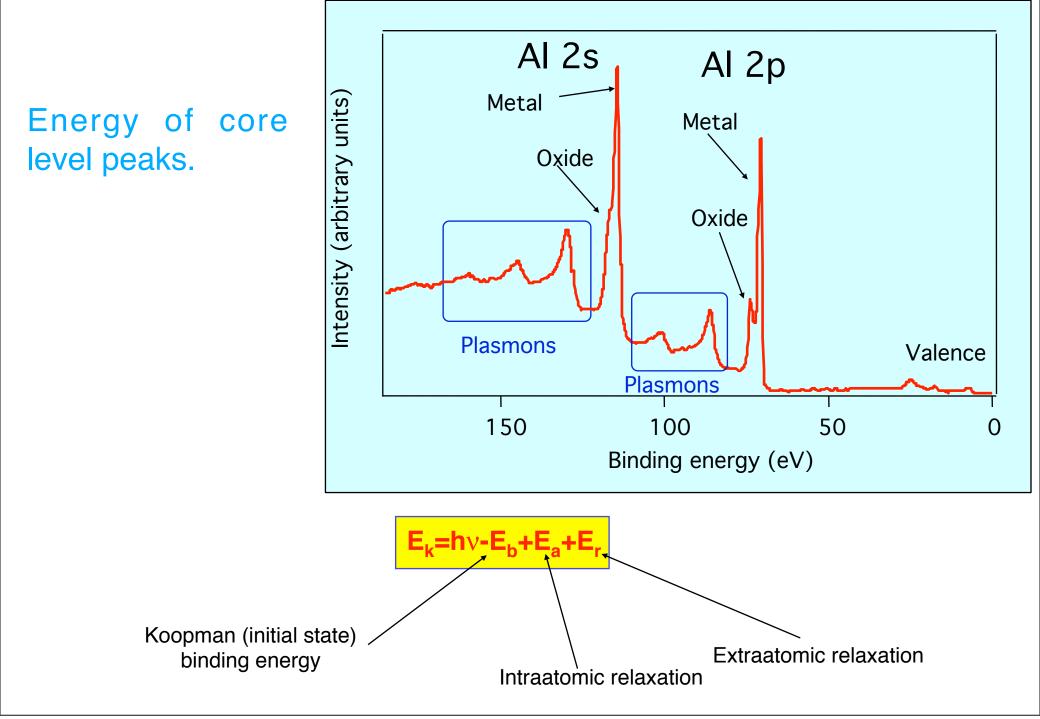
- Element specificity
- Sensitivity to chemical environment
  - the core level shift
- Photoelectron diffraction
- Examples

#### Surface chemical analysis.



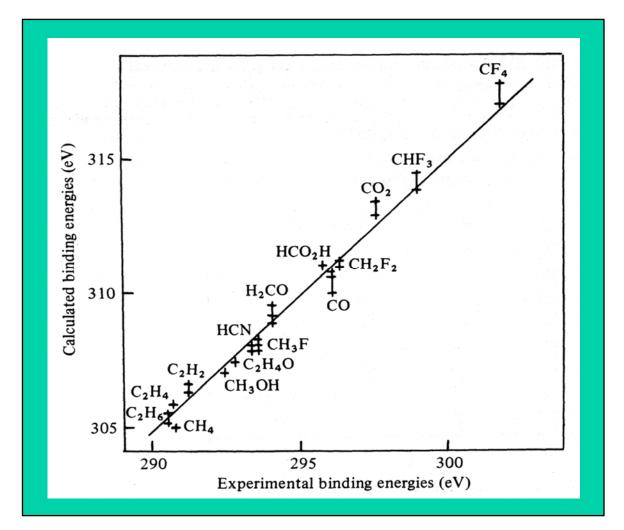
#### Each element has a specific set of accessible core levels

		К	L - I	L - 1 I	L - 111	M - I	M - I I	M - I I I	M-IV	M - V
		1 s	2 s	2p1/2	2p3/2	3 s	3p1/2	3p3/2	3d3/2	3d5/2
1	Η	13.6								
2		24.6*								
3	Li	54.7*								
4		111.5*								
5	В	188*								
6	С	284.2*								
7	N	409.9*	37.3*							
8	0	543.1*	41.6*							
9	F	696.7*								
10		870.2*	48.5*	21.7*	21.6*					
11		1070.8+	63.5+	30.4+	30.5*					
12		1303.0+	88.6*	49.6+	49.21					
13	AI	1559	117.8*	72.9*	72.5*					
14	Si	1839	149.7*b	99.8*	99.2*					
15	Ρ	2145.5	189*	136*	135*					
16	S	2472	230.9	163.6*	162.5*					
17	CI	2822	270*	202*	200*					
18	Ar	3205.9*	326.3*	250.6+	248.4*	29.3*	15.9*	15.7*		
19	K	3608.4*	378.6*	297.3*	294.6*	34.8*	18.3*	18.3*		
20	Са	4038.5*	438.4+	349.7+	346.2+	44.3+	25.4+	25.4+		
21	Sc	4492	498.0*	403.6*	398.7*	51.1*	28.3*	28.3*		
22	Ti	4966	560.9+	460.2+	453.8+	58.7+	32.6+	32.6+		
23	V	5465	626.7+	519.8+	512.1+	66.3+	37.2+	37.2+		
24		5989	696.0+	583.8+	574.1+	74.1+	42.2+	42.2+		
25		6539	769.1+	649.9+	638.7+	82.3+	47.2+	47.2+		
26		7112	844.6+	719.9+	706.8+	91.3+	52.7+	52.7+		
27		7709	925.1+	793.2+	778.1+	101.0+	58.9+	59.9+		
28	Ni	8333	1008.6+	870.0+	852.7+	110.8+	68.0+	66.2+		
29		8979	1096.7+	952.3+	932.7	122.5+	77.3+	75.1+		
30		9659	1196.2*	1044.9*	1021.8*	139.8*	91.4*	88.6*	10.2*	10.1*
31	Ga	10367	1299.0*b	1143.2+	1116.4+	159.51	103.5+	100.0+	18.7+	18.7+
32		11103		1248.1*b	1217.0*b	180.1*	124.9*	120.8*	29.8*	29.2*
33		11867		1359.1*b	1323.6*b	204.7*	146.2*	141.2*	41.7*	41.7*
34		12658		1474.3*b	1433.9*b	229.6*	166.5*	160.7*	55.5*	54.6*
35	Βr	13474	1782*	1596*	1550*	257*	189*	182*	70*	69*

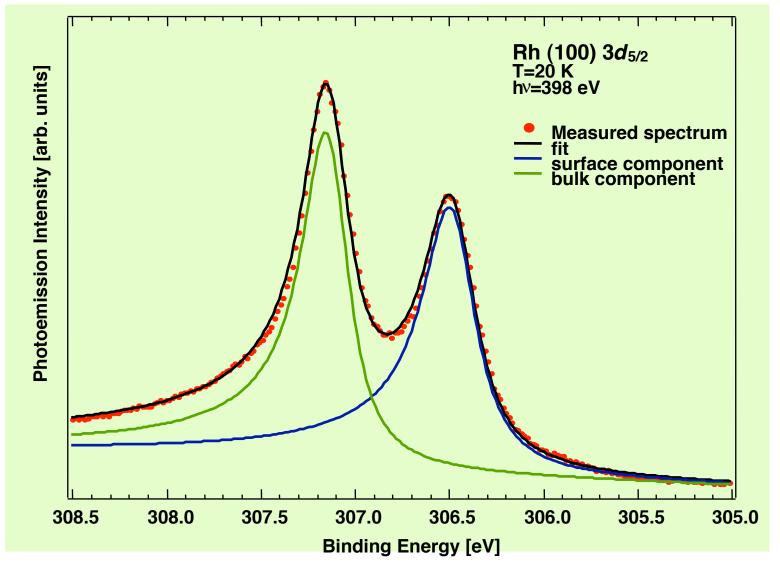


## **Neglecting relaxation...**

Comparison of experimental XPS C 1s binding energies with those calculated via Koopman's theorem for C in a range of molecules. Although experimental and theoretical values differ by 15 eV (associated with relaxation effects) the systematic comparison is excellent as indicated by the straight line of unity slope

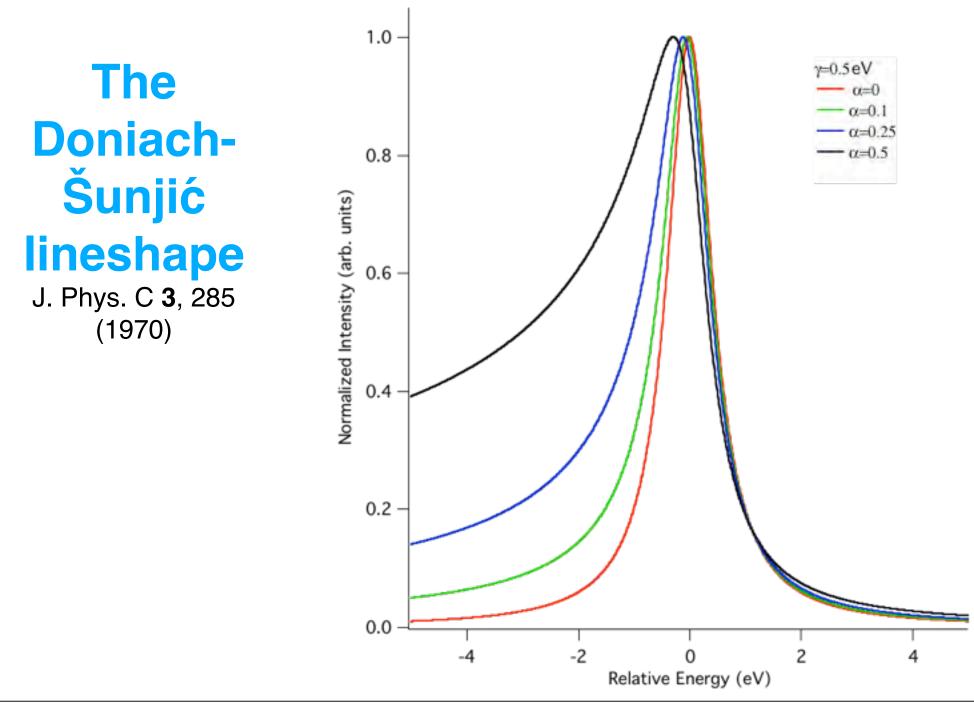


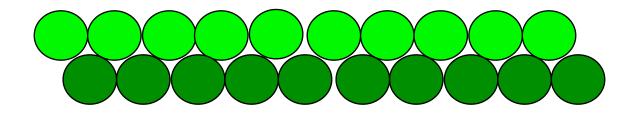
## A particular case of core level shift: the surface core level shift

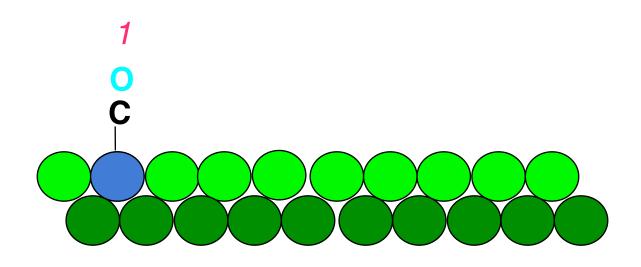


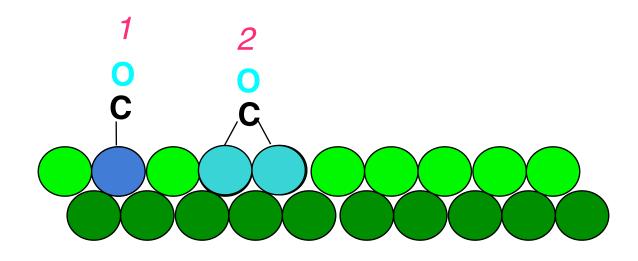
#### The Doniach-Šunjić lineshape J. Phys. C **3**, 285 (1970)

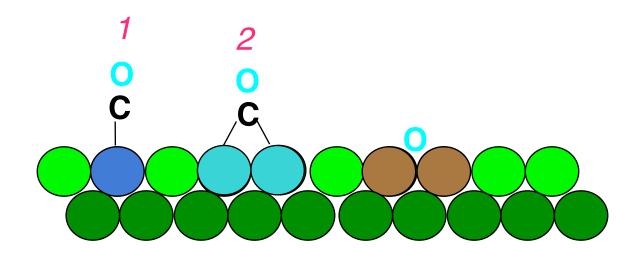
$$Y(E) = \frac{\Gamma(1-\alpha)}{(E^2+\gamma^2)^{\frac{(1-\alpha)}{2}}} \cos\left[\frac{\pi\alpha}{2} + (1-\alpha)\arctan\left(\frac{E}{\gamma}\right)\right]$$

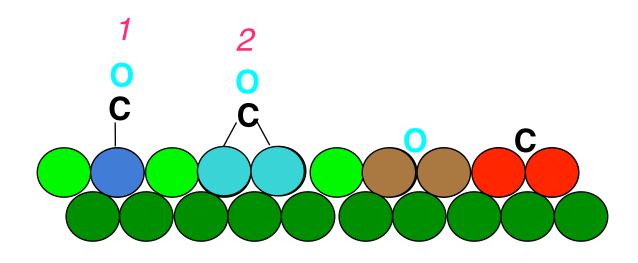


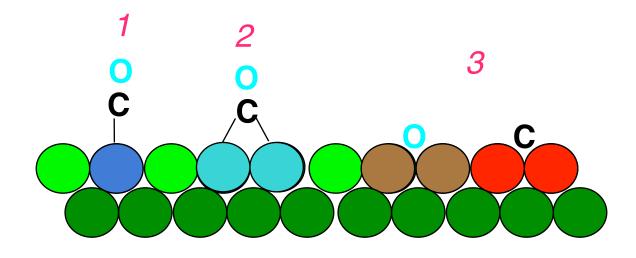


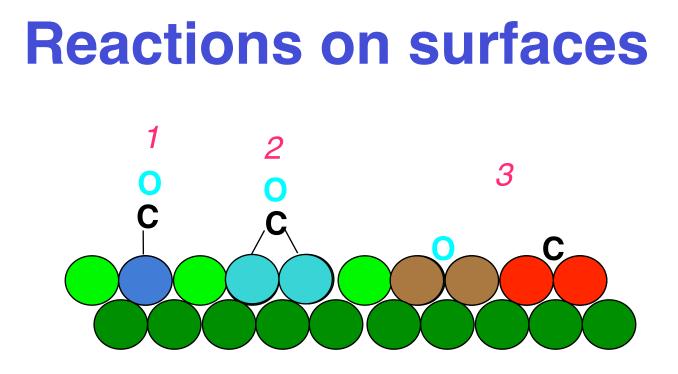




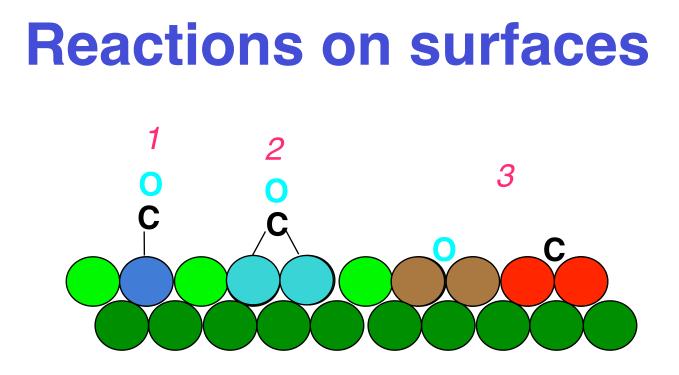




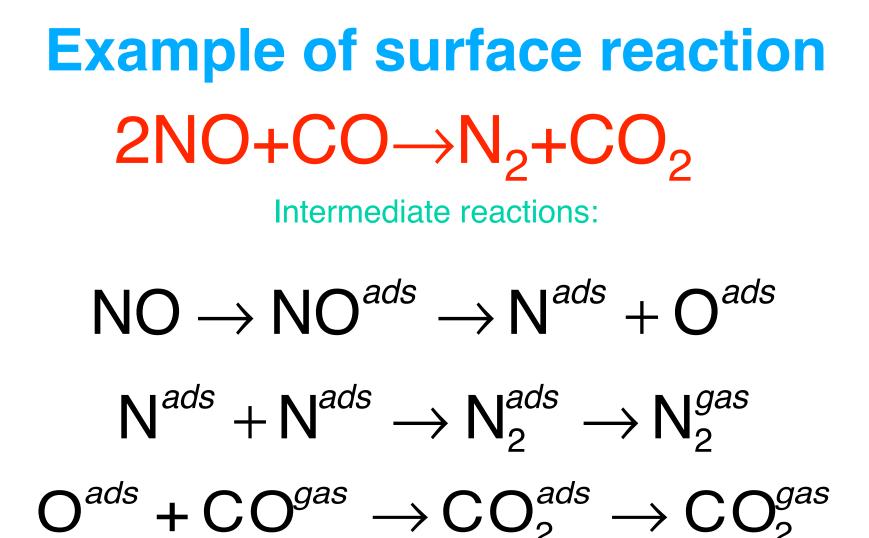




•Distinguish 1 (CO on top) from 2 (CO on a bridge site) and from 3 (dissociated CO)



- •Distinguish 1 (CO on top) from 2 (CO on a bridge site) and from 3 (dissociated CO)
- Follow changes from 1 to 2 and/or to 3



## Why XPS?

- has unambigous correspondence between surface species and spectral features;
- is quantitative;
- is applicable to both molecular and atomic adsorbates;
- changes in both adsorbate and substrate can be detected.

## For t<1994 XPS used to be a "slow" technique

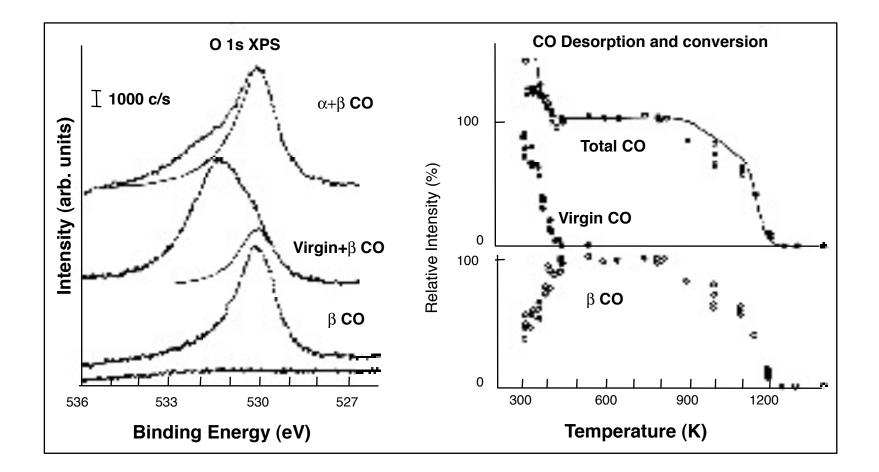
Typical acquisition time ~30 minutes for adsorbates

only "frozen" and/or low resolution experiments were possible

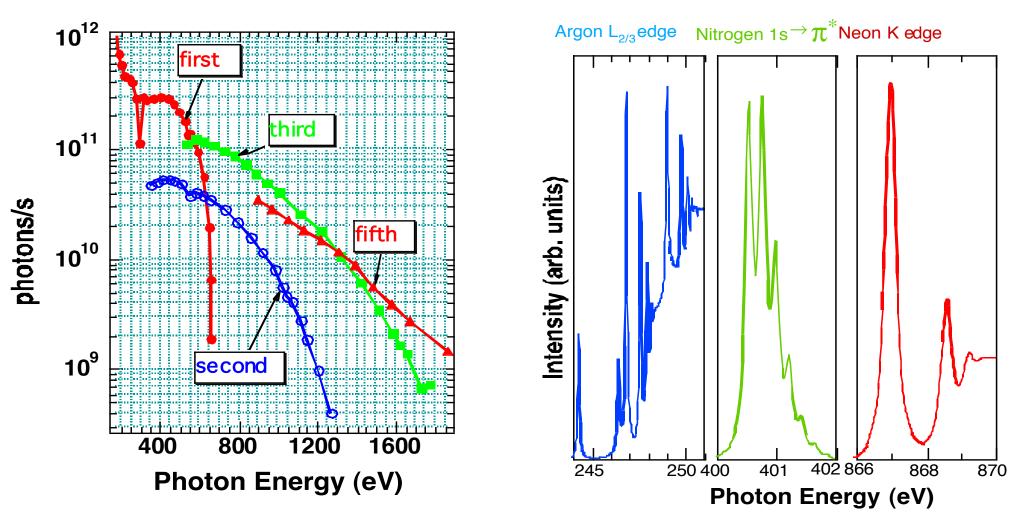
better to go for vibrational spectroscopies!

## First attempts to use XPS to follow surface reactions: dissociation of CO/W(110)

E. Umbach, J.C. Fuggle, D. Menzel, J. Electron Spectrosc. 10,15 (1977)



# With 3rd generation SR sources: flux& resolution at the same time



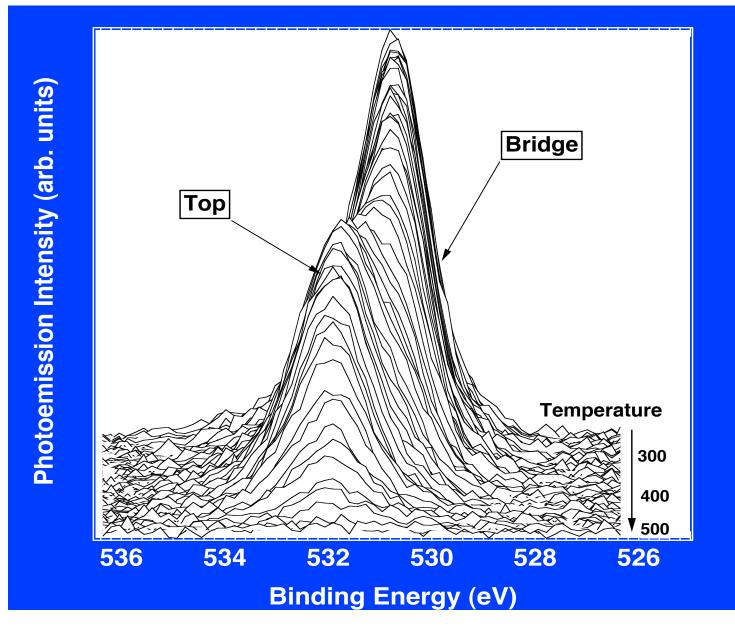
## Measure surface time-dependent phenomena

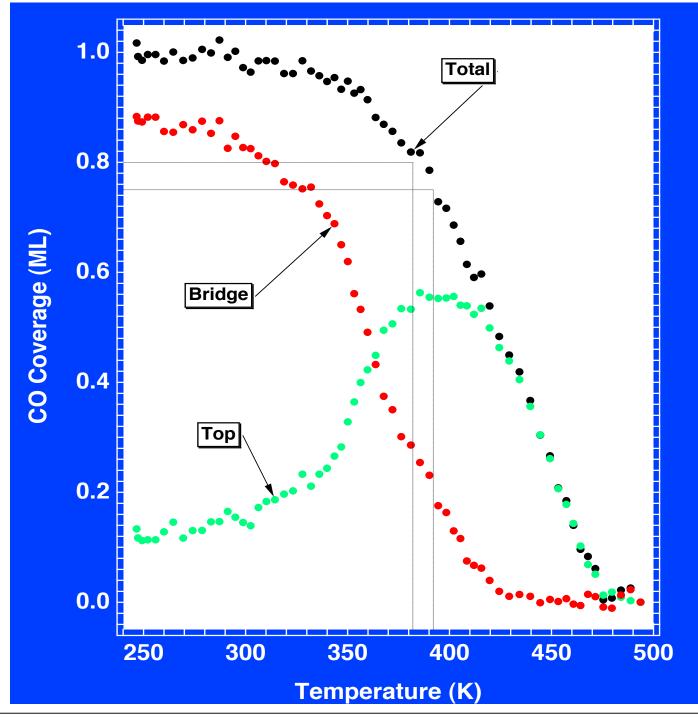
- Trigger the phenomenon (e.g. open a leak valve!)
- Measure a lot of spectra
- Analyze them to get quantitative information

# CO thermal desorption from Rh (110)

- Two adsorption sites
- Migration and desorption

## **Desorpotion of CO/Rh(110)**





CO/Rh(110): CO desorption & migration

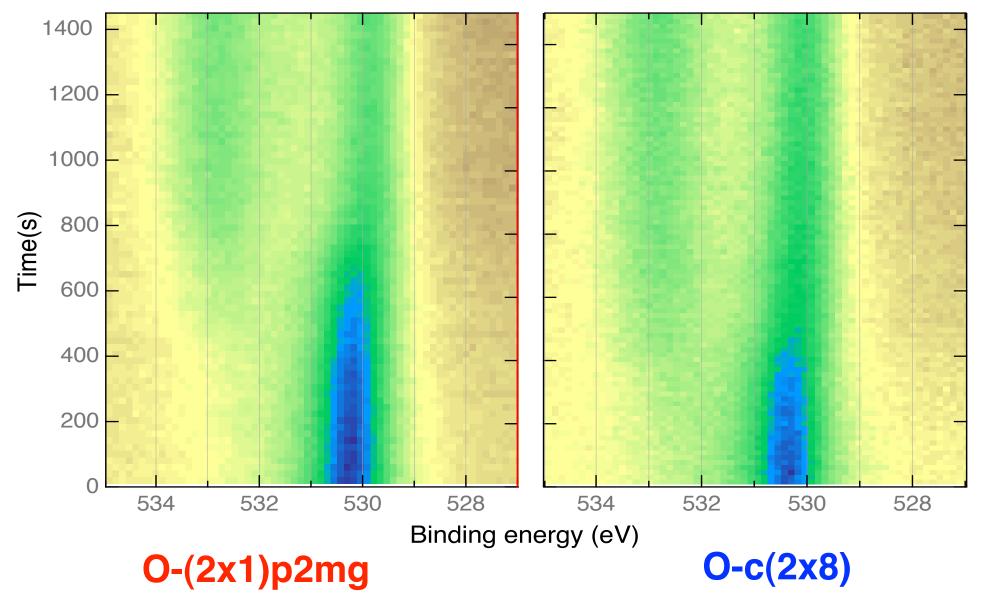
Wednesday, July 10, 2013

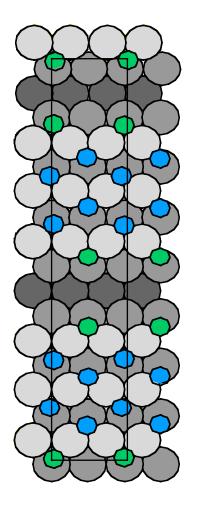
# CO titration of oxygen overlayers on Rh (110) at T=200 K

$$O^{ads} + CO^{gas} \rightarrow CO^{ads}_2 \rightarrow CO^{gas}_2$$

Effect of surface restructuring on reaction rate

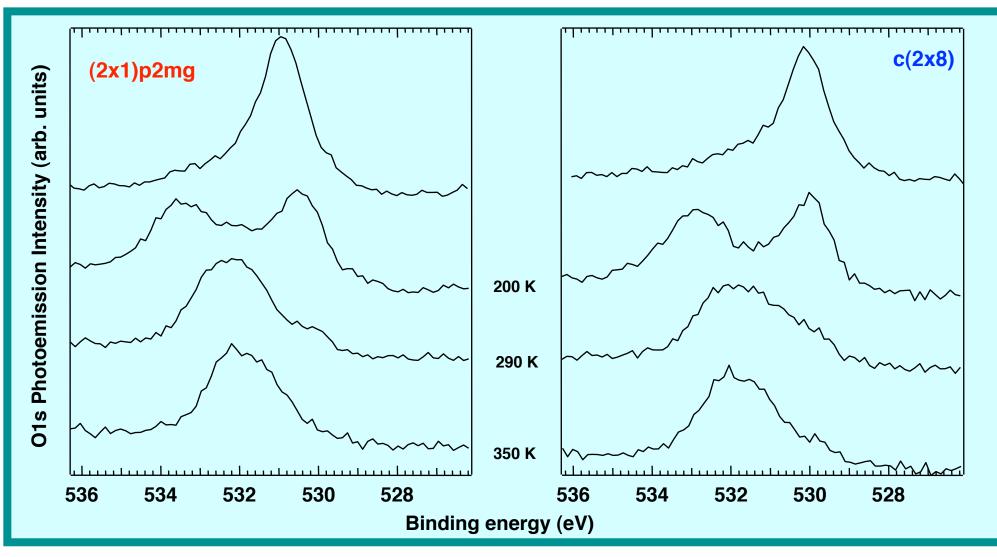
#### **CO titration of oxygen overlayers on Rh (110)** T=200 K





La struttura O–c(2x8) con gli atomi di ossigeno nei siti *threefold* nei solchi non ricostruiti (azzurri-più reattivi) e nei solchi ricostruiti (verdi-meno reattivi)

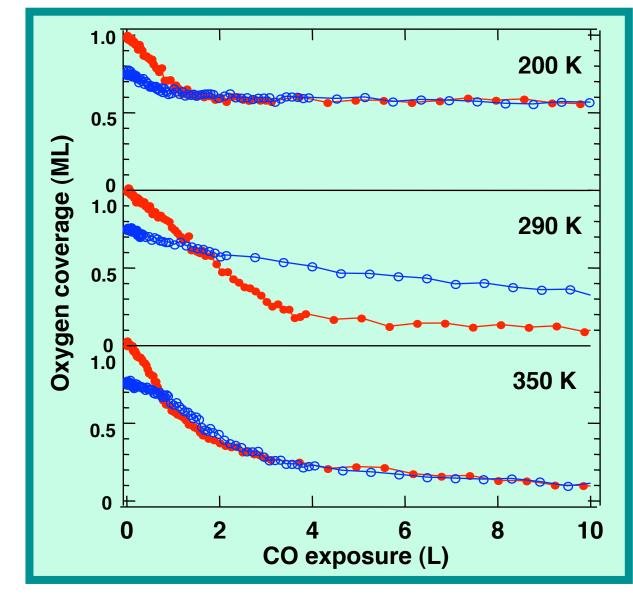
#### CO titration of oxygen overlayers on Rh (110)



spectra taken after 20 L CO exposure

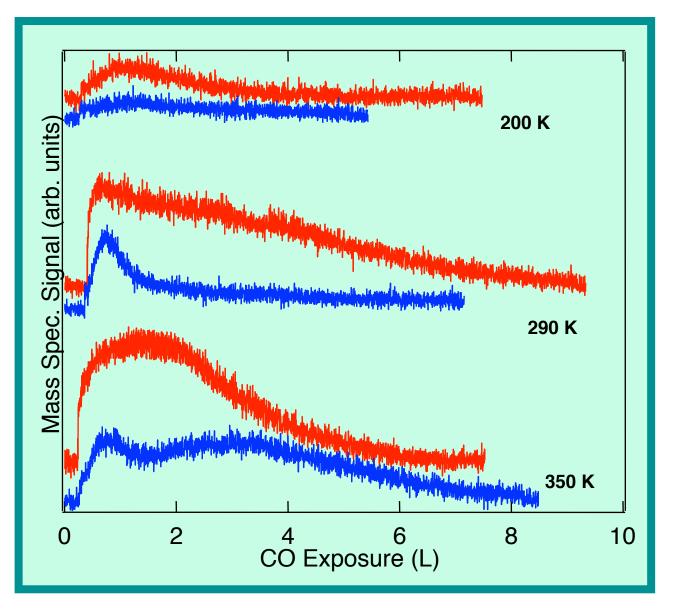
#### CO titration of oxygen overlayers on Rh (110)

O decay for O-(2x1)p2mg and O-c(2x8)



#### CO titration of oxygen overlayers on Rh (110)

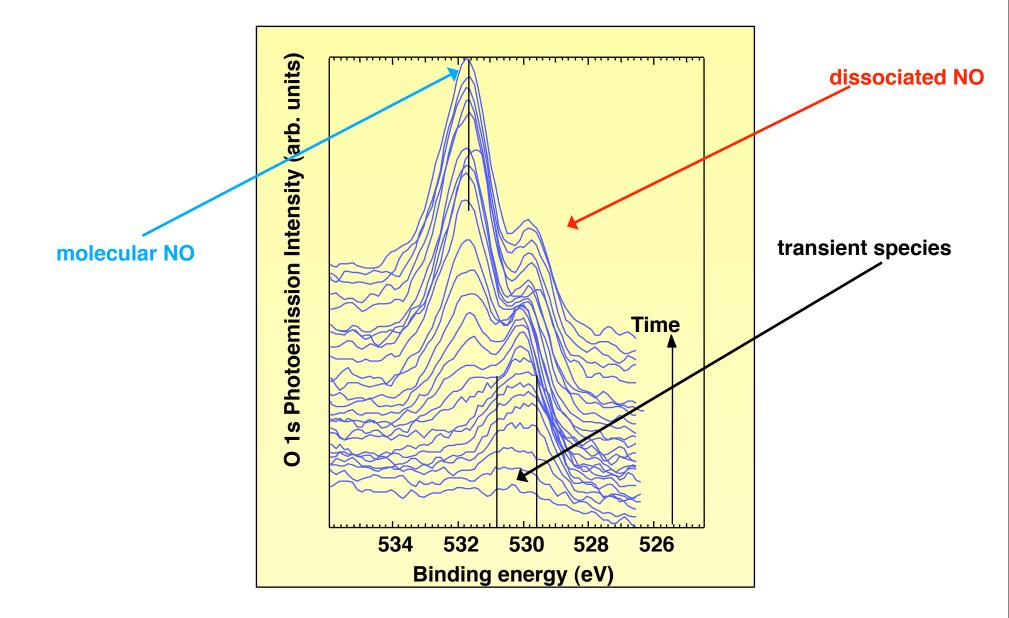
CO<sub>2</sub> production from O-(2x1)p2mg and O-c(2x8)



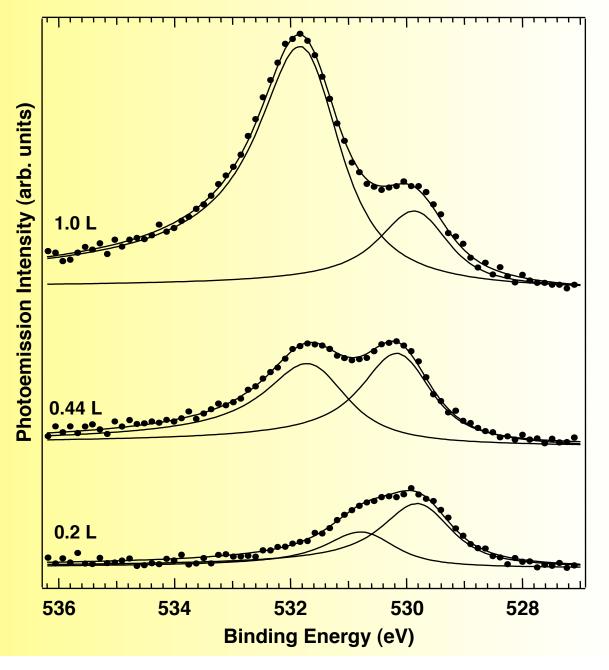
# Adsorption and dissociation of Nitric Oxide on Rh(110)

Observation of an adsorption state precursor to dissociation

#### O1s spectra during NO exposure at 270 K

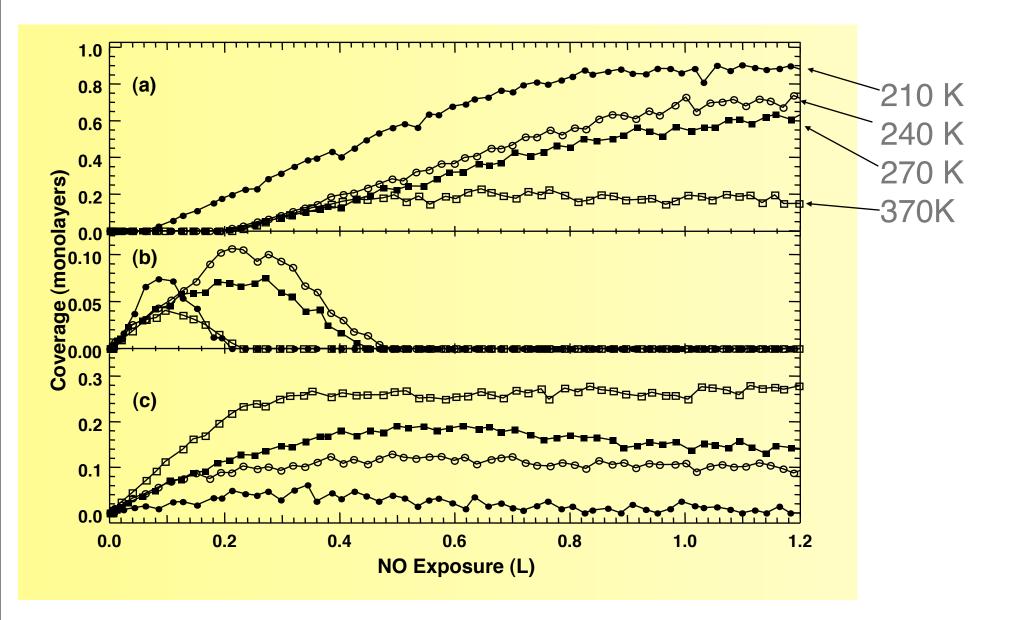


#### NO dissociation on Rh (110)



Selection of O 1s spectra during NO exposure at 270 K

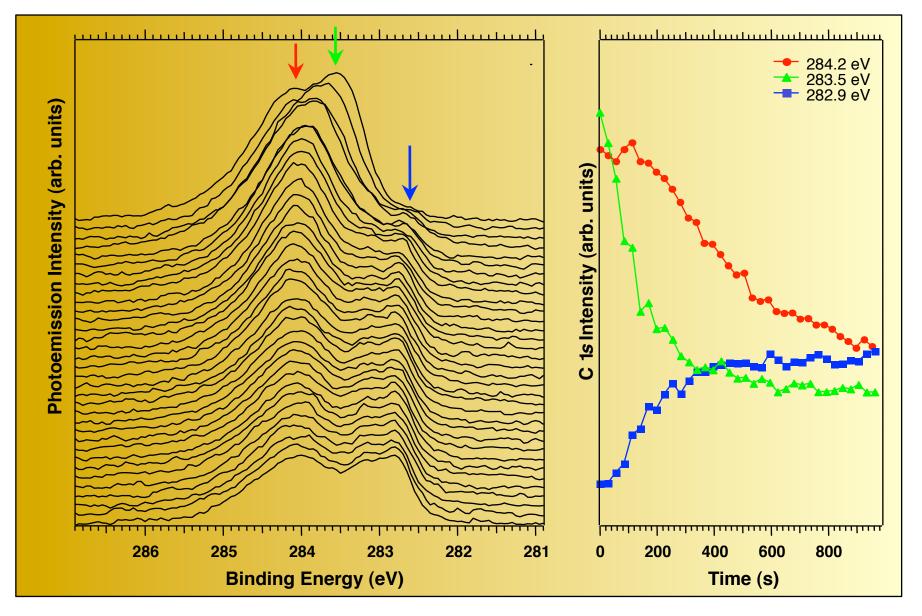
#### NO dissociation on Rh (110)



# Photochemistry of CH<sub>4</sub> on Pt (111)

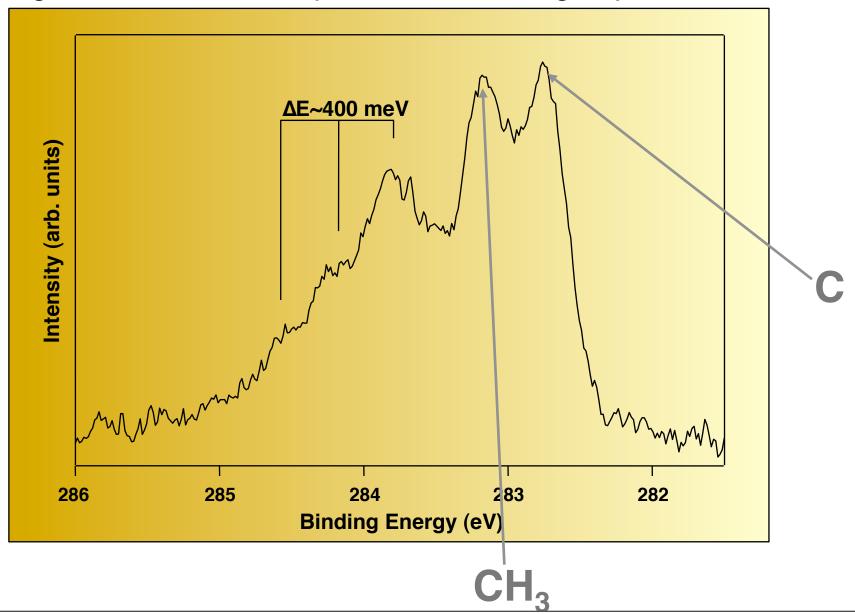
Photodesorption of multilayers Dissociation into C+CH<sub>3</sub> species

# Photochemistry of CH<sub>4</sub> on Pt(111)

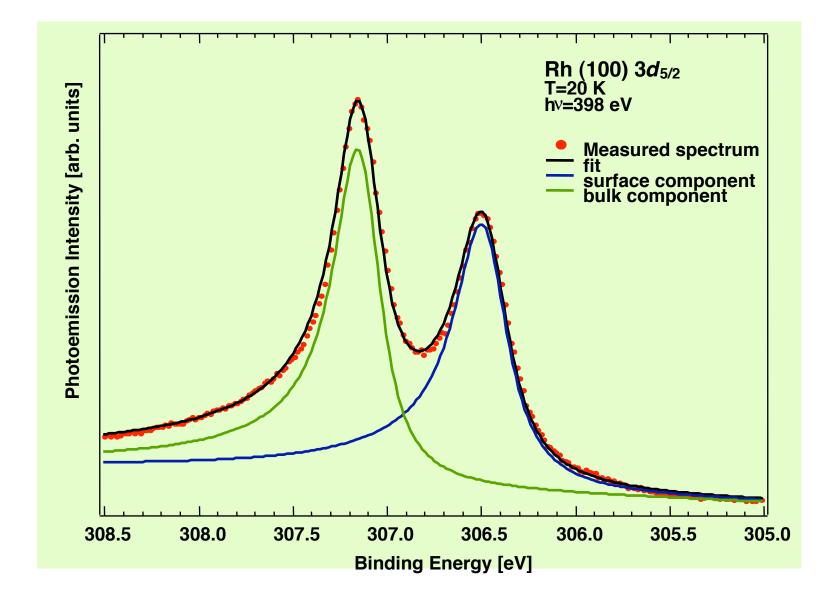


# Photochemistry of CH<sub>4</sub> on Pt(111)

High resolution C 1s spectrum after long exposure to hv

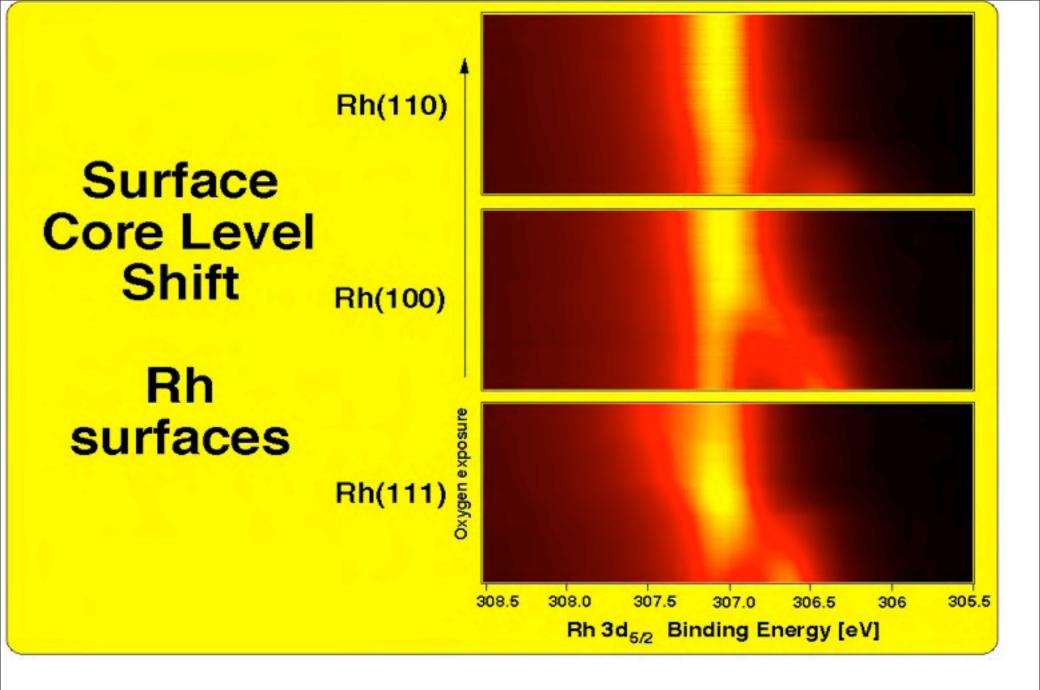


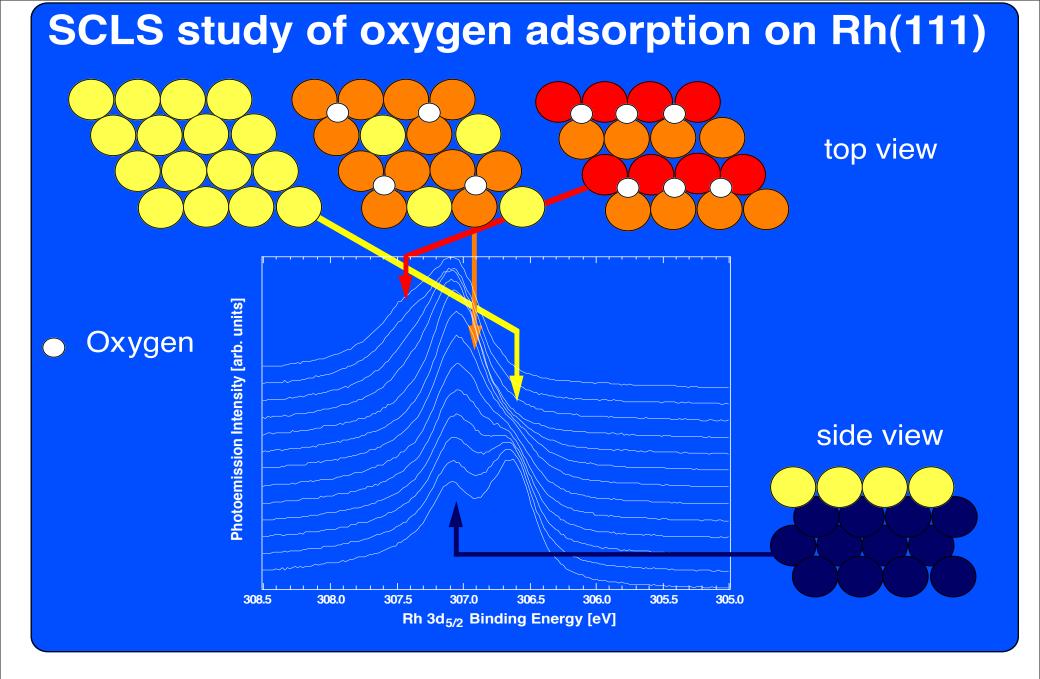
### The surface core level shift



## Identification of adsorbate bonding by changes in the substrate *Surface Core level Shift*

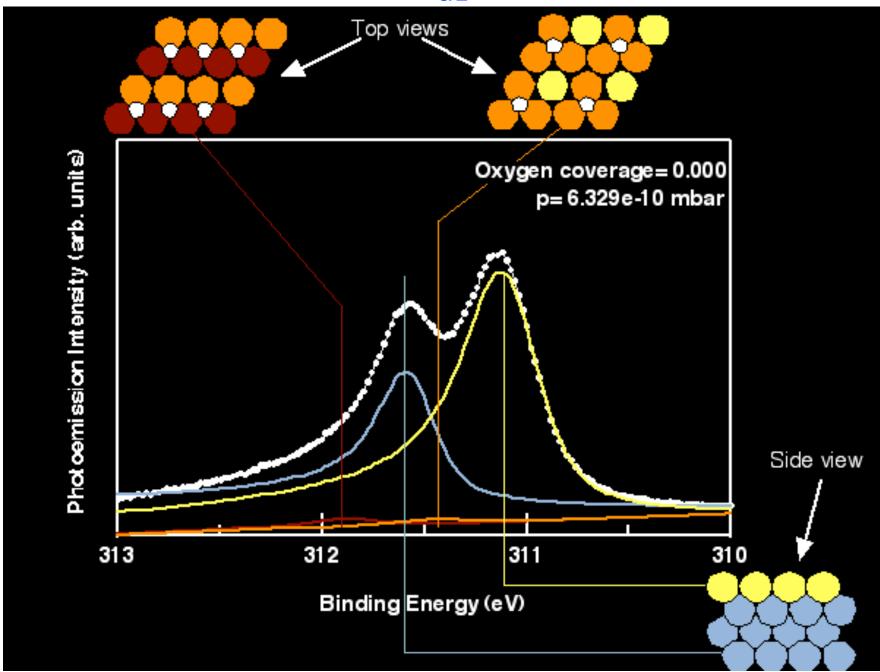
Evolution of the del SCLS of low Miller indices Rh surfaces as a function of  $O_2$  dose



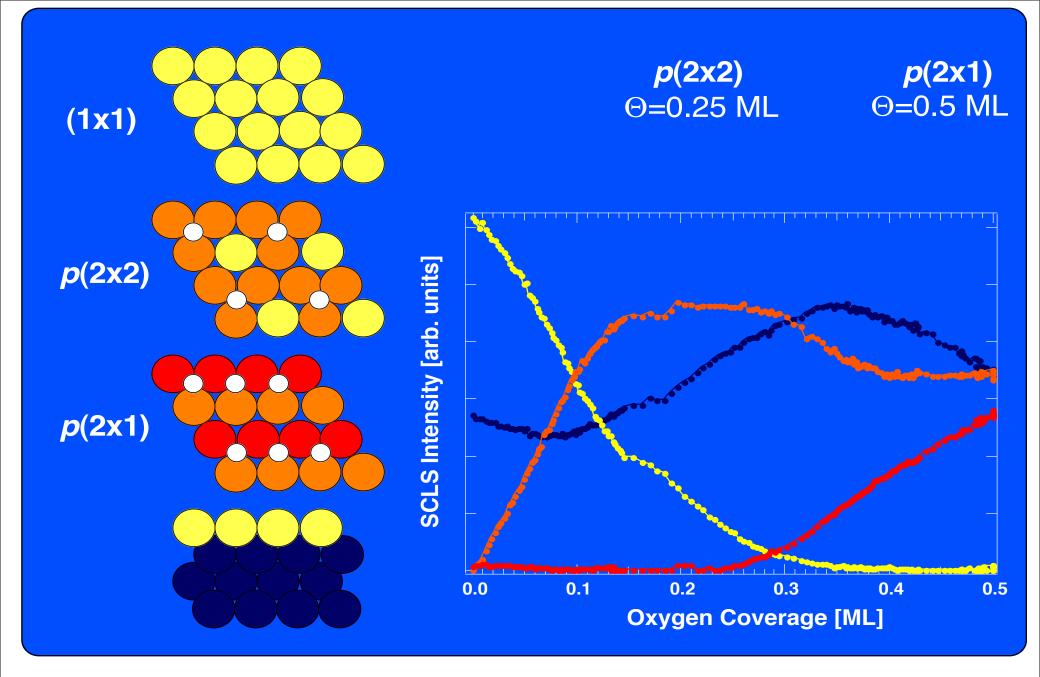


#### Rh(111): evolution of the Rh $3d_{5/2}$ peak during exposure to $O_2$

Rh(111): evolution of the Rh 3d<sub>5/2</sub> peak during exposure to O<sub>2</sub>

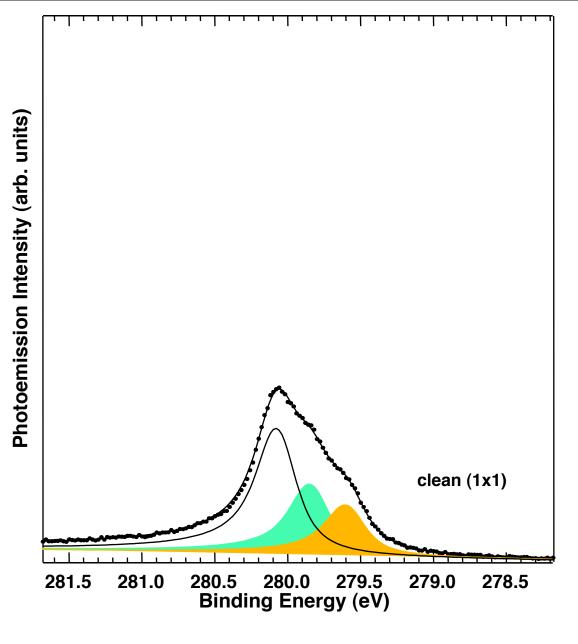


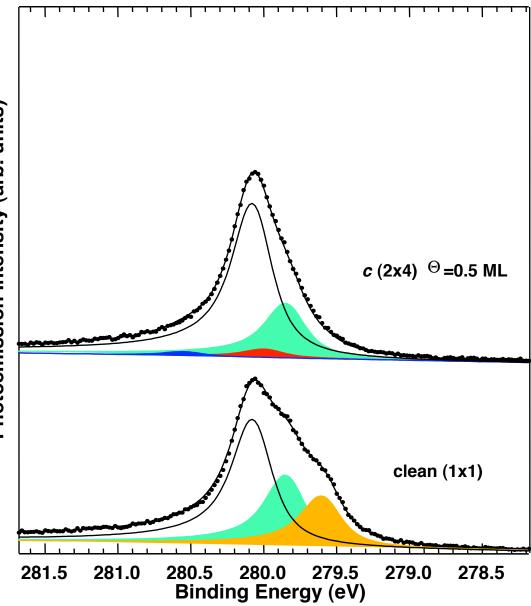
Wednesday, July 10, 2013



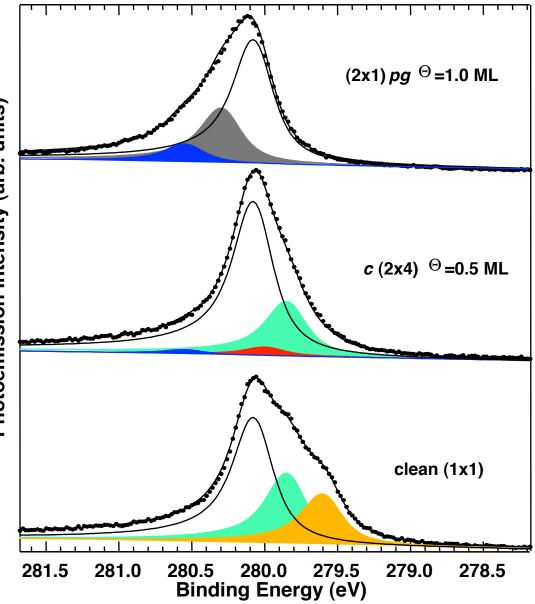
## Identification of adsorbate bonding by the substrate SCLS

2) O on  $Ru(101\overline{0})$ 

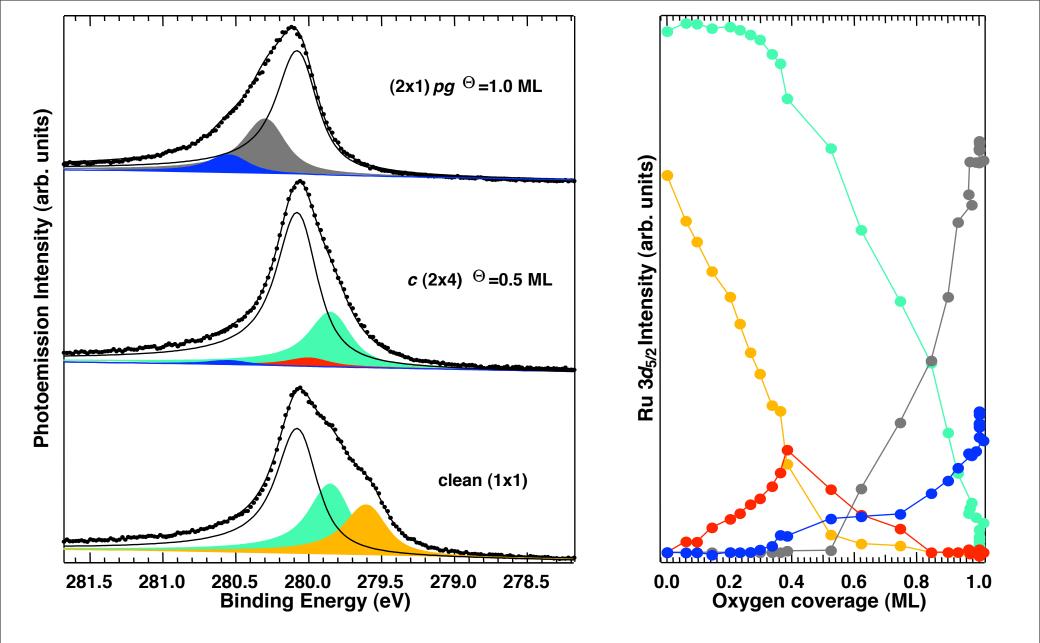


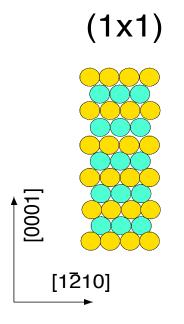


Photoemission Intensity (arb. units)

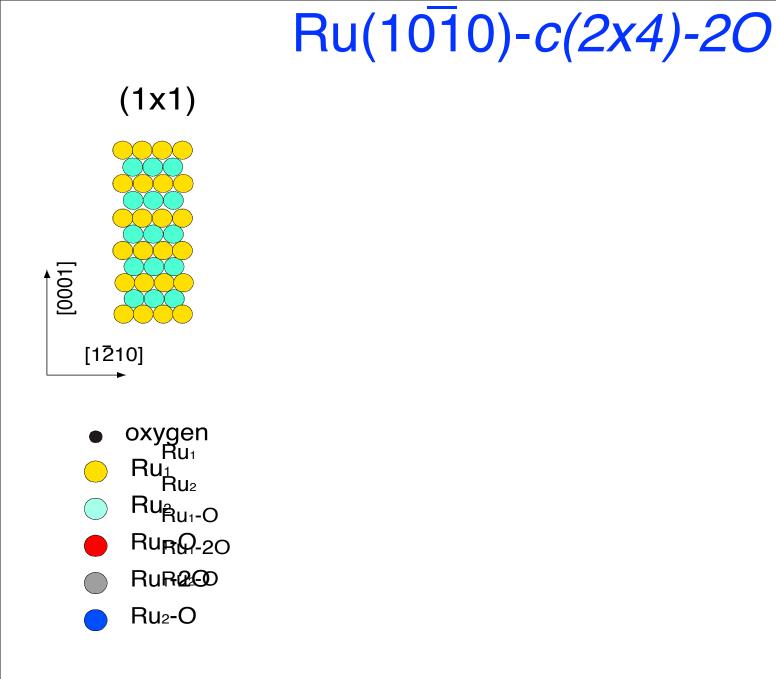


Photoemission Intensity (arb. units)

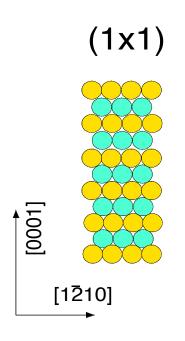


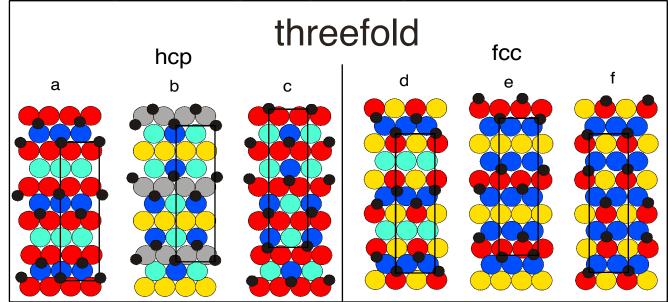


Ru1 Ru2 Ru1-O Ru1-2O Ru2-O

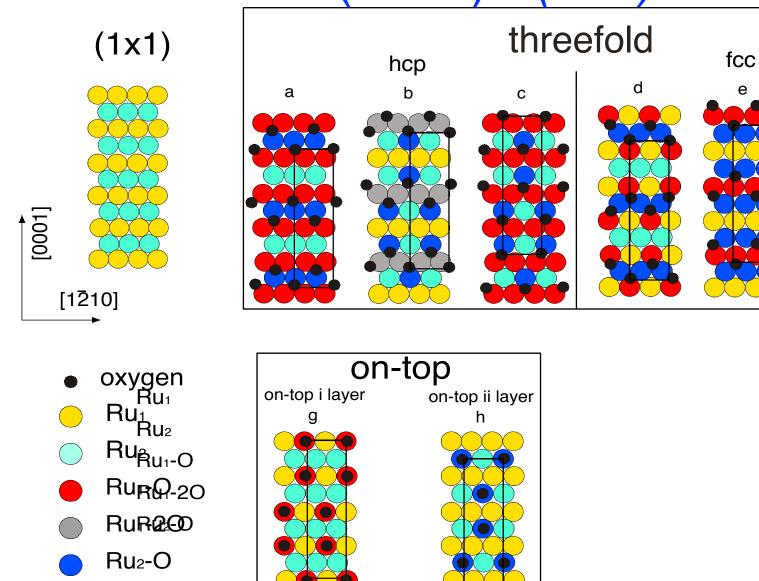


# Ru(1010)-*c(2x4)-20*

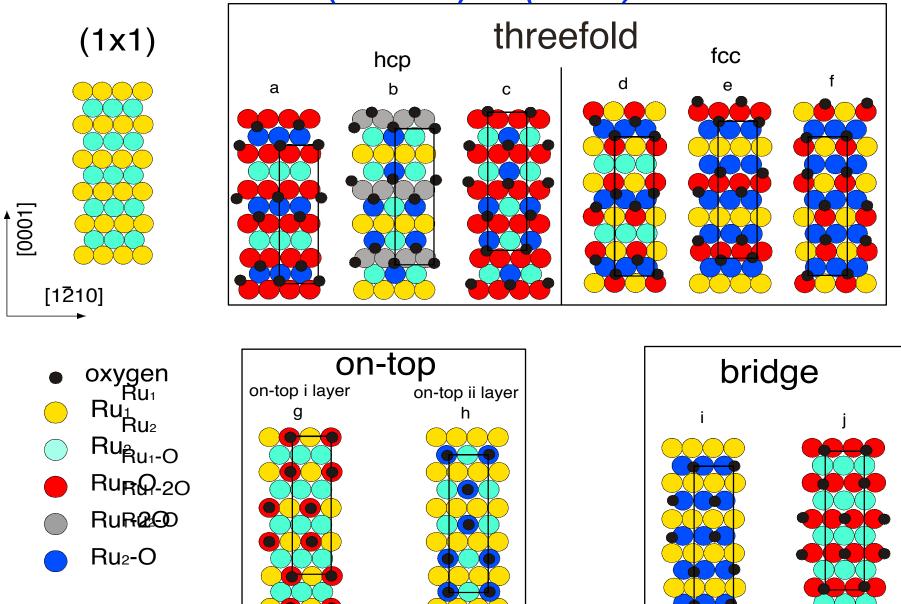




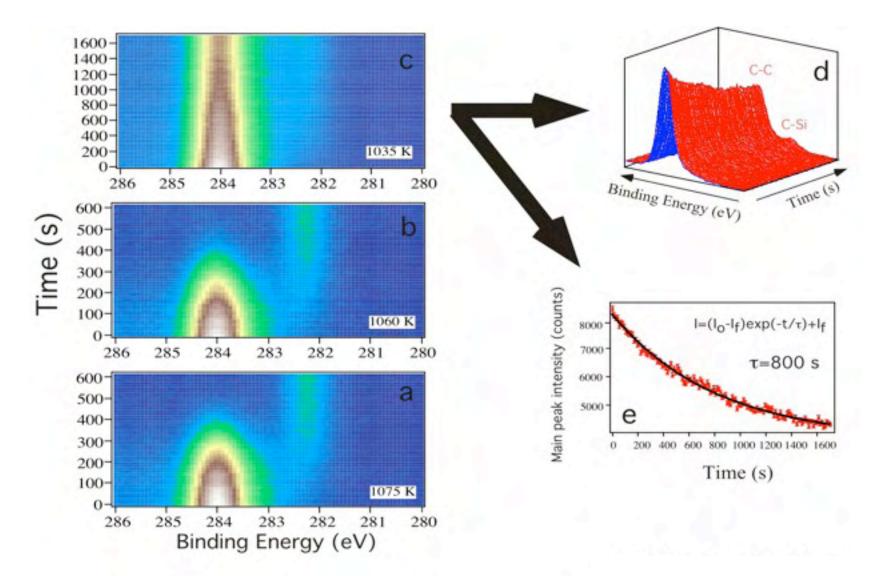
# Ru(1010)-*c(2x4)-20*



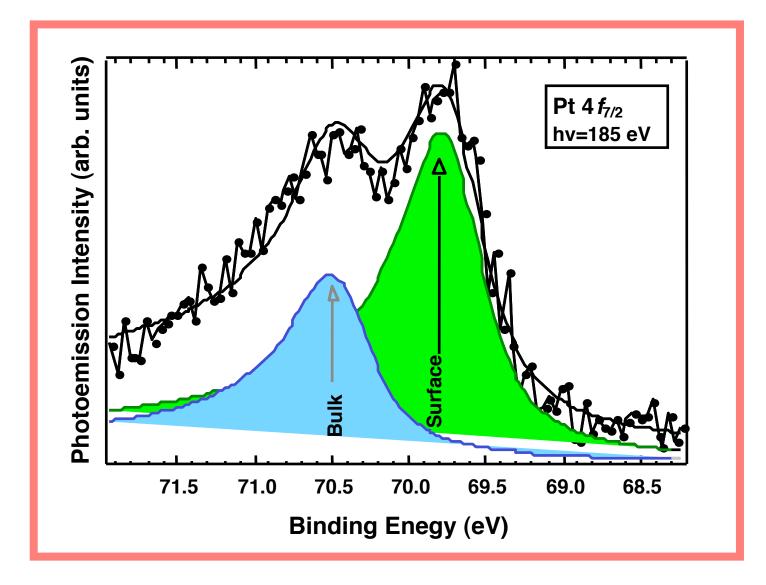
# Ru(1010)-*c(2x4)-20*



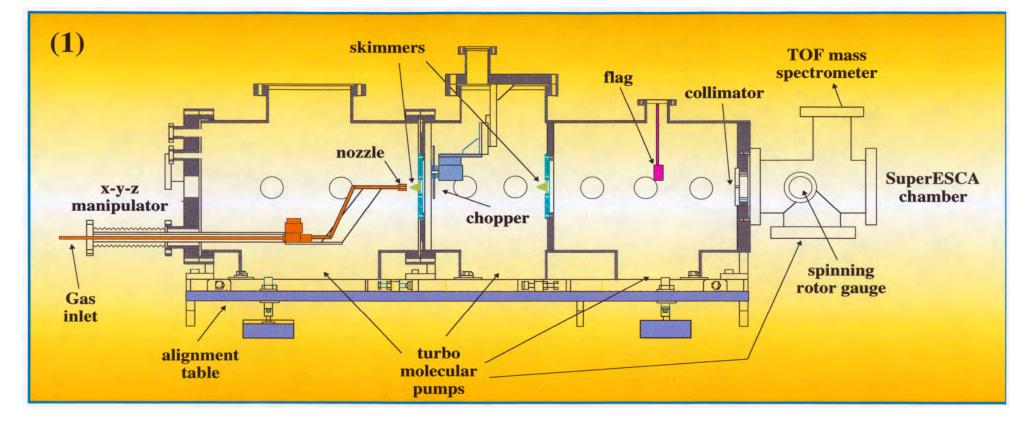
#### SiC formation by decomposition of C<sub>60</sub>/Si



## Single shot spectrum (~100 ms):



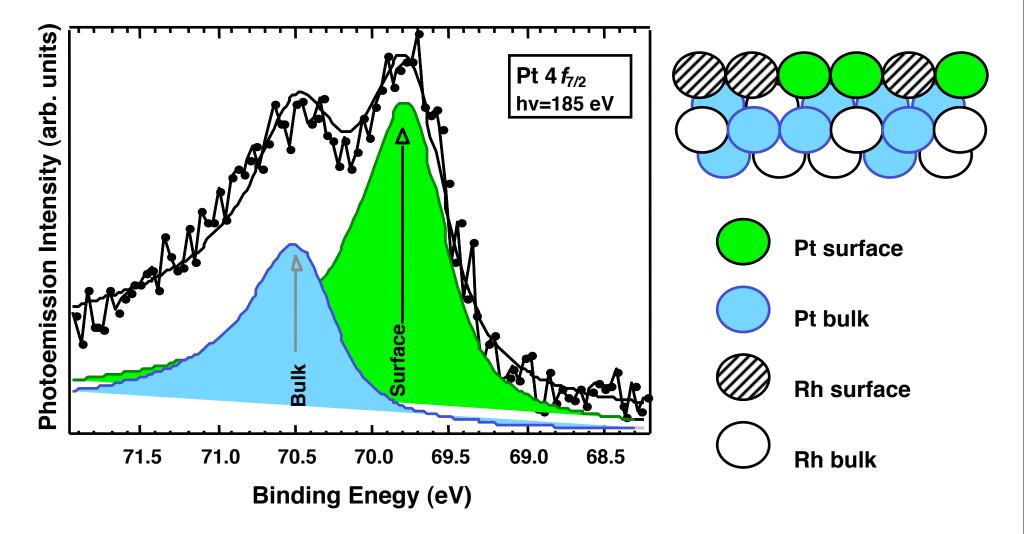
## The supersonic molecular beam



# Application of the supersonic molecular beam

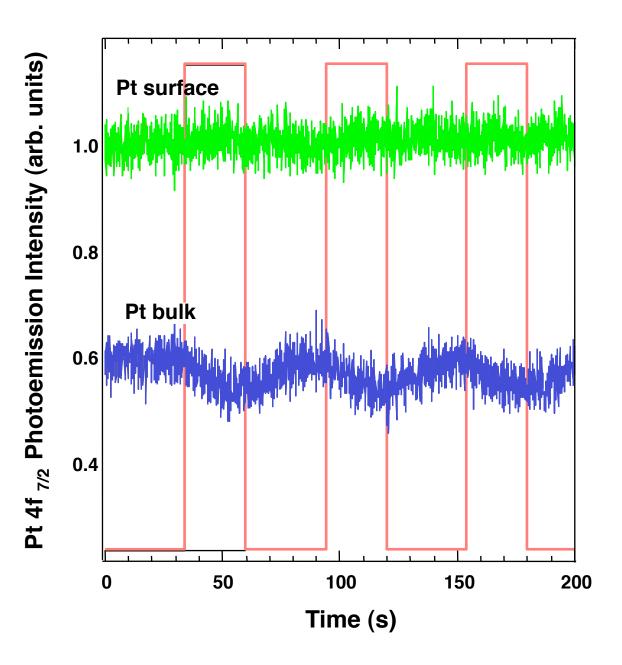
Reaction between  $O_2$  and  $H_2$  on  $Pt_{50}Rh_{50}(100)$  via Surface core level shift

### The supersonic molecular beam

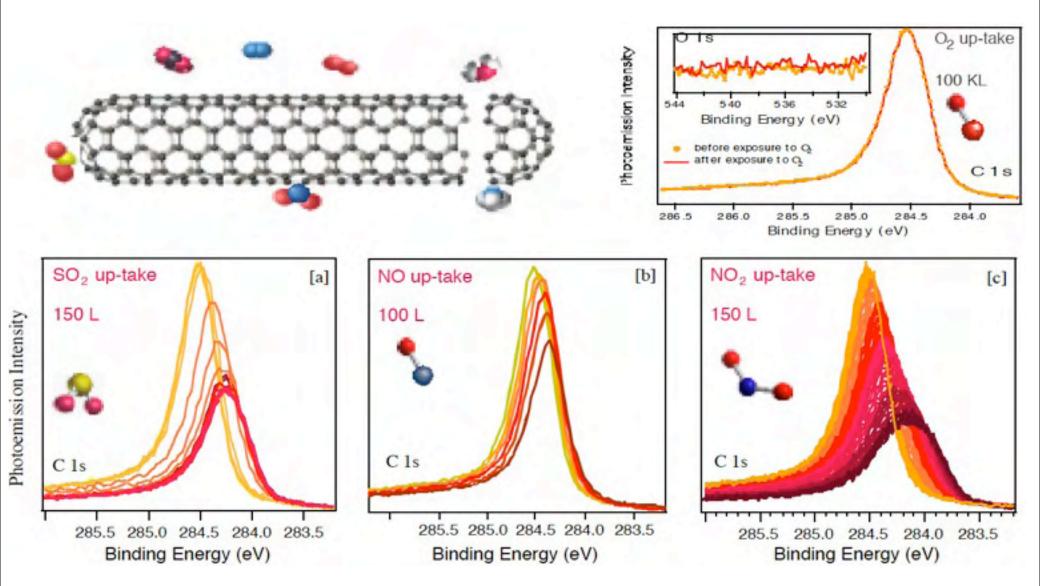


# The supersonic molecular beam

Oxygen sticks to Rh only and subsurface Pt is "attracted" from O on the surface



### **Reactivity of carbon nanotubes**



### **Reactivity of carbon nanotubes**

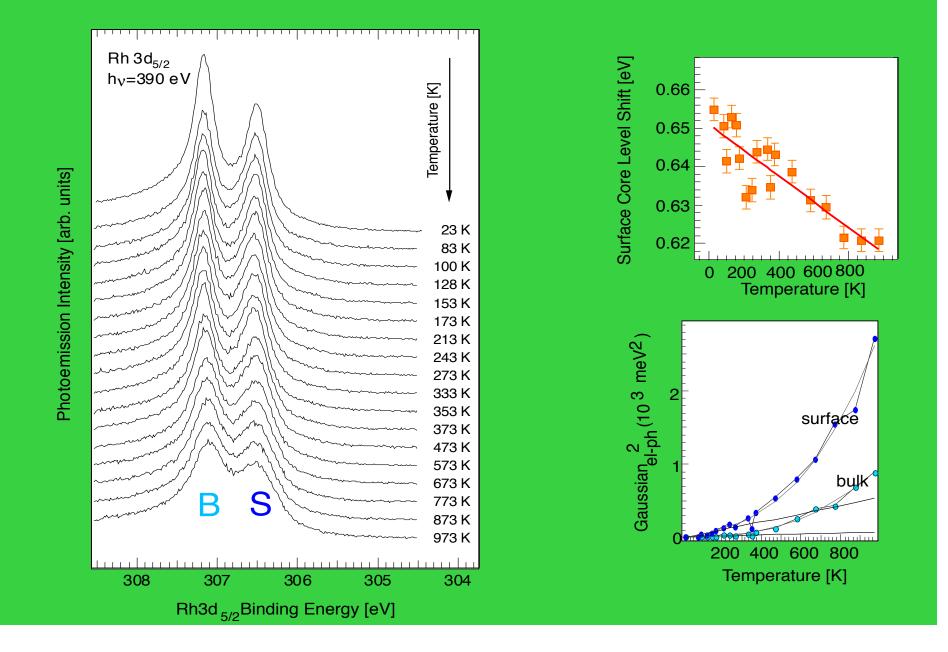
When contaminants are removed from SWCNTs they show little (or no) interaction of SWCNTs with  $O_2$ ,  $H_2O$  and  $N_2$ (countrary to what reported by P.G. Collins et al., Science **287**, 1801 (2000))

Strong reactivity of purified SWCNTs towards NOx and SOx

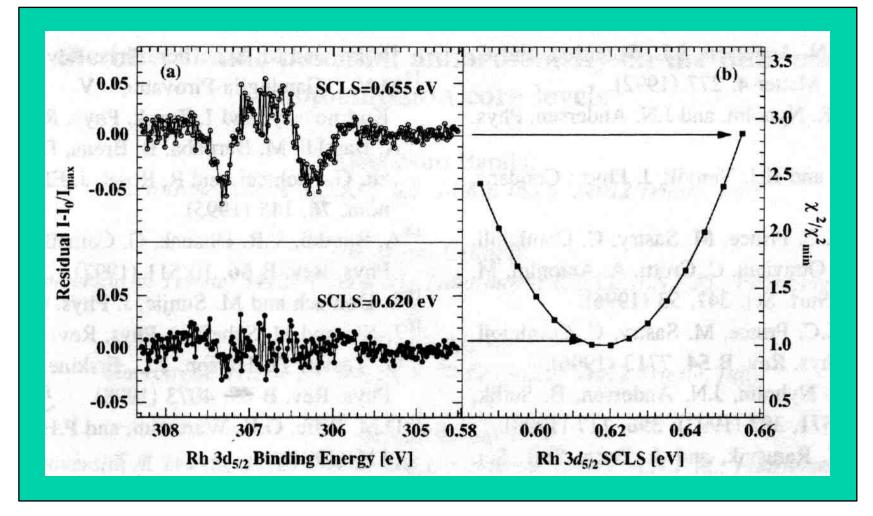
# Temperature dependence of core levels

- Temperature dependent surface core level shift
  - surface thermal expansion
- T-dependent width of C 1s in C<sub>60</sub>
   a measure of surface specific heat

#### Temperature dependence of Rh(100) surface core level shift



### **A real effect?**



comparison of the residuals obtained by forcing the SCLS to its low-T value with a T-dependent SCLS

## **Surface thermal expansion**

- Calculations (Xie and Scheffler) show that  $\Delta d_{12}/d_0$  goes from -2.5% (at 0 K) to 0% (at 770 K)
- The calculated SCLS is 0.62 eV for  $\Delta d_{12}/d_0 \sim 0$  (Andersen *et al.*) in very good agreement with our measurements and *increasing* with *decreasing*  $\Delta d_{12}$

Our measurements support an inward relaxation in agreement with theory but not with LEED which gives  $\Delta d_{12}/d_0 \sim +1\%$  at 300 K (Teeter *et al.*)

# Surface calorimetry lf a core level lifetime broadening is small and there is a gap in the vibrational excitation spectrum then surface calorimetry by XPS is possible **molecular** solids such as C<sub>60</sub> are good candidates

Molecular solids such as C60 are good candidates as core level lifetime broadening is small

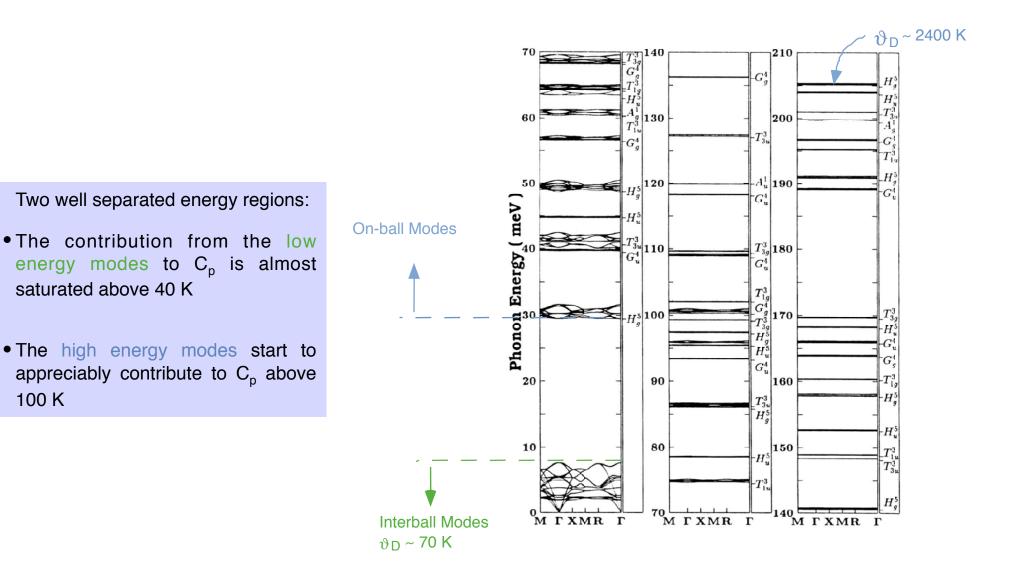
and

there is a gap in the vibrational excitation spectrum

then

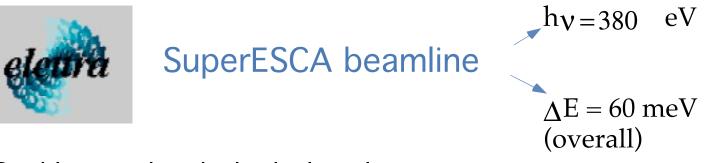
surface calorimetry by XPS is possible

### The bulk phonon modes of solid C<sub>60</sub>



100 K

Photoemission experiments performed at:

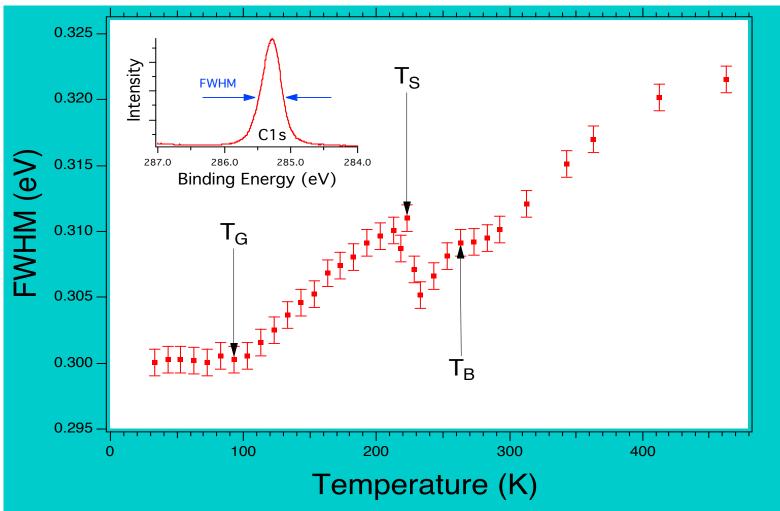


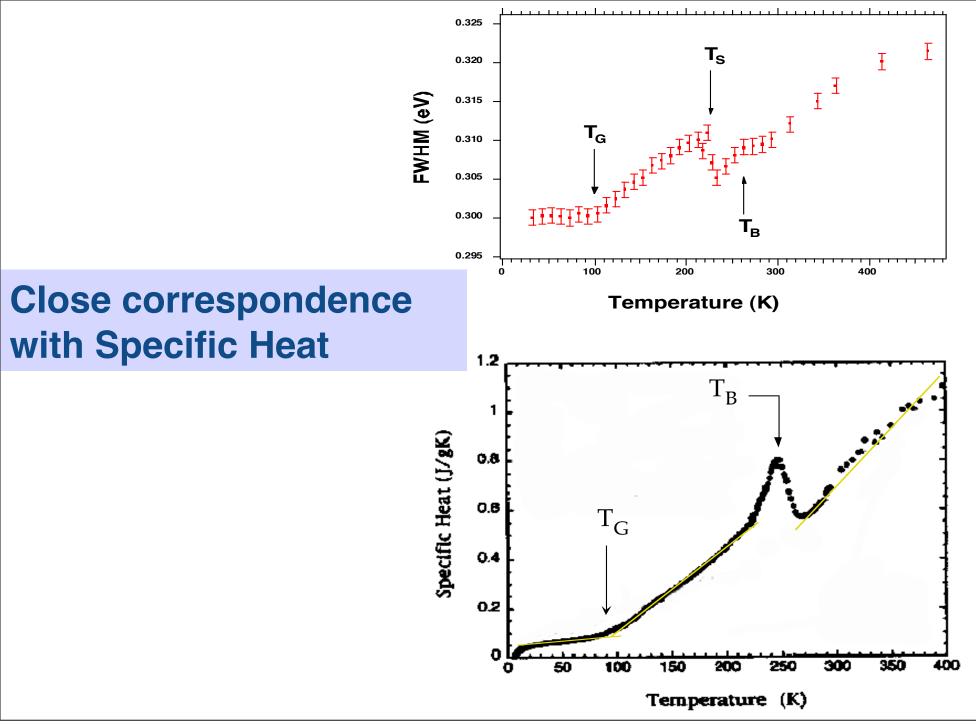
Double-pass hemispherical analyzer 96-channels detector ~ 20 seconds per spectrum high signal-to-noise ratio fine temperature control (± 0.1 K)

#### Sample:

 $C_{60}(111)$  thick film (20 ML) grown in situ on Ag(100)

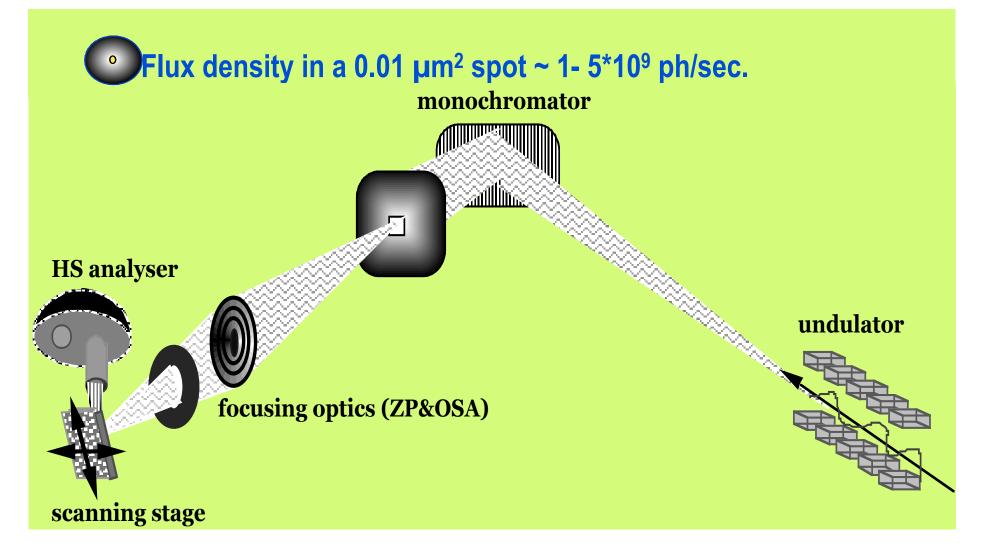
# Temperature dependence of C1s level width





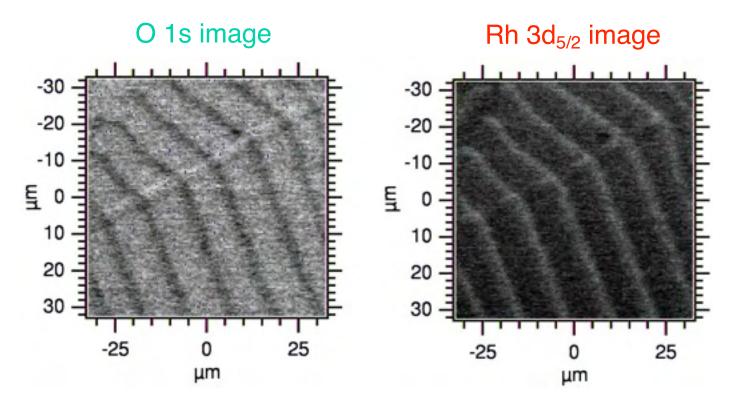
# Photoemission microscopy: spatial+chemical information

### ESCAmicroscopy Beamline and Scanning Photoelectron microscope layout

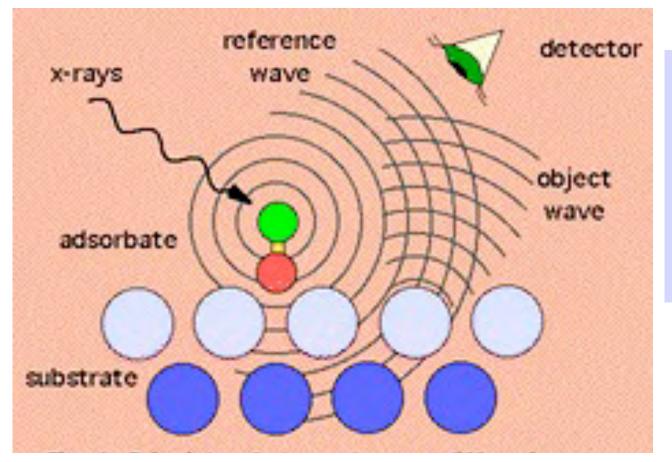


Elemental maps recorded with SPEM showing propagating pulse trains in the system Rh(110)/NO +  $H_2$ . Experimental conditions: T= 530 K,  $p_{NO}$ =1.7x10<sup>-7</sup> mbar,

 $p_{H_2}=6.4 \times 10^{-7}$  mbar, photon energy 625.7 eV

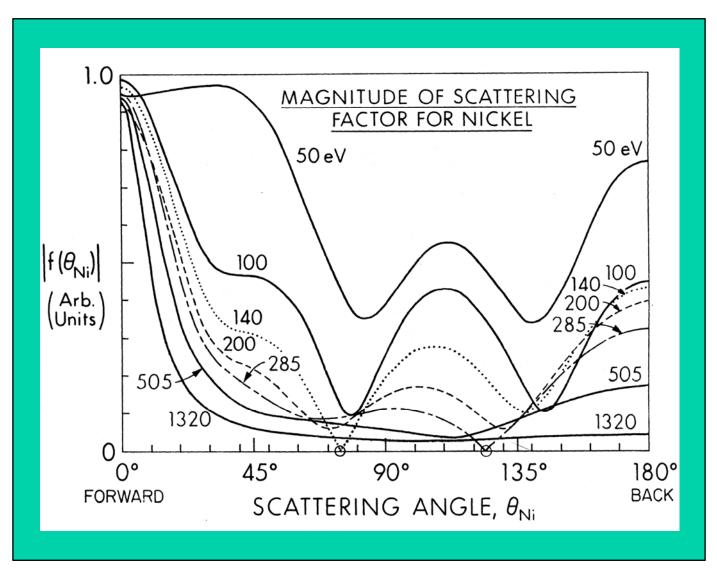


## The principle of photoelectron diffraction

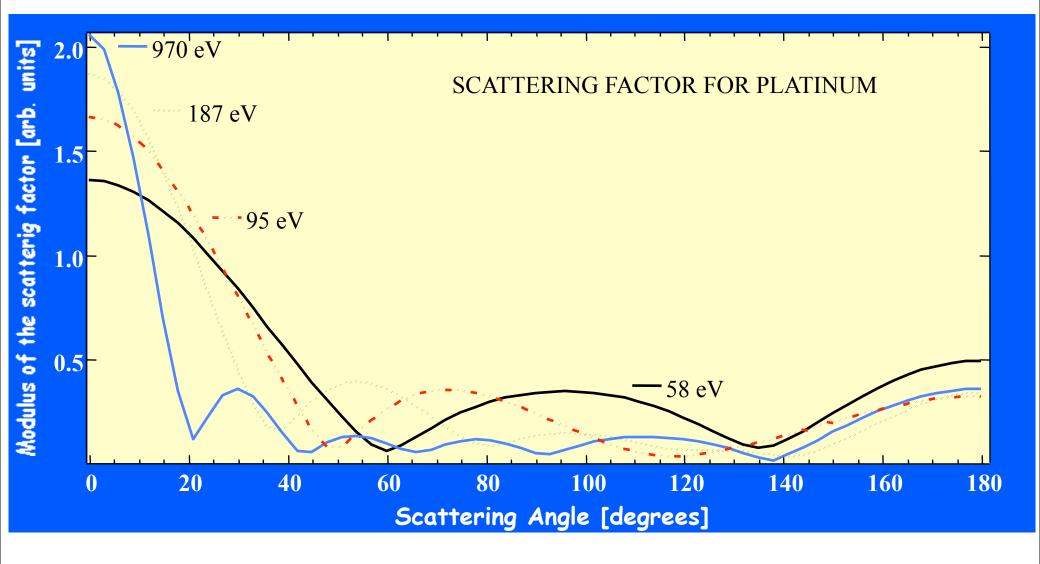


Modulations in the intensity of the photoemitted electron wave are measured. For a given arrangment of atoms, the intensity depends on the photon energy and on the emission angle

# Forward scattering is the dominant mechanism at high kinetic energy



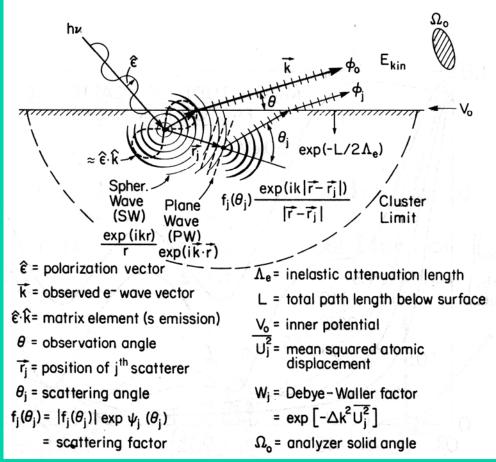
### **Forward scattering and XPD**

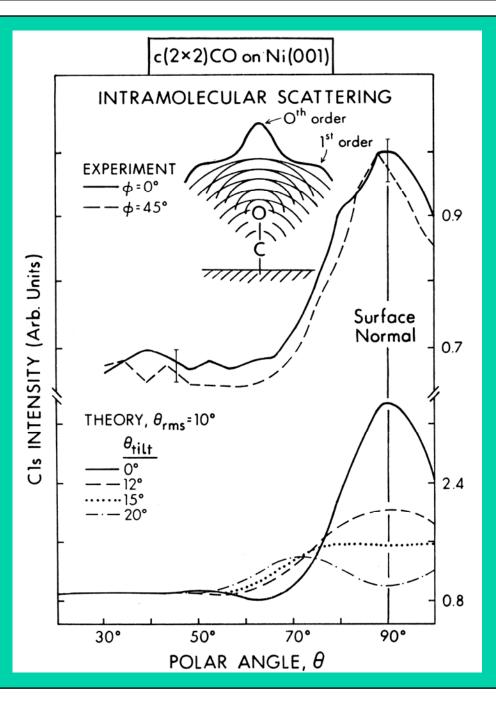


 $\left| I(\vec{k}) \propto \left| \hat{\varepsilon} \cdot \hat{k} e^{-\gamma L} + \sum_{j} \frac{\hat{\varepsilon} \cdot \hat{r}_{j}}{r_{j}} \right| f_{j}(\theta_{j}) \left| W_{j} e^{-\gamma L_{j}} e^{i[kr_{j}(1-\cos\theta_{j})+\psi_{j}(\theta_{j})]} \right|$ 

$$+\sum_{j} \left(\hat{\varepsilon} \cdot \hat{r}_{j}\right) \frac{\left|f_{j}(\boldsymbol{\theta}_{j})\right|^{2}}{r_{j}^{2}} (1 - W_{j}^{2}) e^{-2\gamma L_{j}}$$

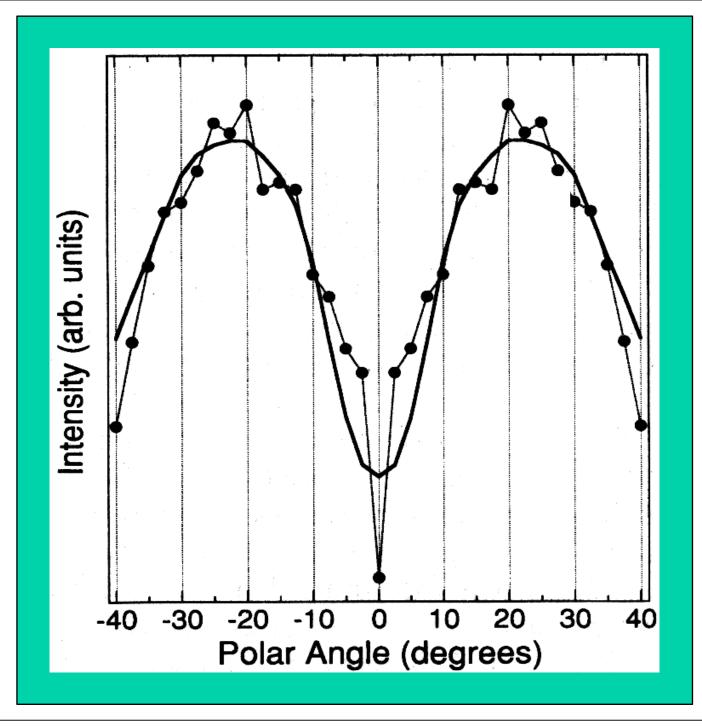
# The single scattering cluster





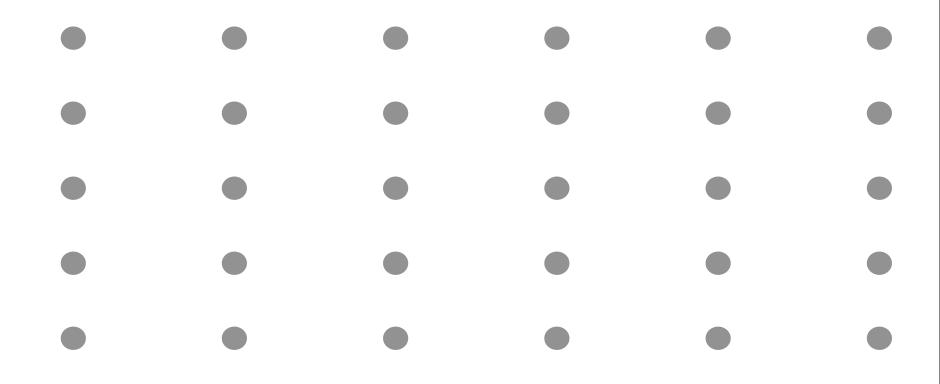
CO/Ni(100): forward scattering produces a pronounced peak along the molecular axis (along the surface normal)

### CO/Pd(110): a compressed zig-zag structure

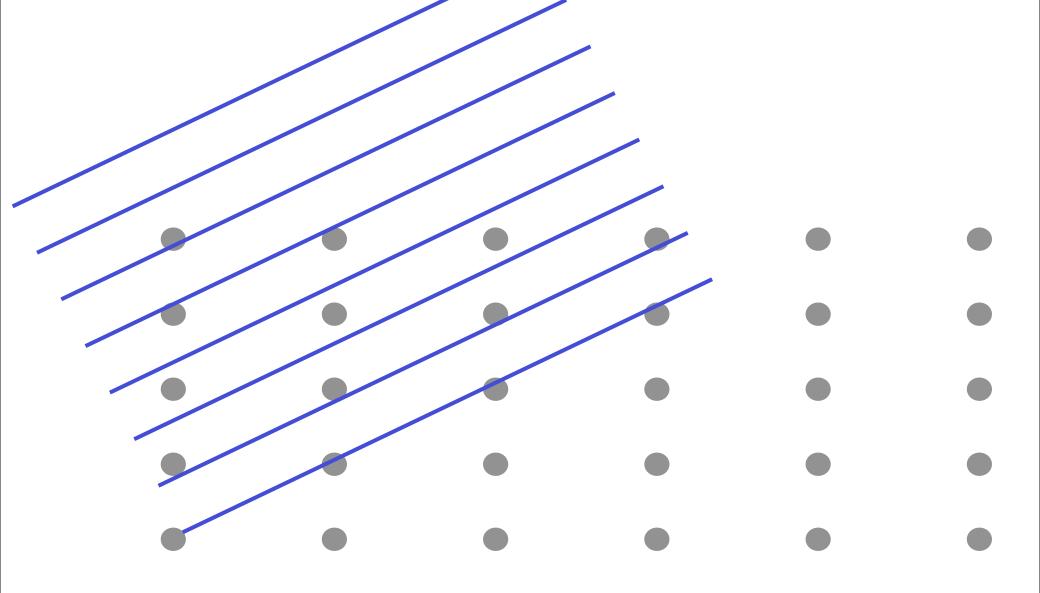


Probe	Ε(λ)	Scatterers
x-rays	$E = \frac{2\pi\hbar c}{\lambda};  E(eV) = \frac{12400}{\lambda(\AA)}$	electrons
electrons	$E = \frac{(2\pi\hbar)^2}{2m} \left(\frac{1}{\lambda}\right)^2;  E(eV) = \frac{150.4}{\left(\lambda(\mathring{A})\right)^2}$	electrons and nuclei
neutrons	$E = \frac{(2\pi\hbar)^2}{2M} \left(\frac{1}{\lambda}\right)^2;  E(eV) = \frac{8.19 \cdot 10^{-2}}{\left(\lambda(Å)\right)^2}$	nuclei
atoms (e.g. He)	$E = \frac{(2\pi\hbar)^2}{2MA} \left(\frac{1}{\lambda}\right)^2;  E(eV) = \frac{2.05 \cdot 10^{-2}}{\left(\lambda(Å)\right)^2}$	electrons

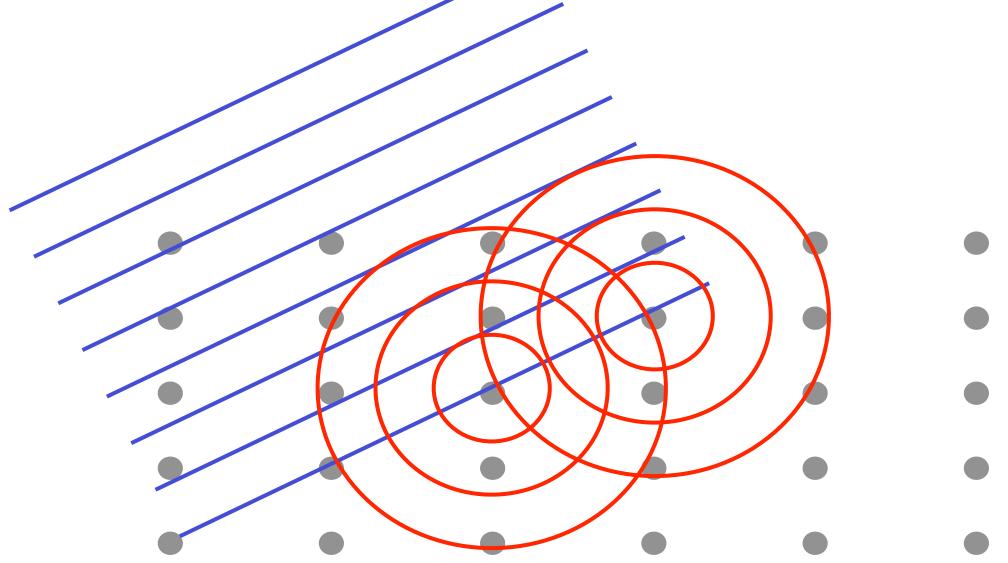
### **External wave source**



### **External wave source**



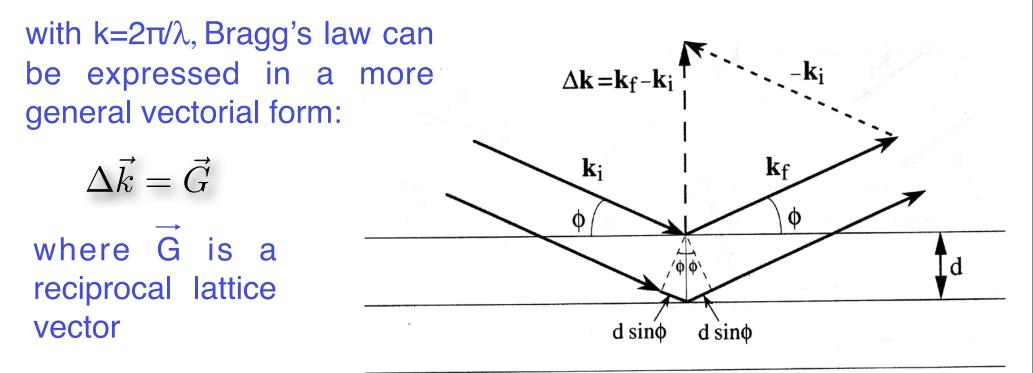
### **External wave source**



### Diffraction

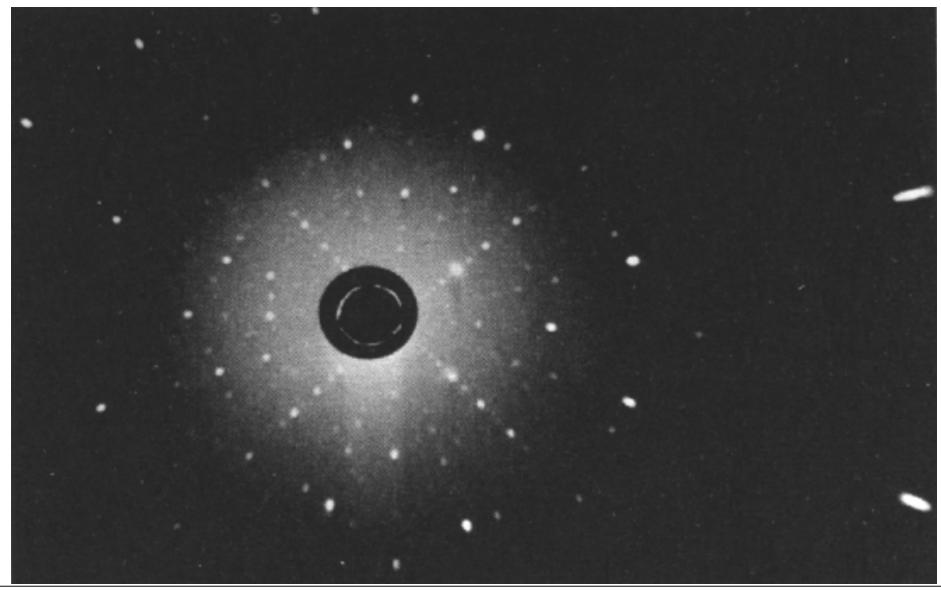
If one considers the wavevector k of the plane wave

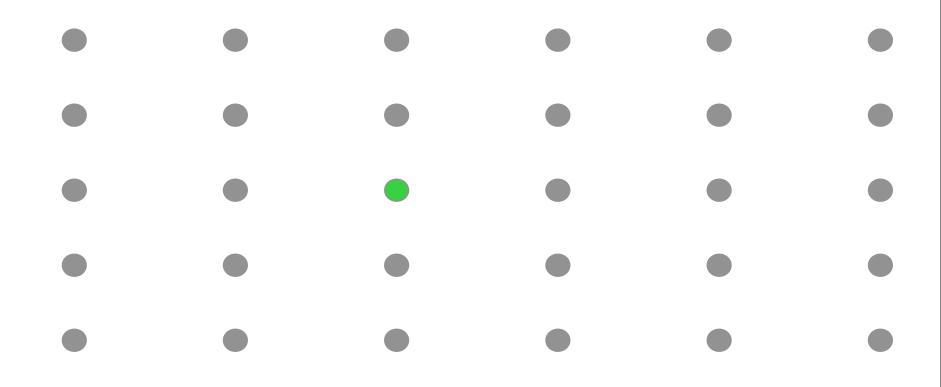
$$\vec{E}(\vec{r},t) = \vec{E}_0 e^{i(\vec{k}\cdot\vec{r}-\omega t)}$$

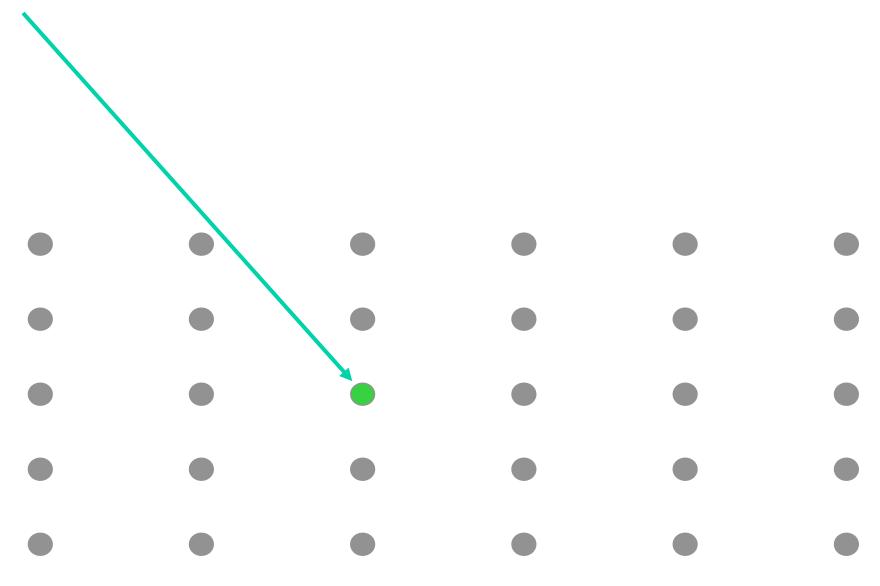


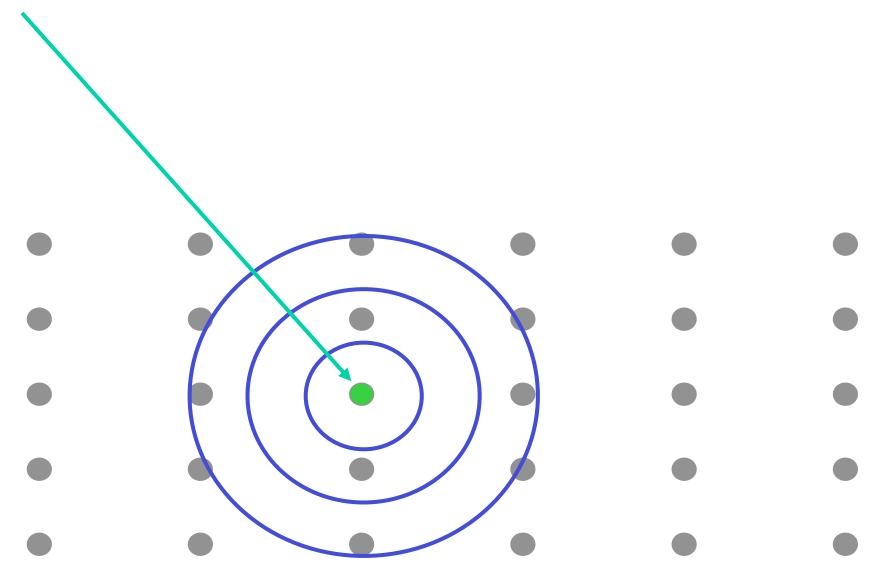
### Diffraction

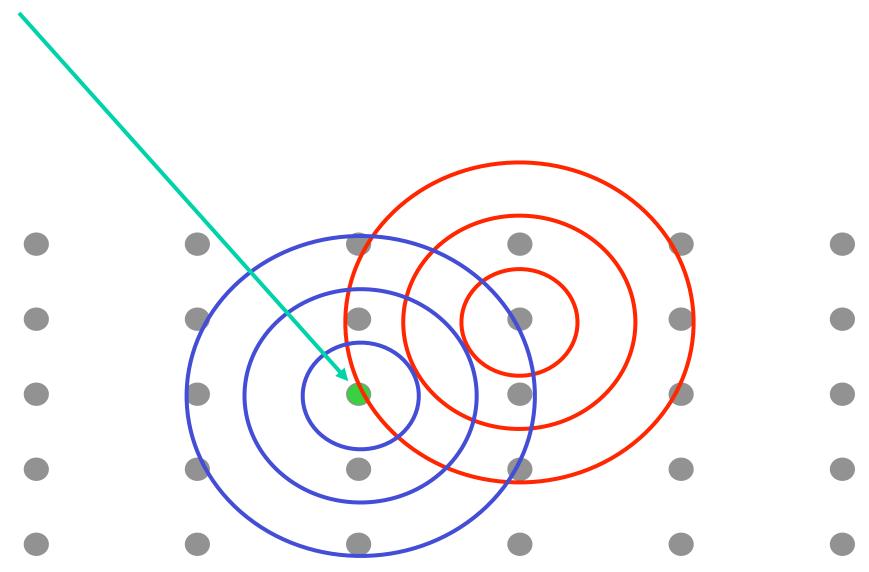
#### A Laue pattern: Si(100)









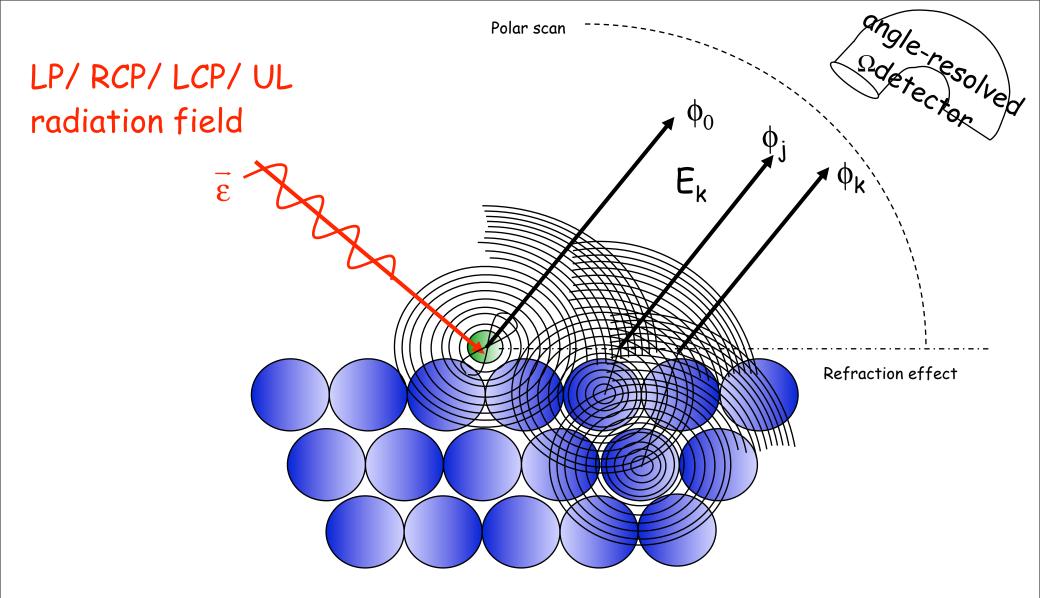


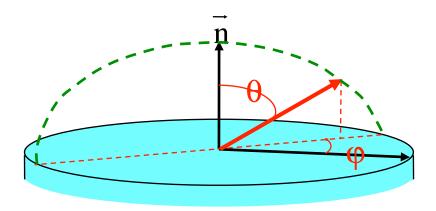
External plane wave source: single crystal (long range order)

**Internal spherical wave source:** 

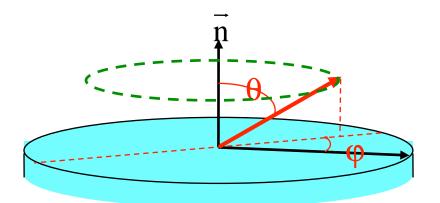
1) Measure what happens at the absorber (i.e. absorption)→ short range order

Measure outside the sample
 (i.e. photoemission) → short range
 order+same orientation at different sites



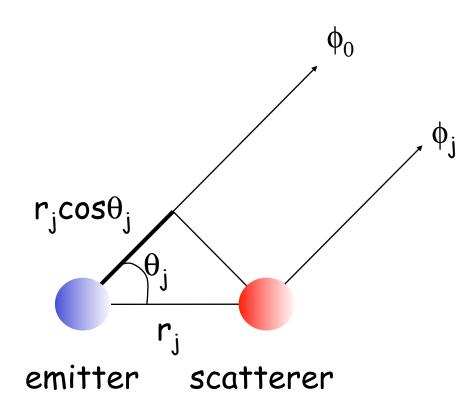


Polar scan

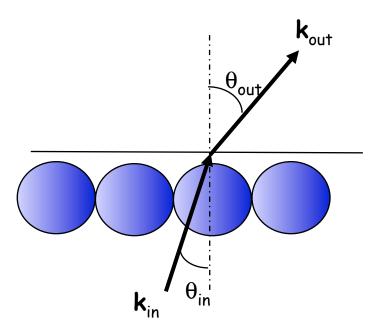


Azimuthal scan

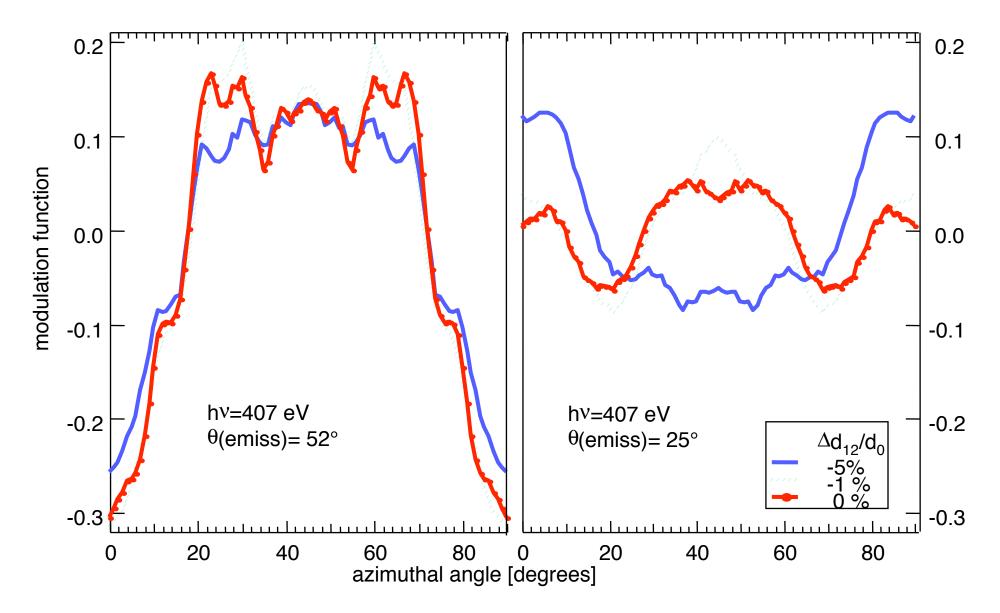
#### The basic scattering event:



#### **Refraction at the surface**

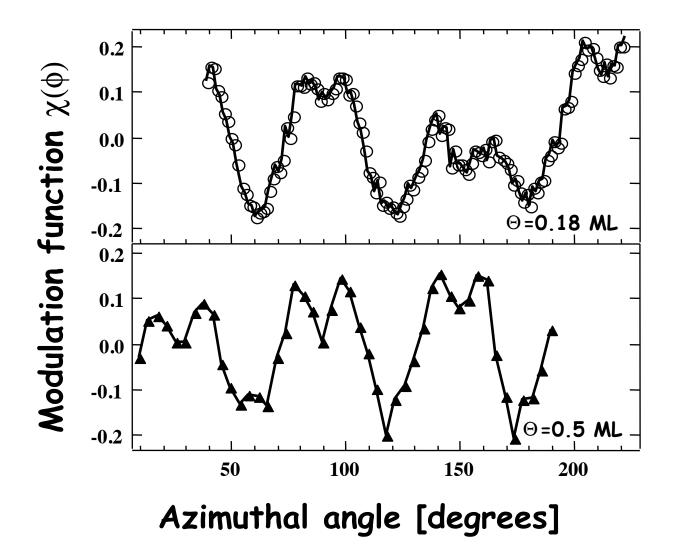


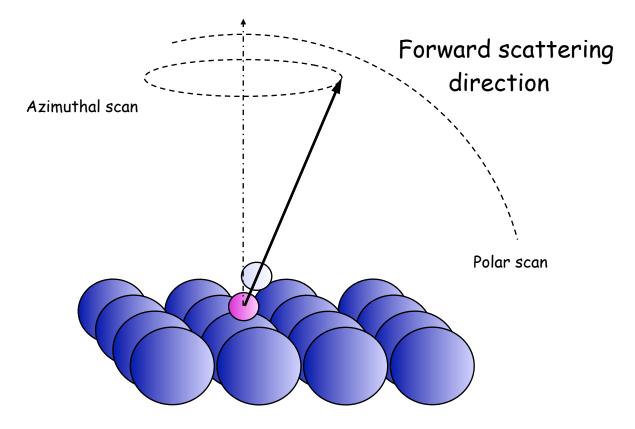
# Sensitivity to structural parameters in different measurement conditions: clean Rh(100)



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## "Fingerprinting": CO/Pt(111)





# Chemical shift photoelectron diffraction



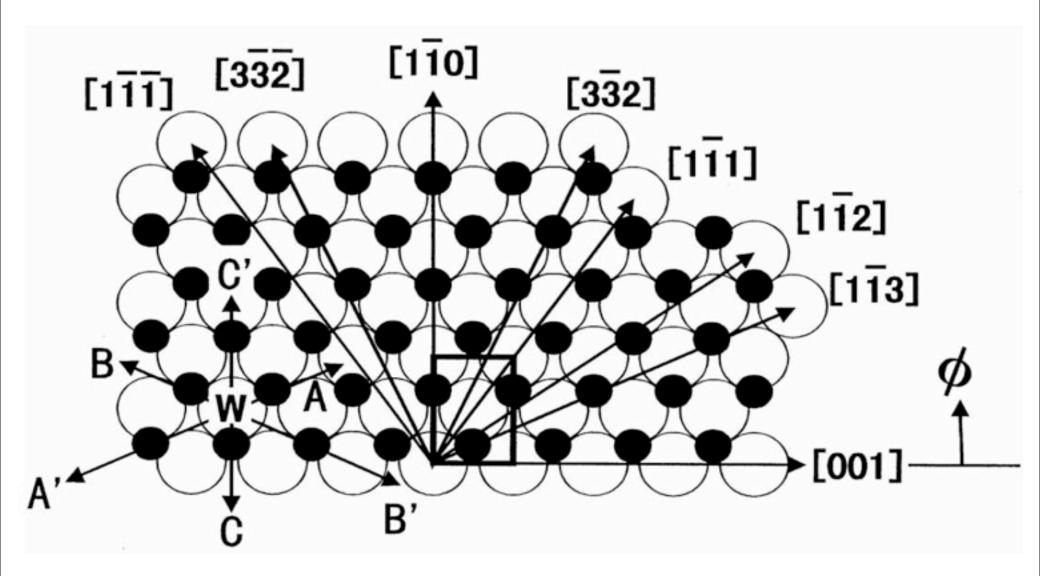
Surface Science 408 (1998) 260-267

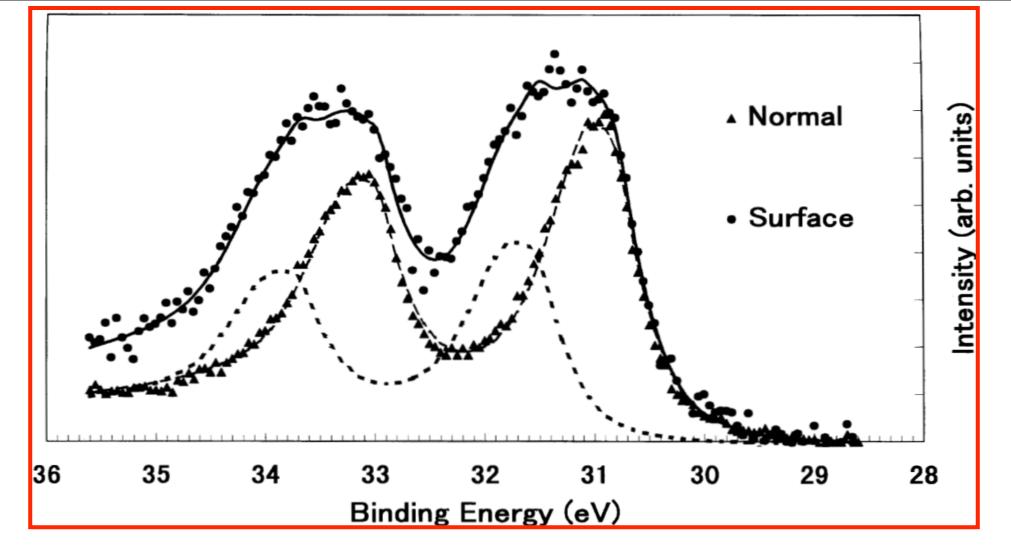
surface science

# Direct structure analysis of $W(110)-(1 \times 1)-O$ by full solid-angle X-ray photoelectron diffraction with chemical-state resolution

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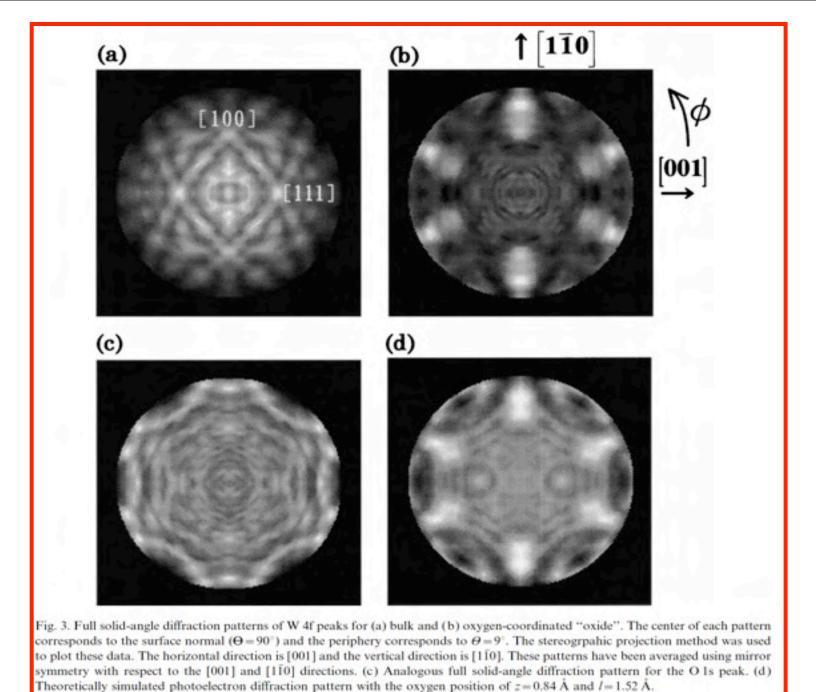
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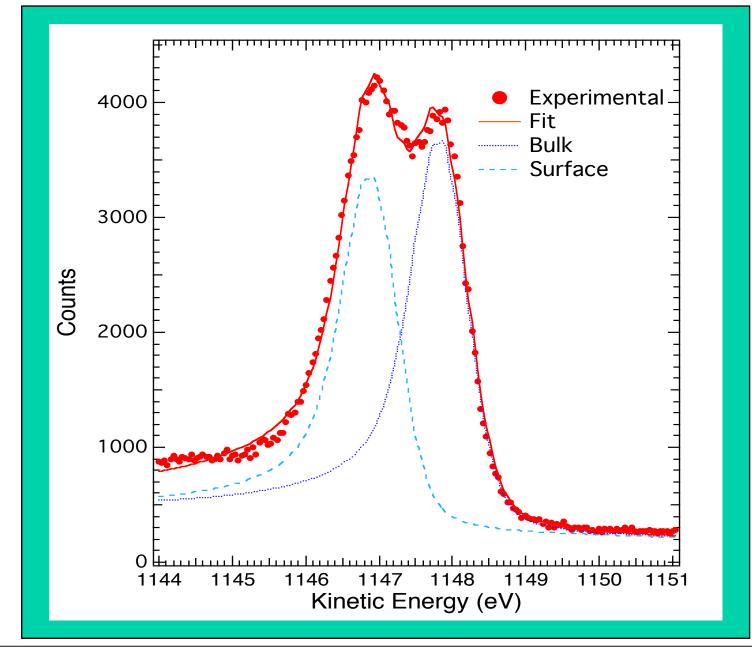
W4f XPS spectra from the W(110)-(1x1)-O surface as excited by Al K<sub> $\alpha$ </sub> radiation. The triangles represent a bulk-sensitive spectrum taken with emission normal to the surface. The circles represent data taken at a maximally surface-sensitive direction ( $\Theta$ , $\phi$ )=(12°,26°), where  $\Theta$  is the take-off angle with respect to the surface and  $\phi$  is measured with respect to [001].The surface-sensitive spectrum is fitted well by the solid curve composed of two pairs of peaks having the same shape and separation. The dashed curve is that for normal emission and the dotted curve derived from this peak fitting we associate with electrons from the first-layer "oxide" W atoms which are directly bound to oxygen. The latter exhibit a core-level shift of 0.73 eV due to charge transfer from W to oxygen.

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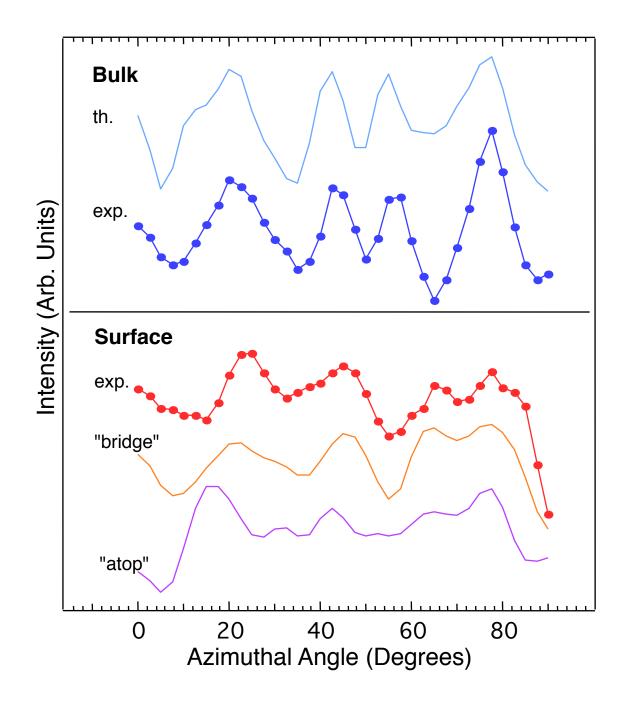


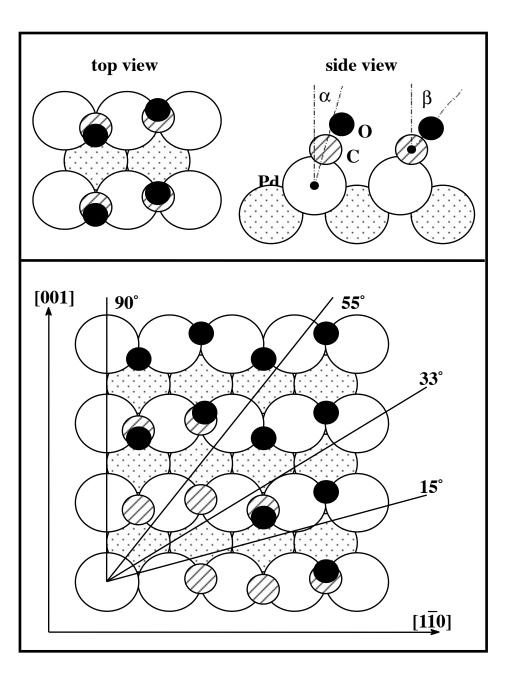
### SCLS induced by CO on Pd(110)

A. Locatelli et al., Phys. Rev. Lett. 73, 90 (1994)

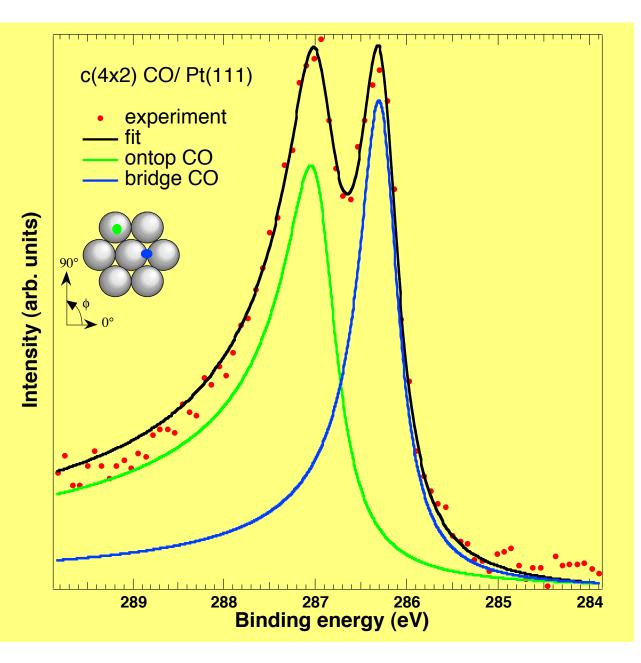


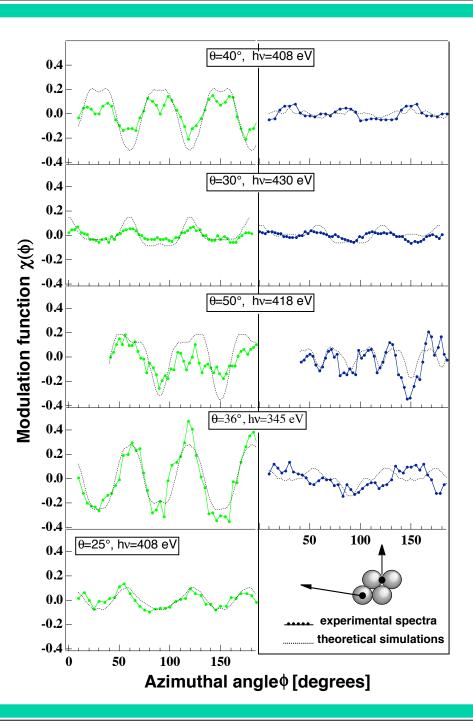
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In the c(4x2)structure of **CO/Pt(111) the** adsobate occupies two adsorption sites: the photoelectron diffraction pattern is different for the two components and allows to measure the local geometry

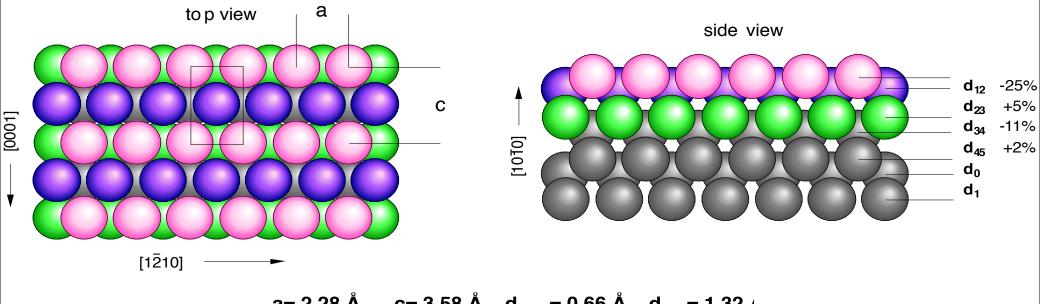




Multiple scattering calculations reproduce the experimental data, confirm the peak assignment and give the structural parameters

# Be (1010): a complex core

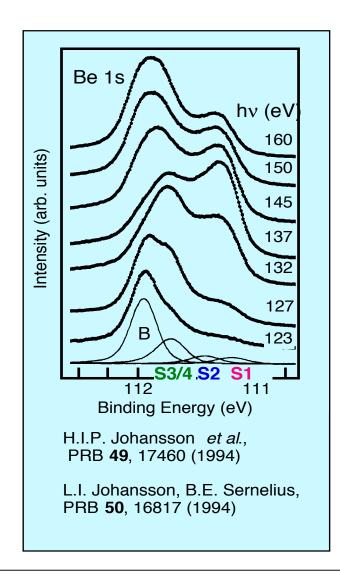
# Structure of the Be (1010) surface



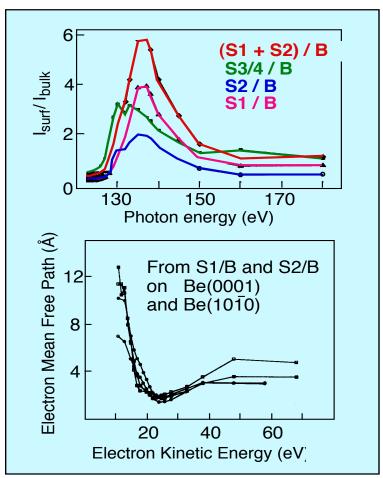
a= 2.28 Å c= 3.58 Å d<sub>0</sub> = 0.66 Å d<sub>1</sub> = 1.32  $\mu$ 

Hofmann et al., PRB 53, 13715 (1996)

#### energy dependence

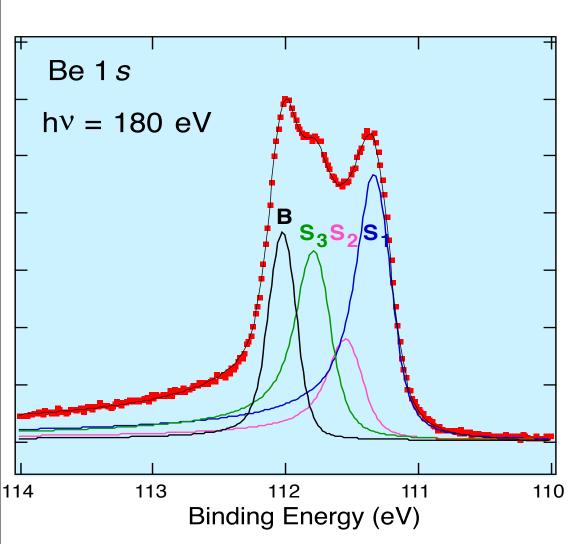


## determination of the inelastic mean free path



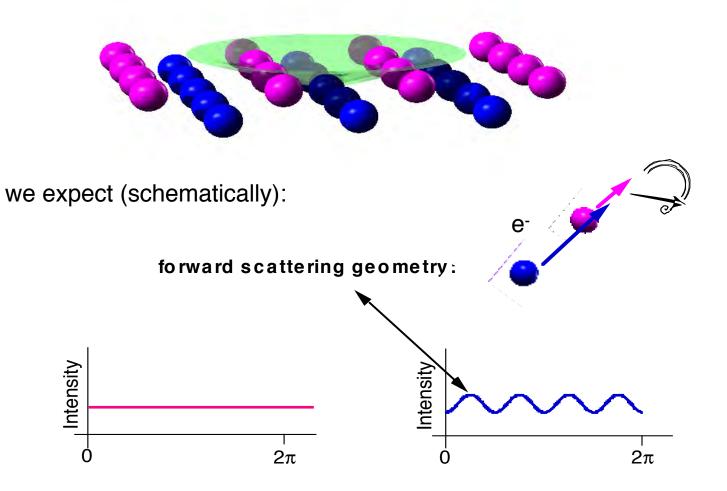
# The assignment of 1. And 2. layers is reversed between theory and experiment



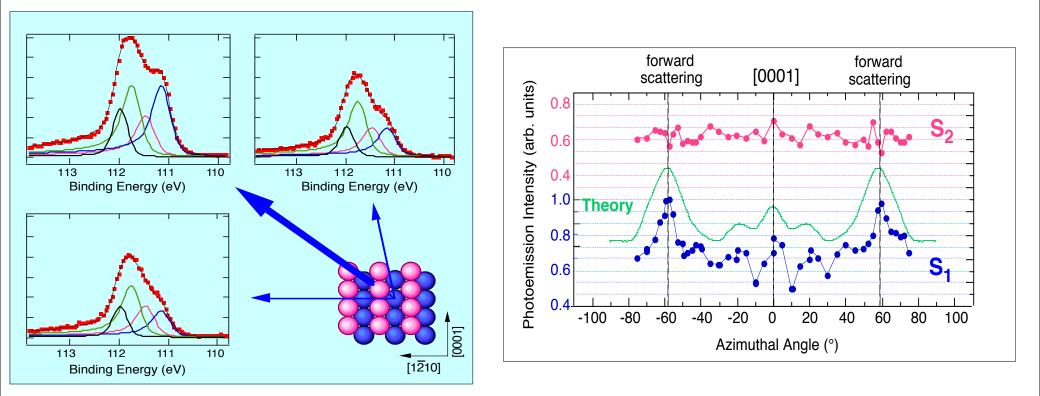


	Same fitting	
	parameters	
Joł	nansson <i>et al.</i>	this study
S <sub>3</sub> (eV)	0.22	0.24
$S_{2} (eV)$	0.50	0.50
$S_1(eV)$	0.70	0.71
W <sub>Lor</sub> bulk (eV)	0.09	0.09
Asym bulk	0.02	0.05
W <sub>Gau</sub> bulk (eV)	0.21	0.19
W <sub>Lor</sub> surf (eV)	0.09	0.10
Asym surf	0.06	0.08
W <sub>Gau</sub> surf (eV)	0.24	0.20

Azimuthal scan 75° away from the surface normal at high kinetic energy (> 400 eV):



## Same assignment as theory



Determination of surface relaxation by variable polarization photoelectron

